



Introduction of TPC for ILC experiment

Keita Yumino (SOKENDAI)



ILC Summer Camp2020 online

TPC talk @ILC summer camp 2019

Main topics: Overview of LCTPC

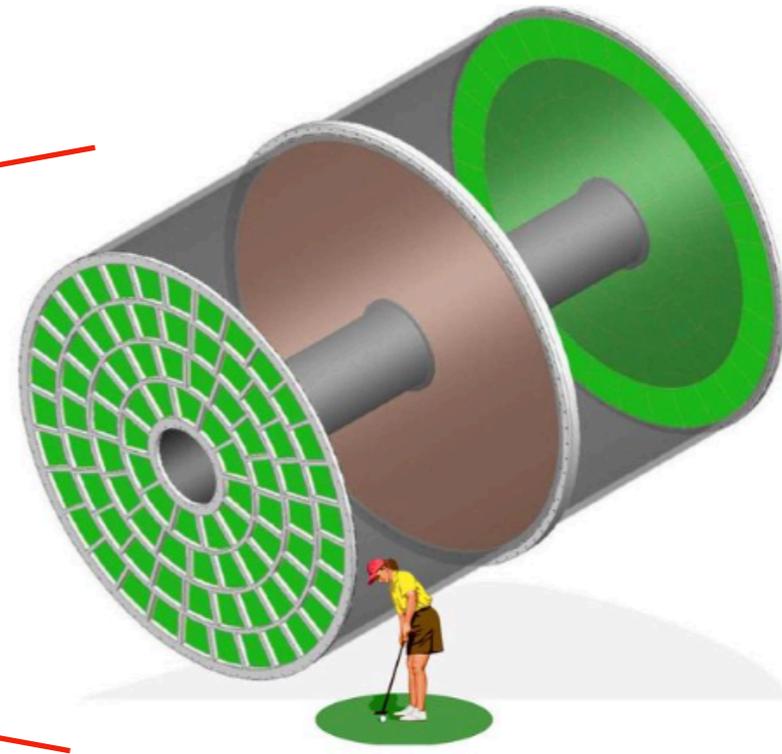
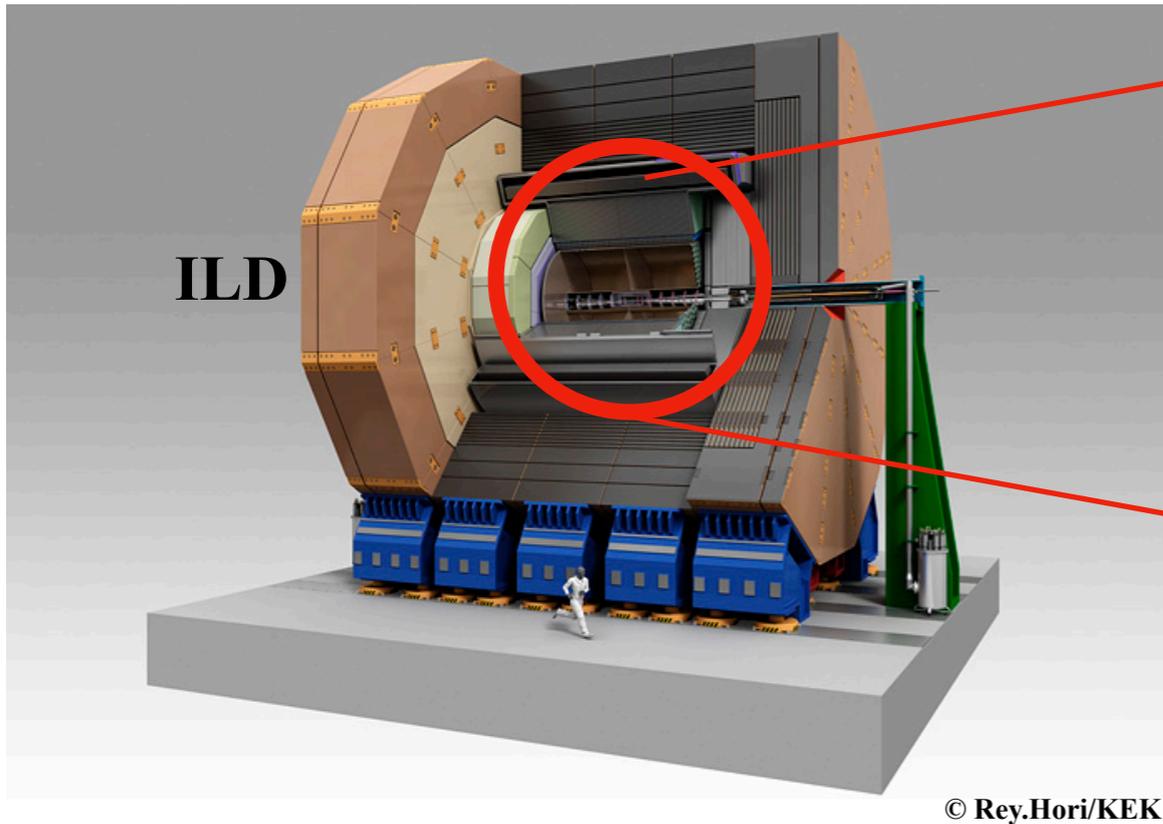
https://agenda.linearcollider.org/event/8237/contributions/44016/attachments/34697/53550/ILC_SummerCamp_Yumino2019ENG_0.pdf

This year Mainly focus on

- **dE/dx**
- **Gas mixture**
- **Avalanche gas gain**

Time Projection Chamber (TPC)

Central tracker of ILD



Detects reactions of charged particles in 3-dim as tracks

Role of TPC

charged particle

Track measurement

Measure passing points along trajectory

↳ Directions of track

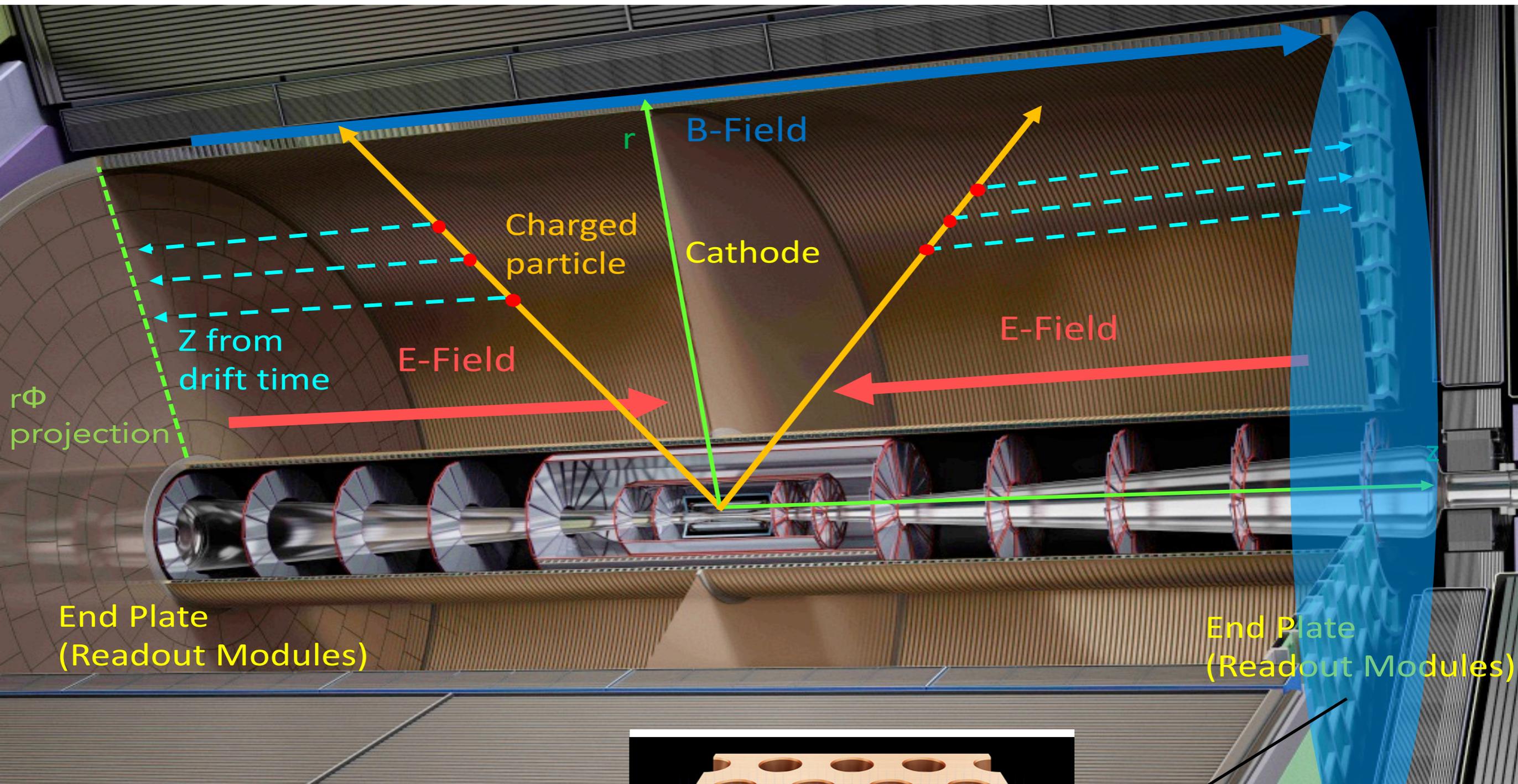
Momentum measurement

Measure the bend of tracks in B-Field

↳ Momentum of charged particle

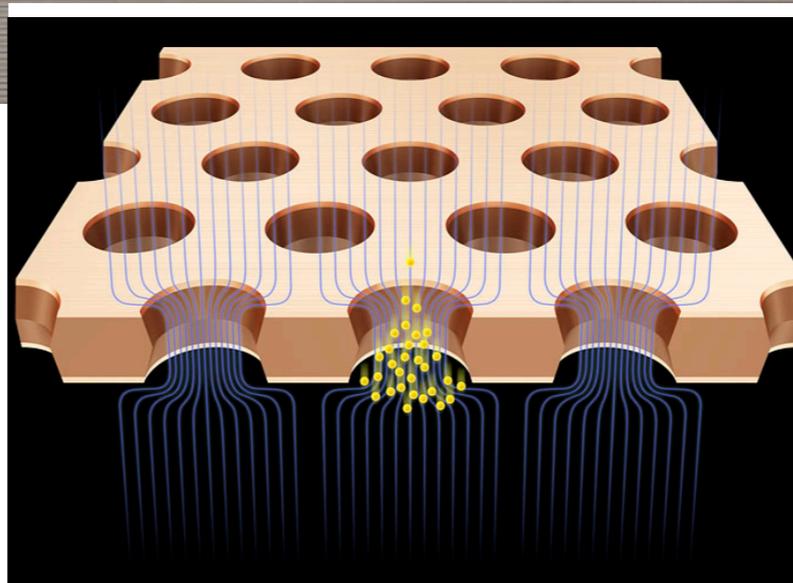
Particle Identification (PID)

Inside of ILD-TPC



T2K gas $\text{Ar} : \text{CF}_4 : \text{iC}_4\text{H}_{10} = 95 : 3 : 2$

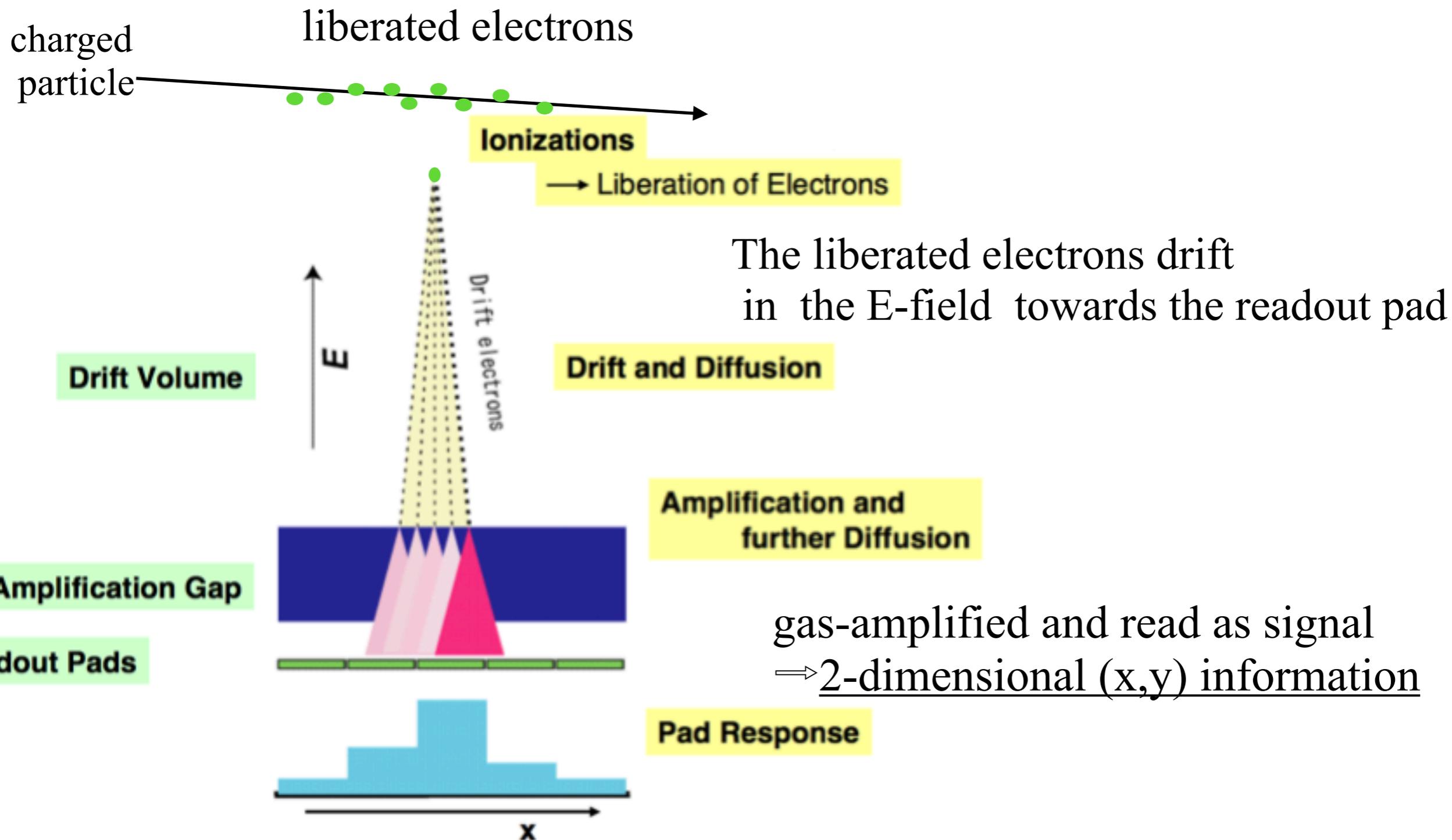
Gas amplification of ionised electrons
and read out as electrical signal



Example of gas-amplifier
GEM (Gas Electron Multiplier)

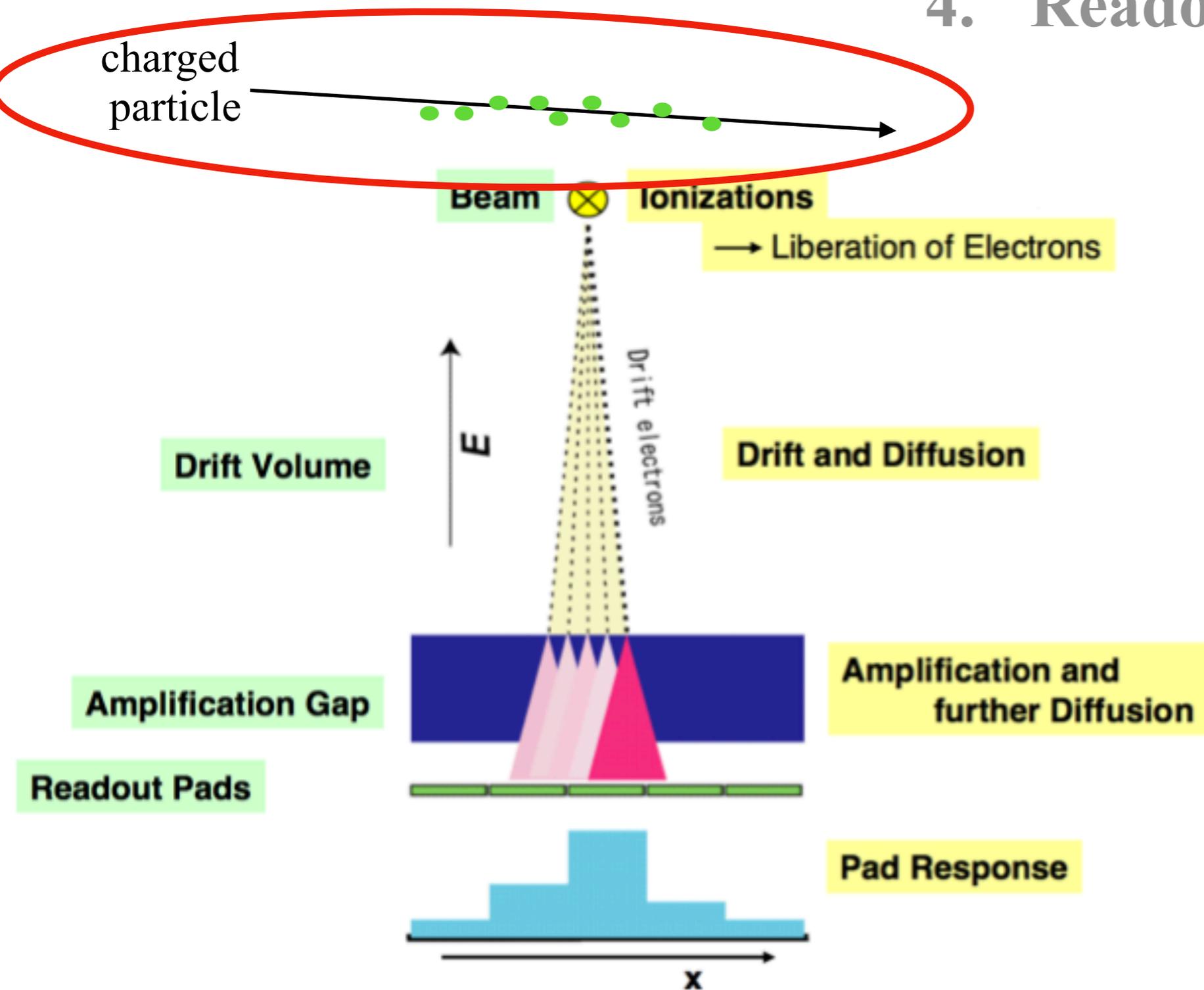
Operating principle of TPC

A charged particle ionizes the atoms of the gas mixture along its trajectory

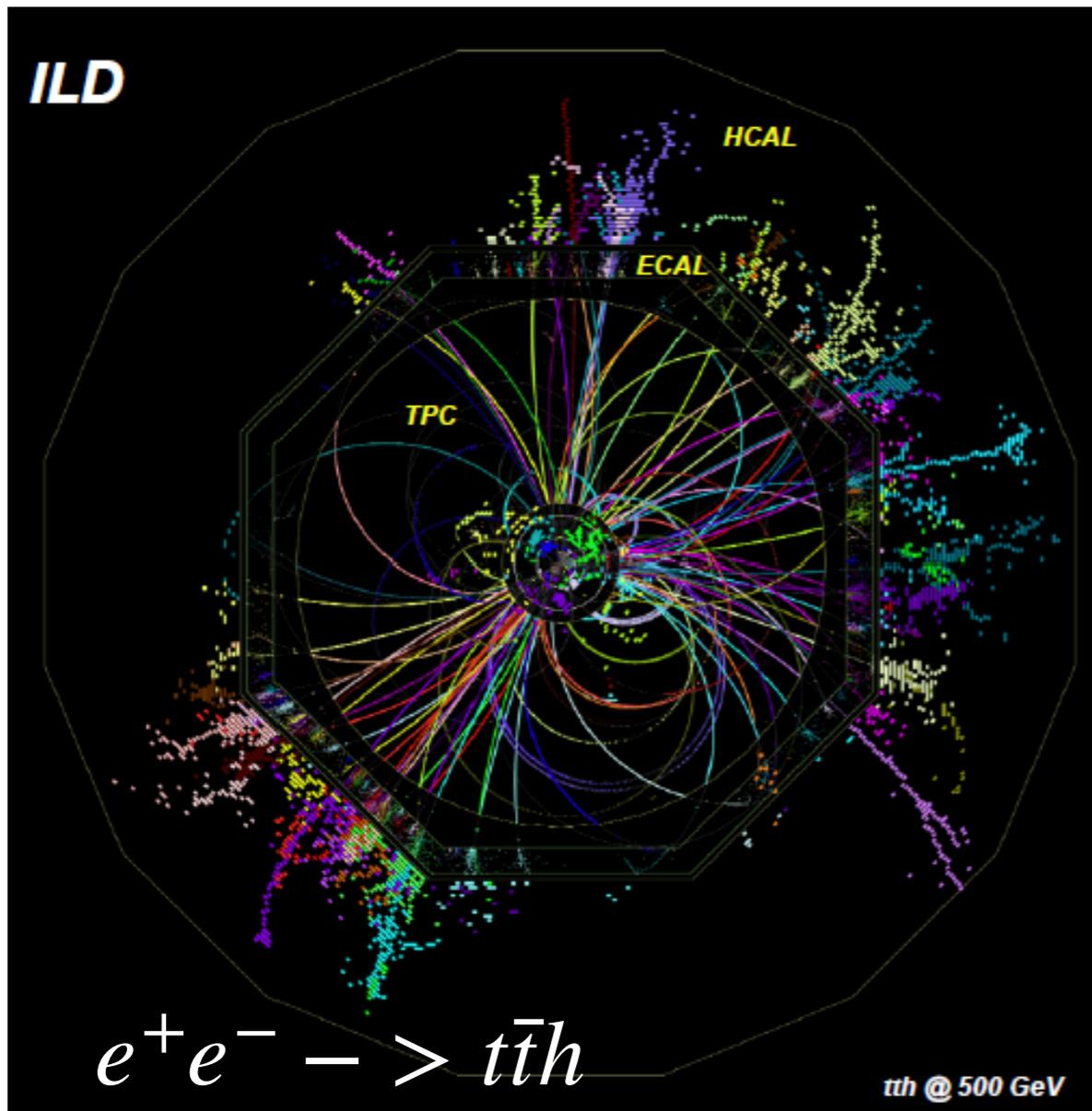


z component is obtained from drift time => 3-dimensional (x, y, z) information

1. Momentum measurement
2. Gas mixture
3. Particle ID and dE/dx
4. Readout module



Momentum measurement



track of particles(simulation) see from the side of TPC

Charged particle : circular motion
in B-Field

$$p_{\perp} = 0.3 BR [GeV/c]$$

$$B = 3.5 \text{ T @ ILC}$$

p_{\perp} : vertical axis component

p_z : beam axis component

R : radius of curvature

The ratio of p_z and p_{\perp} is obtained from the emission angle

The radius of curvature \underline{R} gives momentum \underline{p}

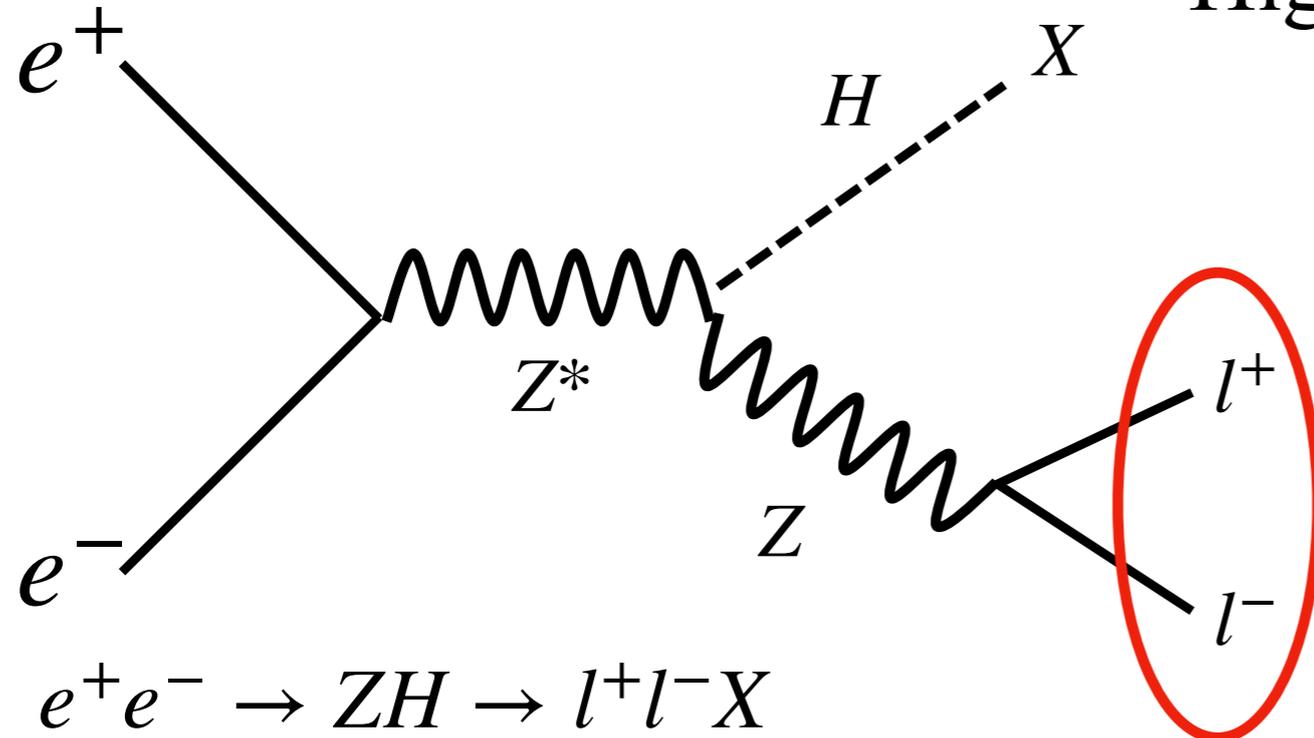
required momentum resolution of ILD-TPC

ILC: “Higgs factory”

Higgs precision measurement is a high-priority goal

“Recoil”

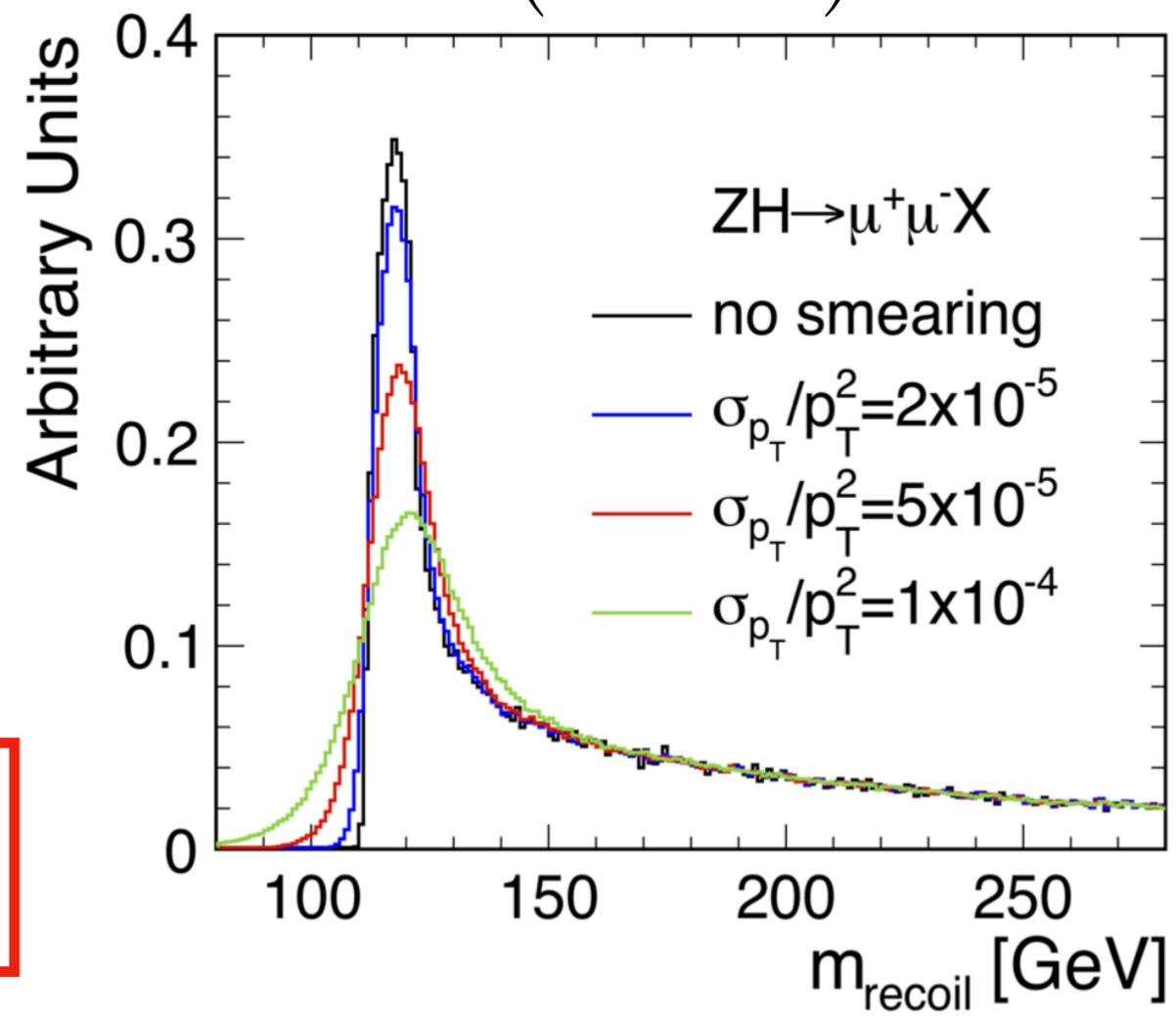
Higgs can be reconstructed indirectly



$$P_h = P_{e^-} + P_{e^+} - P_Z$$

or

$$m_{recoil}^2 = \left(\sqrt{s} - E_{ll} \right)^2 - |P_{ll}|^2$$



Reconstruction of $Z \rightarrow ll$

momentum resolution is crucial

Momentum resolution

Momentum resolution

$$\frac{\sigma_{p_{\perp}}}{p_{\perp}} = \sqrt{\underbrace{\left(\frac{\alpha' \sigma_x}{BL^2}\right)^2 \left(\frac{720}{N+4}\right) p_{\perp}^2}_{\text{measurements}} + \underbrace{\left(\frac{\alpha' C}{BL}\right)^2 \frac{10}{7} \left(\frac{X}{X_0}\right)}_{\text{multiple scattering}}}$$

p_{\perp} : transverse momentum B : strength of B-Field L : track detection length α', C : constant
 σ_x : position resolution N : # of measurement points $\frac{X}{X_0}$: radiation length of gas

R.L. Gluckstern, NIM 24 (1963), 381

required momentum resolution of ILD-TPC

$$\frac{\sigma_{p_{\perp}}}{p_{\perp}} \approx 2 \times 10^{-5} p_{\perp} \text{ GeV}/c \quad (\text{including information of silicon tracker})$$

TPC only...

$$\frac{\sigma_{p_{\perp}}}{p_{\perp}} \approx 1 \times 10^{-4} p_{\perp} \text{ GeV}/c$$

Momentum resolution

Momentum resolution

$$\frac{\sigma_{p_{\perp}}}{p_{\perp}} = \sqrt{\underbrace{\left(\frac{\alpha' \sigma_x}{BL^2}\right)^2 \left(\frac{720}{N+4}\right) p_{\perp}^2}_{\text{measurements}} + \underbrace{\left(\frac{\alpha' C}{BL}\right)^2 \frac{10}{7} \left(\frac{X}{X_0}\right)}_{\text{multiple scattering}}}$$

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R.L. Gluckstern, NIM 24 (1963), 381

to achieve required momentum resolution

$$\frac{\sigma_{p_{\perp}}}{p_{\perp}} \approx 1 \times 10^{-4} p_{\perp} \text{ GeV}/c$$

ILCTPC: $B = 3.5 \text{ T}$, $N \simeq 200$, $L = 1.5 \text{ m}$

we need small position resolution σ_x $\sigma_x \approx 100 \mu\text{m}$

Position resolution

$$\sigma_x = \sqrt{\sigma_0^2 + \frac{C_d^2 \cdot z}{N_{eff}}}$$

z : drift length

N_{eff} : effective number of electron

C_d : diffusion constant of gas

depends on **drift length**

small position resolution σ_x

$$\sigma_x \approx 100 \mu m$$

even at the large drift length of $2.2 m$

- Strong magnetic field $B = 3.5 T$
- Gas mixture with small diffusion constant

Position resolution

Transverse diffusion constant

$$\sigma_x = \sqrt{\sigma_0^2 + \frac{C_d^2 \cdot z}{N_{eff}}}$$

depends on drift length

$$C_d(B, E) = \frac{1}{\sqrt{1 + (\omega\tau)^2}} C_d(0, E)$$

z: drift length
 N_{eff} : effective number of electron
 C_d : diffusion constant of gas

ω : Cyclotron frequency
 τ : mean free time

Signal electrons are affected by diffusion

† transverse diffusion makes position resolution worse

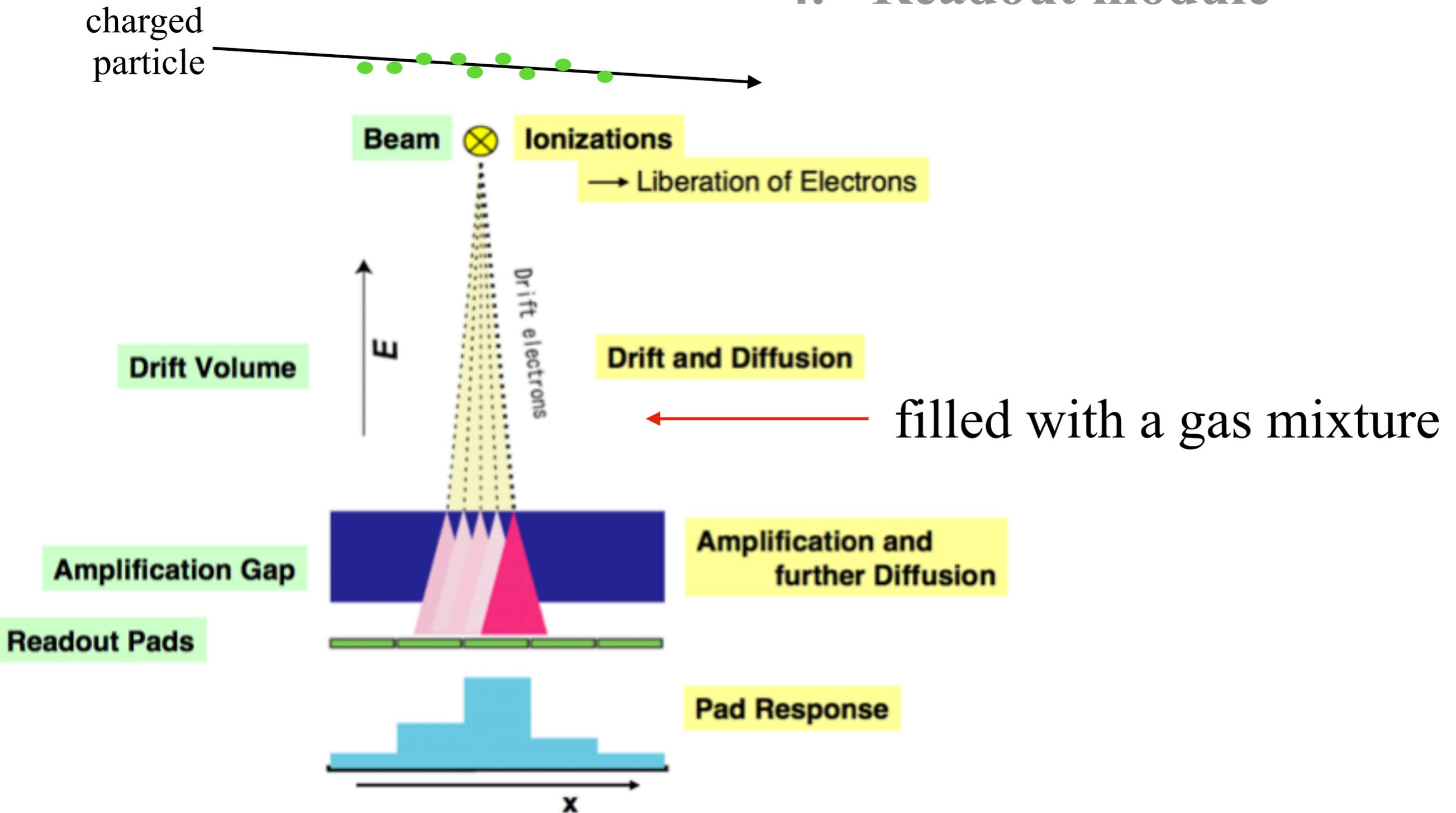
In TPC : E // B

**Lorentz force suppresses transverse diffusion of drift electrons
 by curling them around the B-Field**

Gas: small transverse diffusion in the B-Field

to achieve position resolution required by ILD-TPC

1. Momentum measurement
2. **Gas mixture**
3. Particle ID and dE/dx
4. Readout module



Gas mixture

to achieve the position resolution required by ILD-TPC

In order to reduce transverse diffusion

a gas mixture which has a large $\omega\tau$ is needed

T2K gas Ar : CF4 : iC4H10 = 95 : 3 : 2 $C_d(B, E) = \frac{1}{\sqrt{1 + (\omega\tau)^2}} C_d(0, E)$

CF4

- Ar-CF4 is a relatively fast gas

-> Large $\omega\tau$ ∴ drift velocity $\propto \tau$

- The value of $\omega\tau$ is about 11.6 with $E = 230$ V/cm and $B = 3.5$ T

(see the first paragraph of Section 5.3 in NIM A918 (2019) 41)

Gas mixture

T2K gas

Ar : CF₄ : iC₄H₁₀ = 95 : 3 : 2

The isobutane

act as a “quencher”

absorb ultraviolet photons from Ar molecules excited during

avalanche process

↳ might cause discharge and destabilise chamber operation.

bonus

A small amount of isobutane is added to obtain a high gas gain at low voltages

⇒ Penning effect

Penning effect

The Penning effect in our case:

additional ionisation of isobutane molecules by meta-stable argon atom (Ar^*)

The Penning effect

Ar: excited state energy higher than an ionisation energy of isobutane

isobutane (iC_4H_{10}) with a low-ionisation potential

$$I_{\text{Isobutane}} = 10.67 \text{ eV} <$$

Argon:

Excitations:

- 11.55 eV (S)
- 13.0 eV (P)
- 14.0 eV (D)



additional electron!!

high gas gain at low voltages

Transverse diffusion

$$D(B, E) = \frac{1}{\sqrt{1 + (\omega\tau)^2}} D(0, E)$$

ω depends only on B

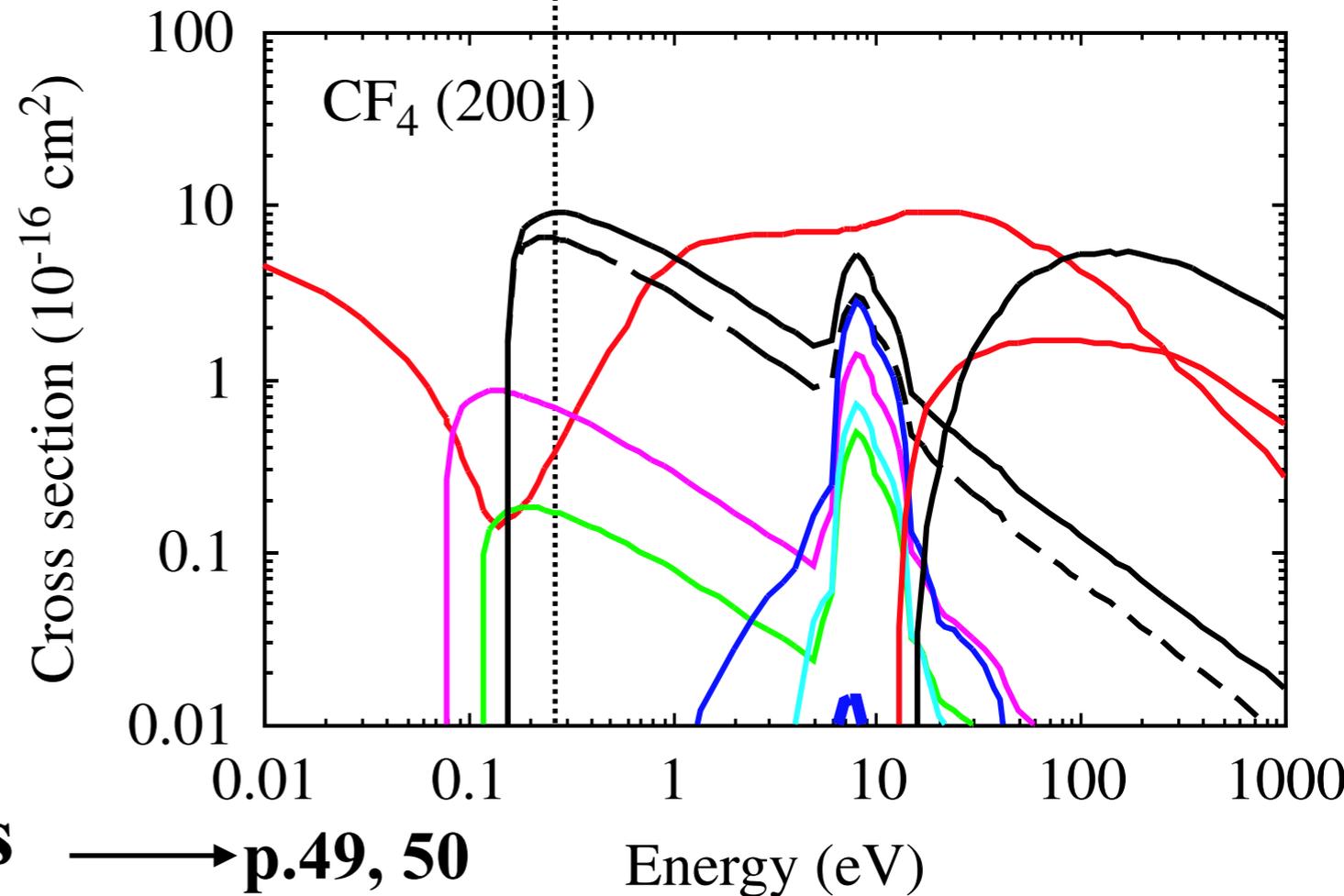
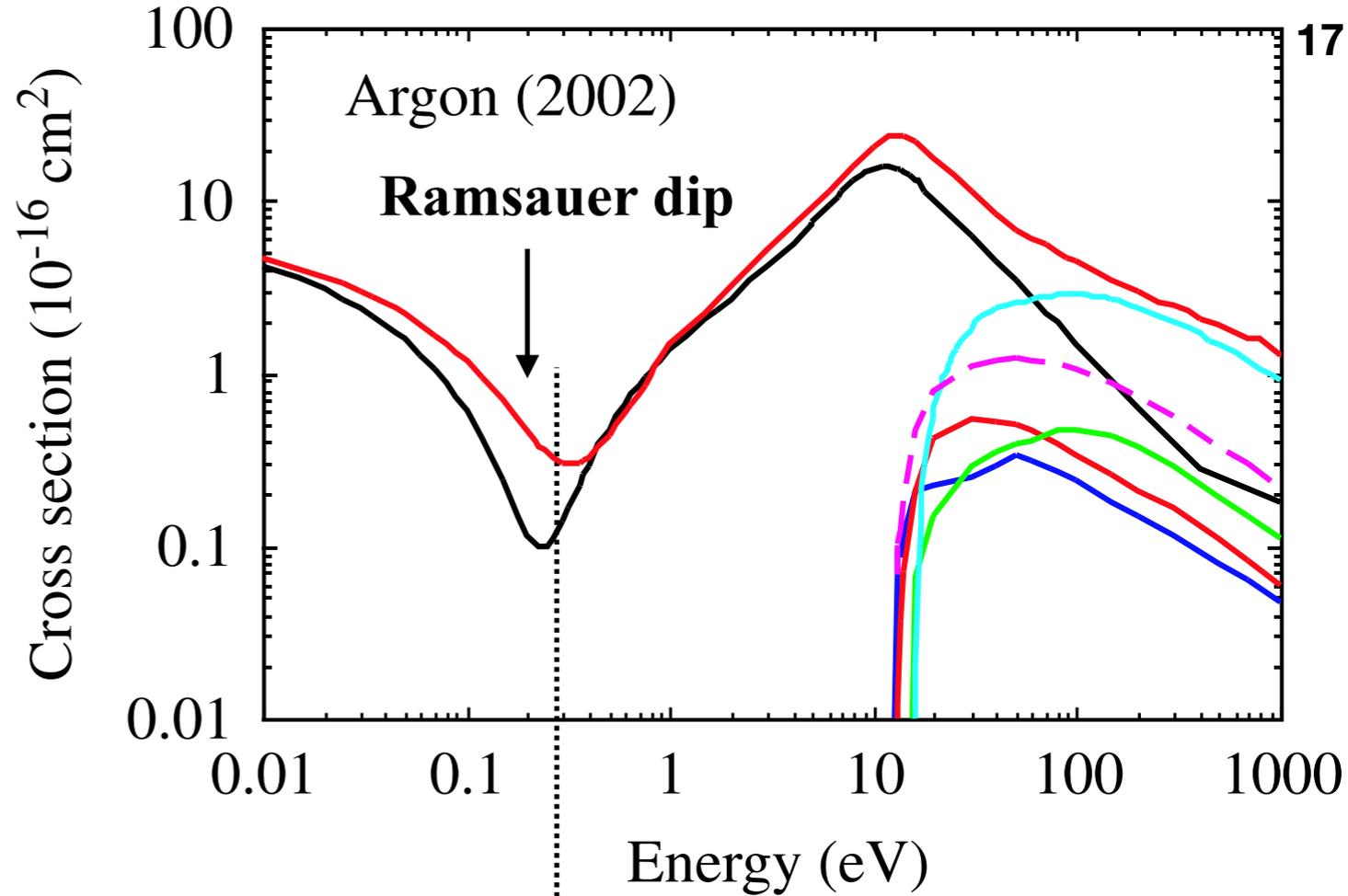
large τ gas is needed!

$$\tau \propto \sigma^{-1}$$

σ : cross-section

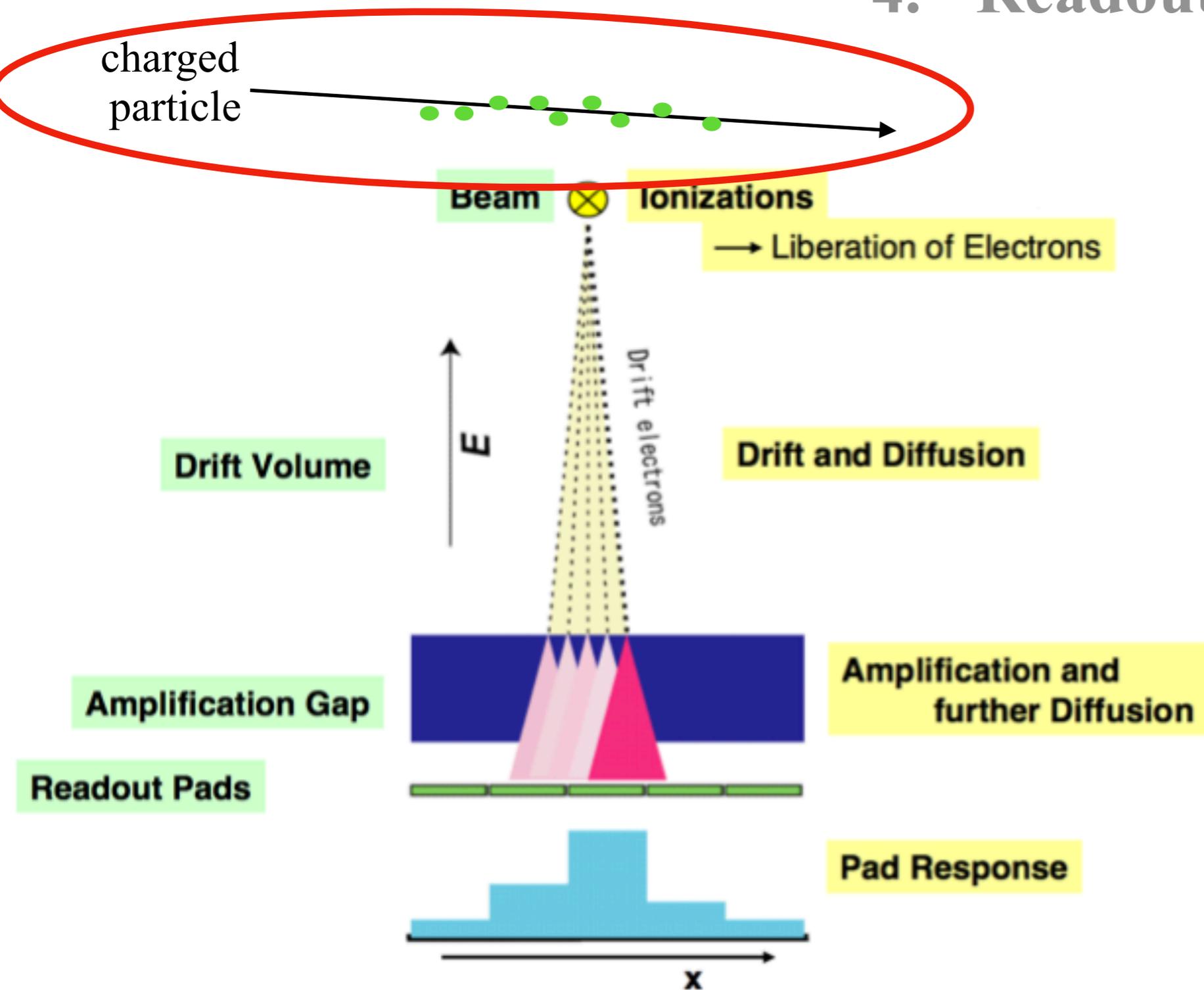
CF4 has a much larger cross-section to electrons with energies near the Ramsauer dip

we can obtain large τ gas by adding CF4 to Ar-based gas



→ p.49, 50

1. Momentum measurement
2. Gas mixture
3. **Particle ID and dE/dx**
4. Readout module



Particle identification

⊙ charged particle pass -> detect as track

main charged particle on the detector

- π
- K
- e
- μ

from the direction of bending
by a B-Field

charge can be identified

particle type

dE/dx : Energy loss per unit length

Bethe-Bloch formula

$$\left\langle -\frac{dE}{dx} \right\rangle = Kz^2 \frac{Z}{A} \frac{1}{\beta^2} \left[\frac{1}{2} \ln \frac{2m_e c^2 \beta^2 \gamma^2 W_{max}}{I^2} - \beta^2 - \frac{\delta(\beta\gamma)}{2} \right]$$

the value of $\langle dE/dx \rangle$ depends on
particle species at a given momentum

→ particle type can be identified

Bethe-Bloch formula

$$\left\langle -\frac{dE}{dx} \right\rangle = K z^2 \frac{Z}{A} \frac{1}{\beta^2} \left[\frac{1}{2} \ln \frac{2m_e c^2 \beta^2 \gamma^2 W_{max}}{I^2} - \beta^2 - \frac{\delta(\beta\gamma)}{2} \right]$$

material parameter

Z, A: atomic, mass number of material I: ionization energy

charged particle parameter

z : particle charge in units of e β, γ : relativistic parameter

non-relativistic region

$$\beta\gamma < 4$$

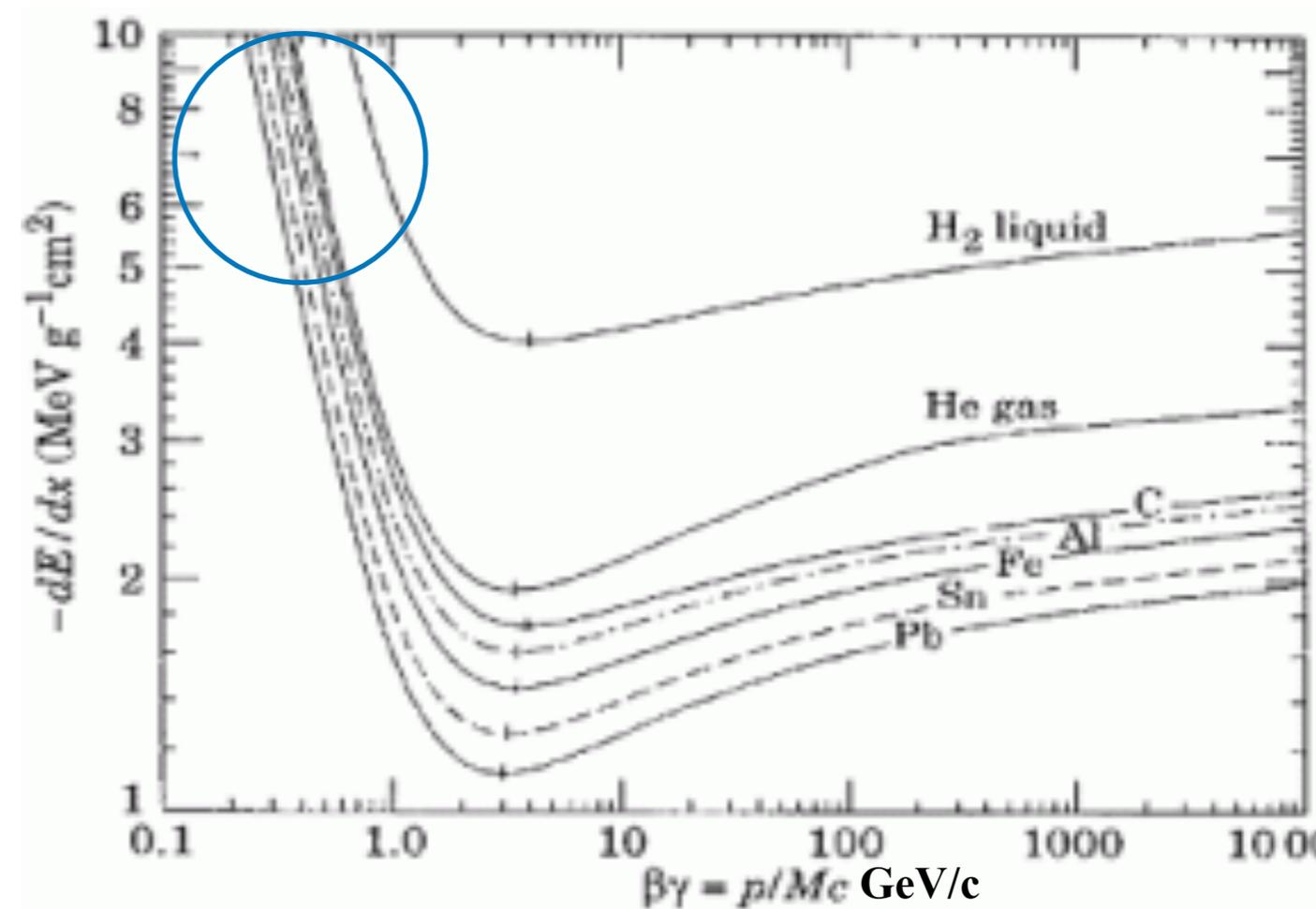
$$\left\langle -\frac{dE}{dx} \right\rangle \propto \frac{1}{\beta^2}$$

“kinematical term”

LARGE ionisation

slower particles receive an electric force from atomic electrons for a longer time

non-relativistic description of scattering of charged particles with electrons of gas molecules



Minimum ionisation particle (MIP)

$$\left\langle -\frac{dE}{dx} \right\rangle = K z^2 \frac{Z}{A} \frac{1}{\beta^2} \left[\frac{1}{2} \ln \frac{2m_e c^2 \beta^2 \gamma^2 W_{max}}{I^2} - \beta^2 - \frac{\delta(\beta\gamma)}{2} \right]$$

material parameter

Z, A: atomic, mass number of material I: ionization energy

charged particle parameter

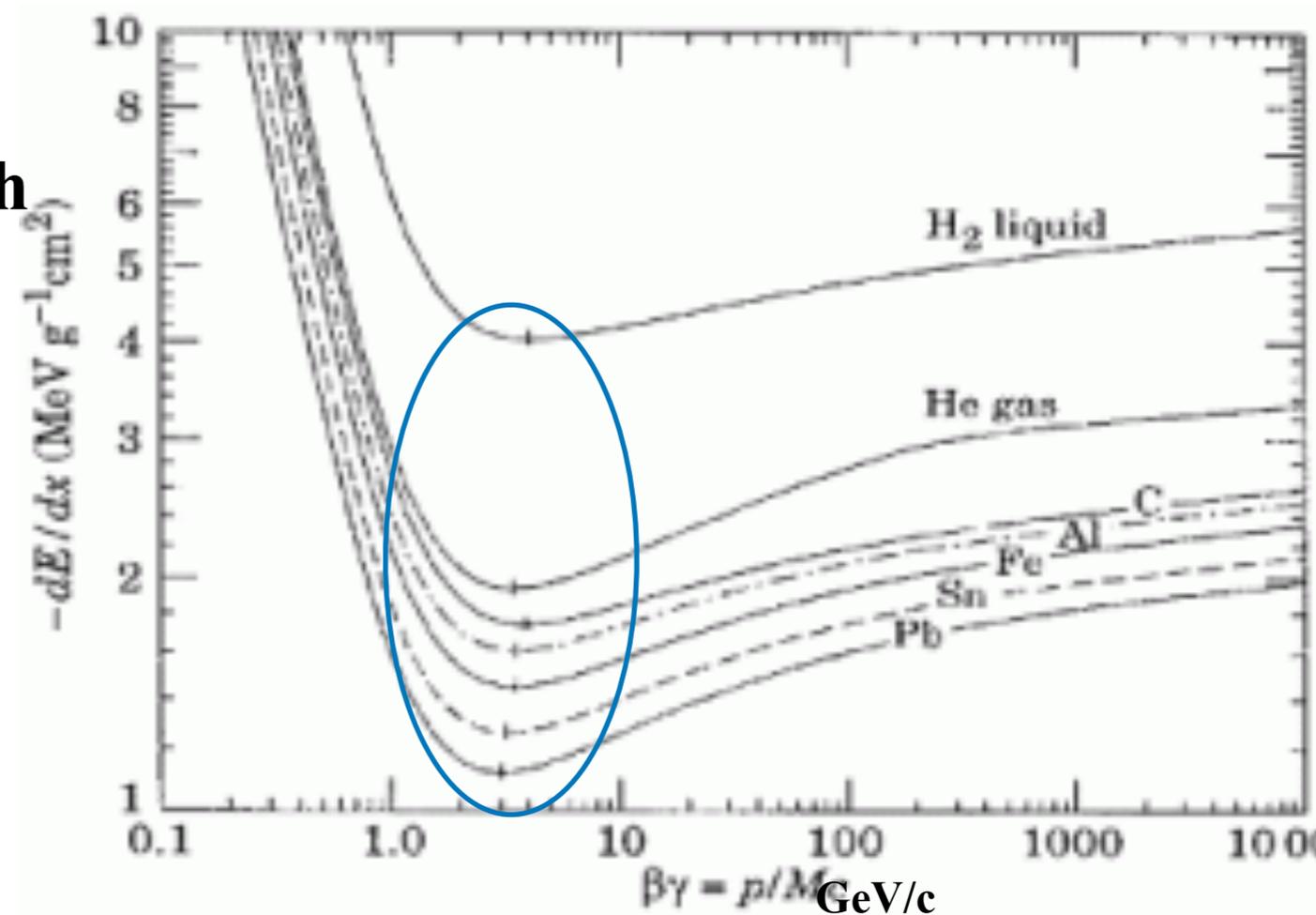
z : atomic number of charged particle β, γ : relativistic parameter

$$\beta\gamma \approx 4$$

Particles pass through a substance with a minimum ionisation loss

minimum ionizing particle
(MIP)

e.g. cosmic-ray muon

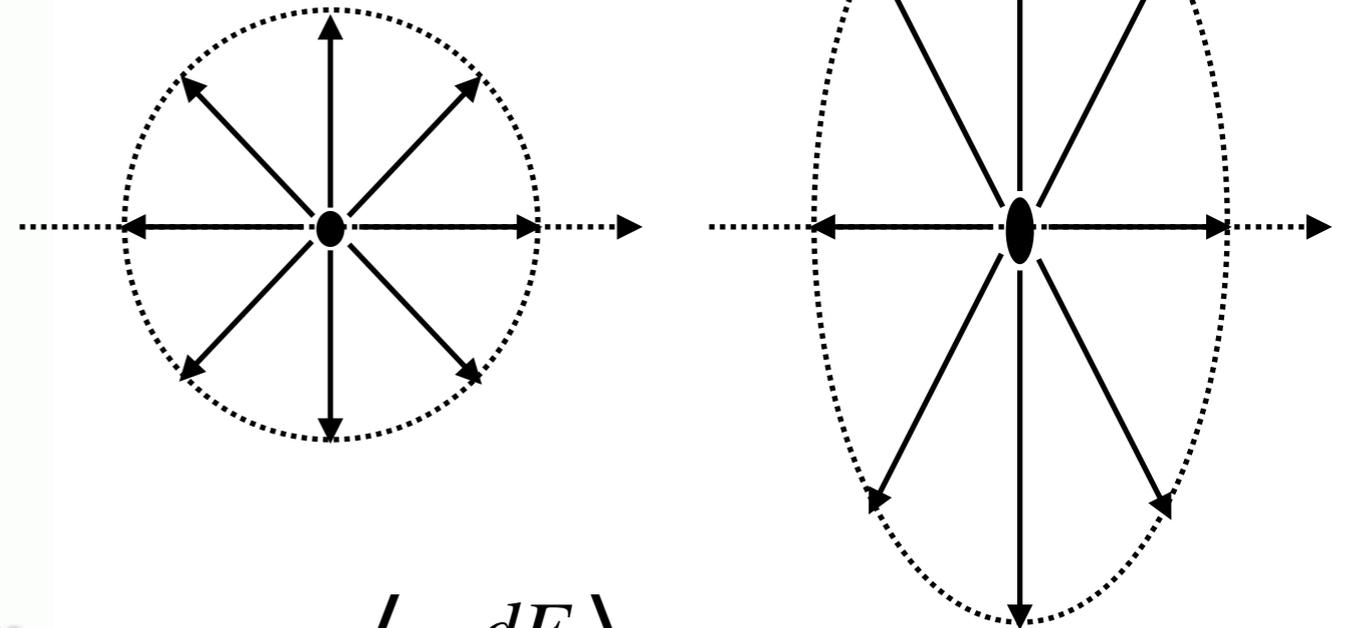
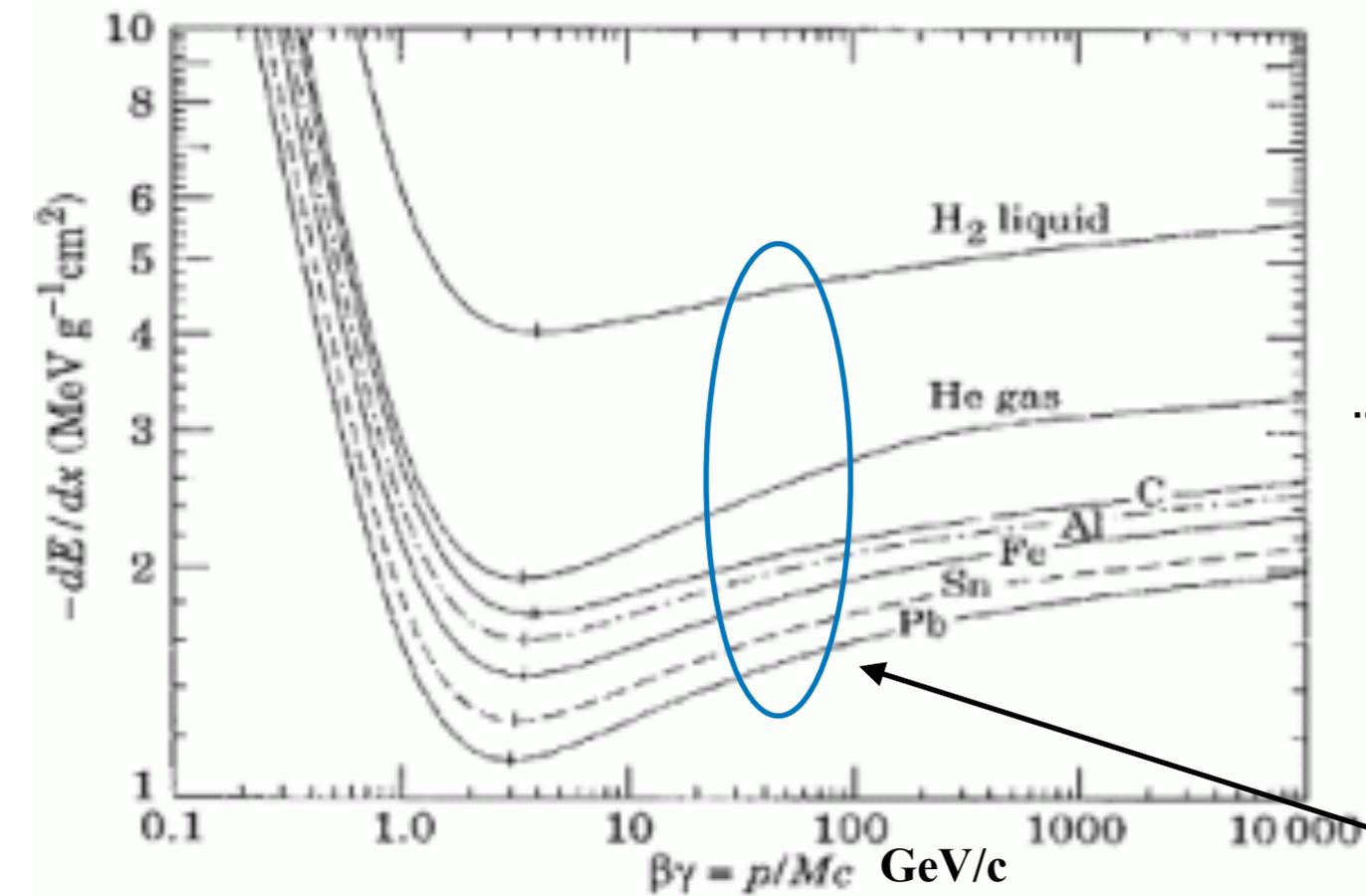


Relativistic effect

$$\left\langle -\frac{dE}{dx} \right\rangle = K z^2 \frac{Z}{A} \frac{1}{\beta^2} \left[\frac{1}{2} \ln \frac{2m_e c^2 \beta^2 \gamma^2 W_{max}}{I^2} - \beta^2 - \frac{\delta(\beta\gamma)}{2} \right]$$

$\beta \sim 0$

$\beta \sim 1$



$$\left\langle -\frac{dE}{dx} \right\rangle \propto \ln \beta^2 \gamma^2$$

“relativistic rise”

relativistic effect

**the energy loss of fast moving particles increases
because the transverse electric field extends by relativistic effect**

Density effect

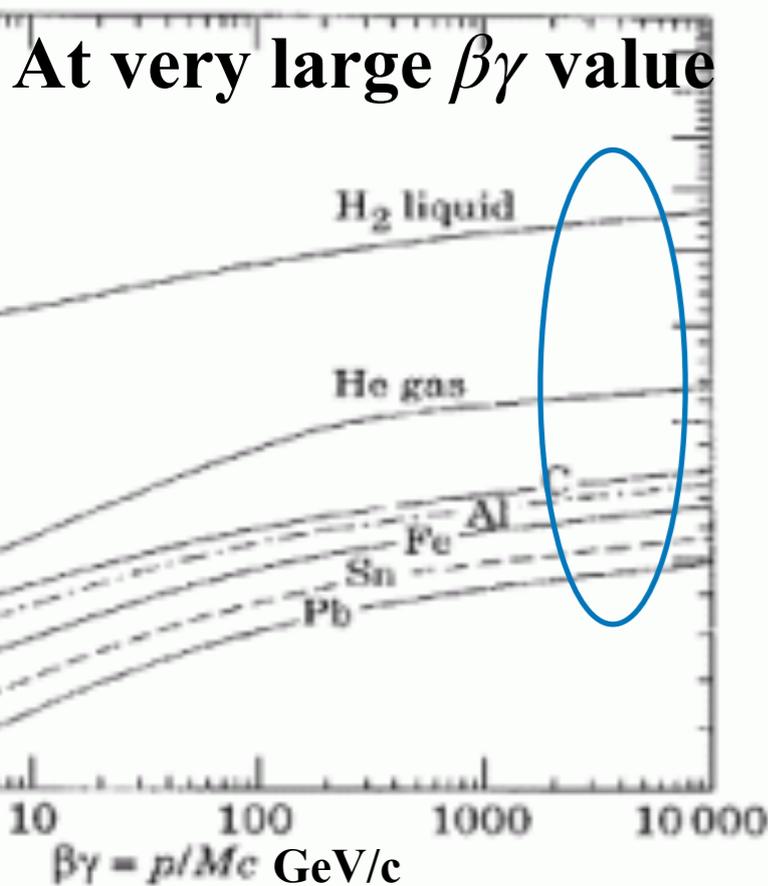
$$\left\langle -\frac{dE}{dx} \right\rangle = K Z^2 \frac{Z}{A} \frac{1}{\beta^2} \left[\frac{1}{2} \ln \frac{2m_e c^2 \beta^2 \gamma^2 W_{max}}{I^2} - \beta^2 \frac{\delta(\beta\gamma)}{2} \right]$$

relativistic rise stops

energy loss becomes independent of $\beta\gamma$

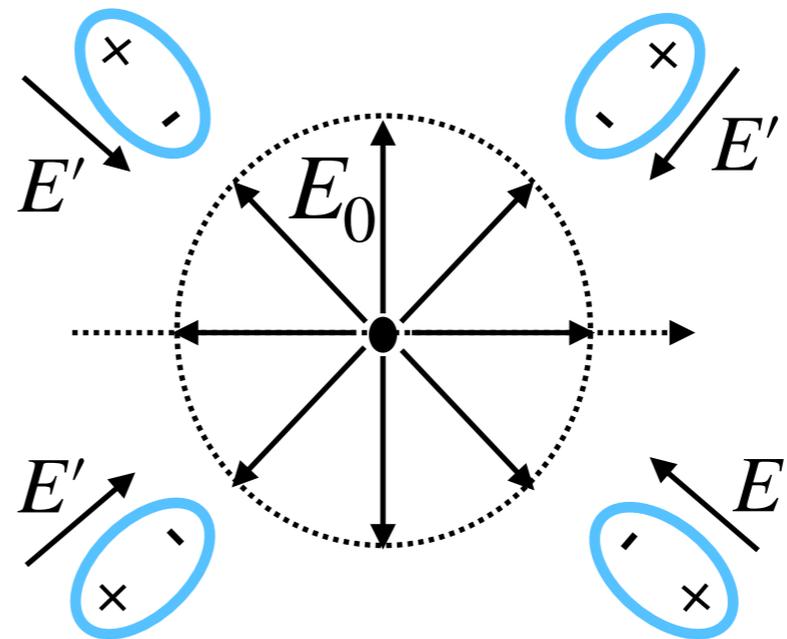
"Fermi plateau"

At very large $\beta\gamma$ value



electric field of the moving particles tends to polarise the atoms along its path

electrons far from this moving particles will be shielded



transverse size of the electric field are limited by polarisation of gas medium

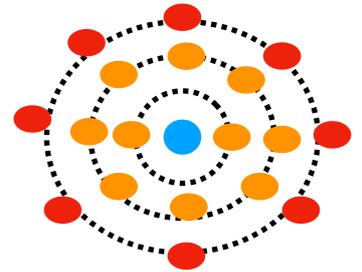
this polarisation of gas medium depends on its "density"

"density effect"

Landau distribution

energy loss calculated by **Bethe-Bloch** formula is the “average” energy loss

In very thick materials, the number of scattering with electrons increases
→ a symmetric Gaussian distribution

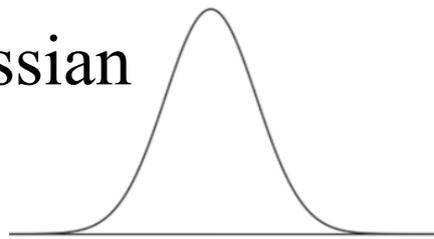


In very thin materials, the number of scattering with electrons decreases

● electrons of the outermost shell
binding energy small
easily ionised

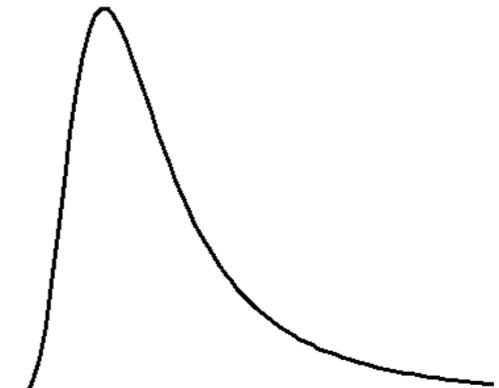
● electrons of the inner shell
binding energy Large
rarely ionised

Gaussian

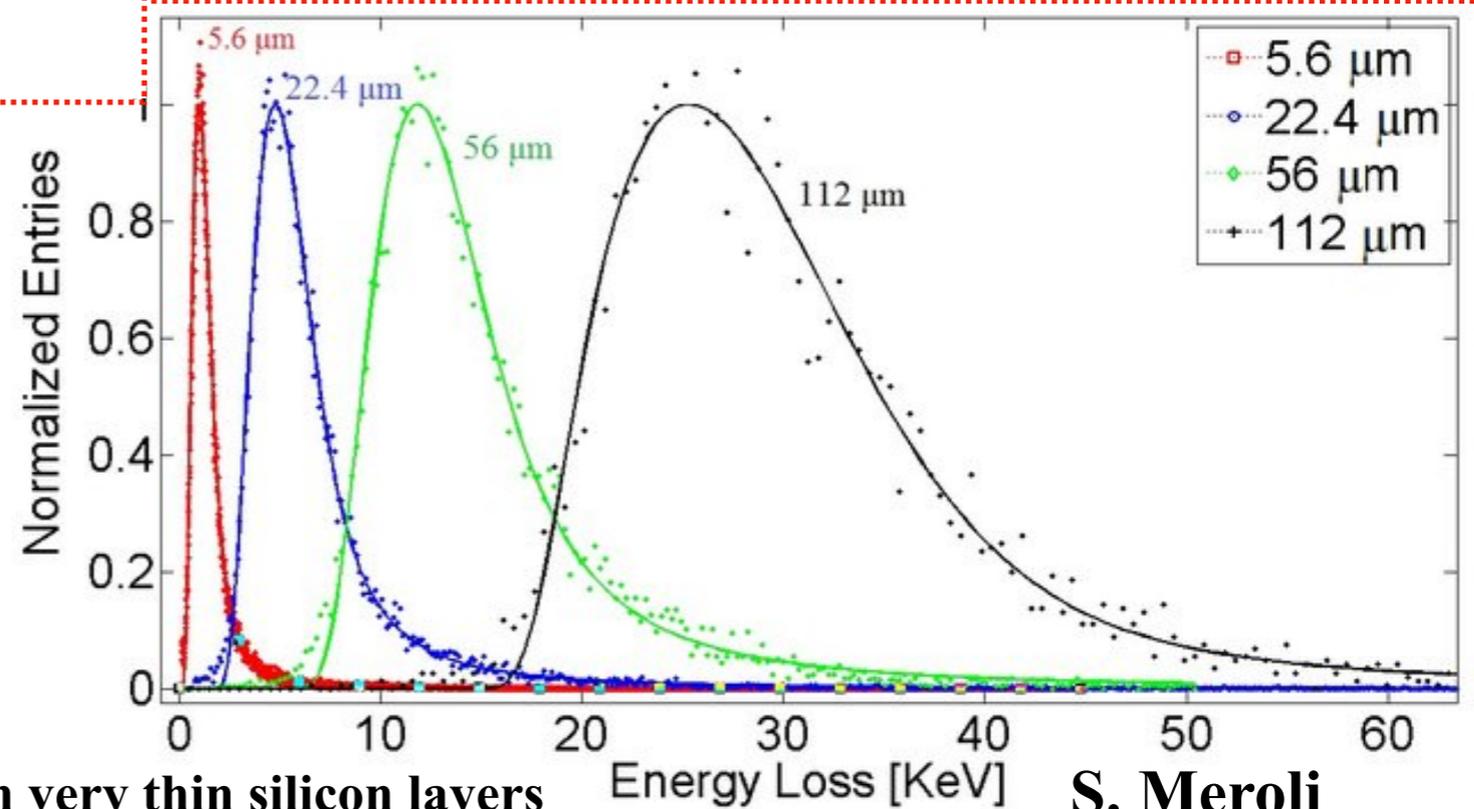


long tail distribution

Convolution



The distribution of energy loss will be an asymmetric Landau distribution with a long tail



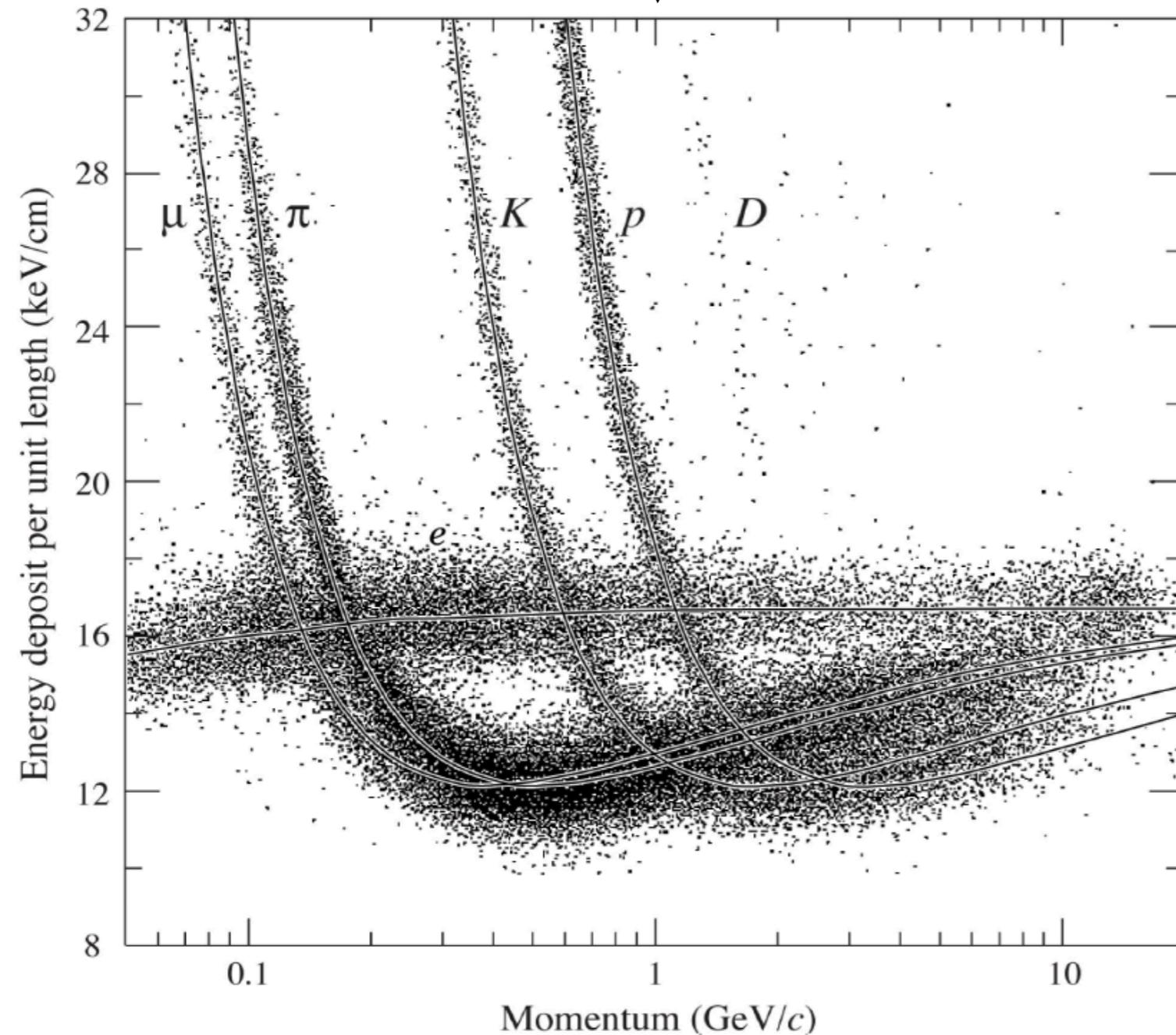
Particle identification

function of $\beta\gamma = p/M$: same distribution
regardless of particle type

plot with function of $p = M\beta\gamma$



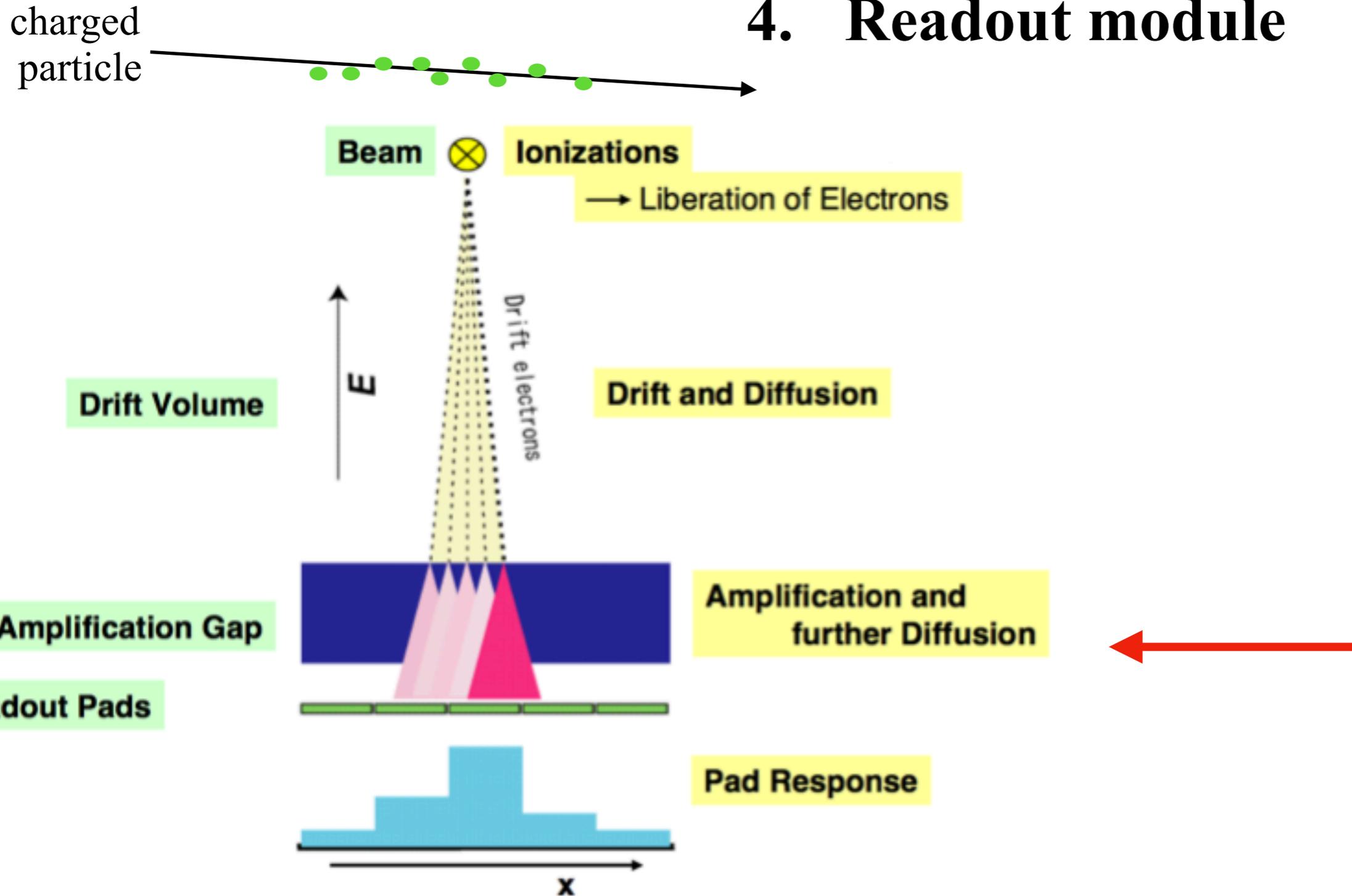
shift according to
particle type



Particle ID using the specific
ionization loss is possible at
LOW MOMENTA

(PEP4/9-TPC energy deposit measurement)
Physics Letters B667 (2008) 1
available on the PDG WWW page

1. Momentum measurement
2. Gas mixture
3. Particle ID and dE/dx
4. **Readout module**



Readout module

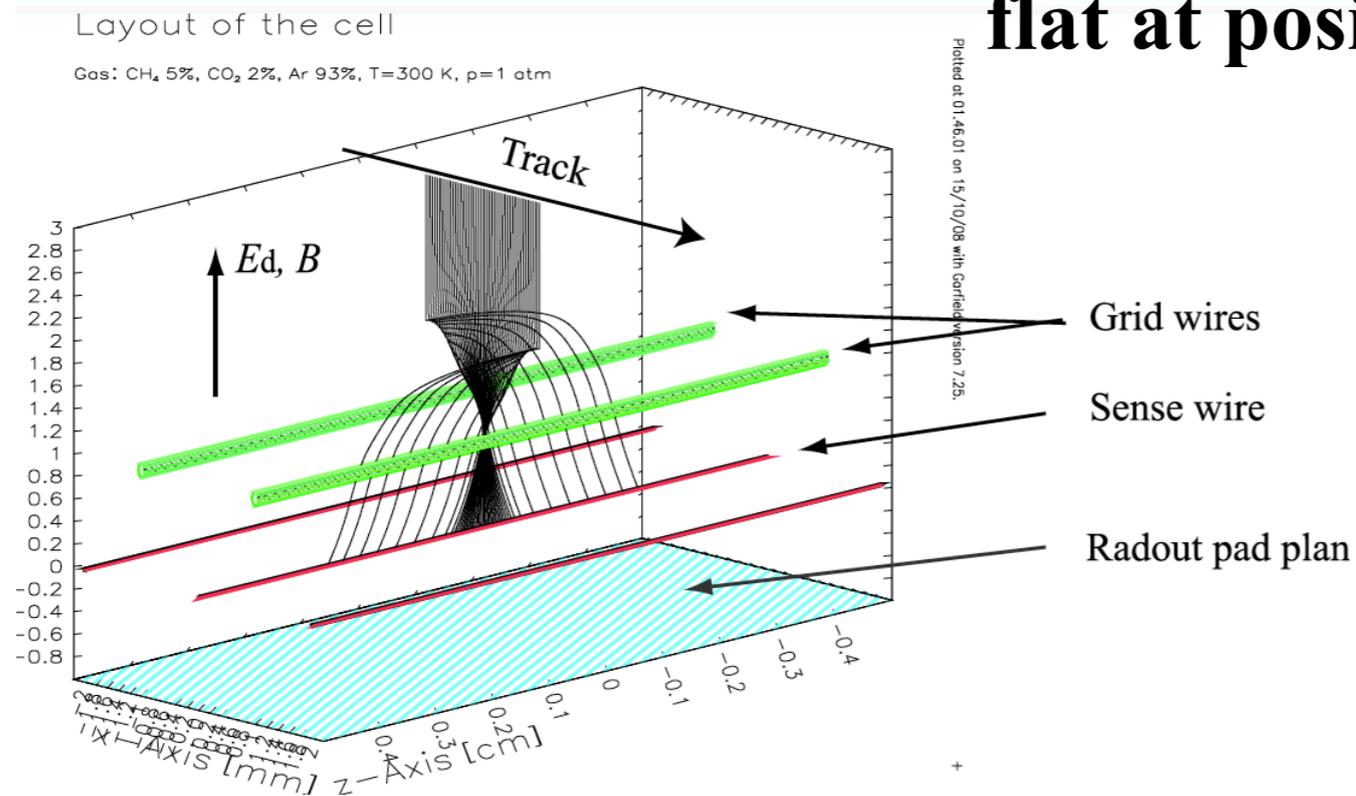
MWPC (Multi-Wire Proportional Chamber)
has been used in various experiments

ILD: B-field = 3.5T

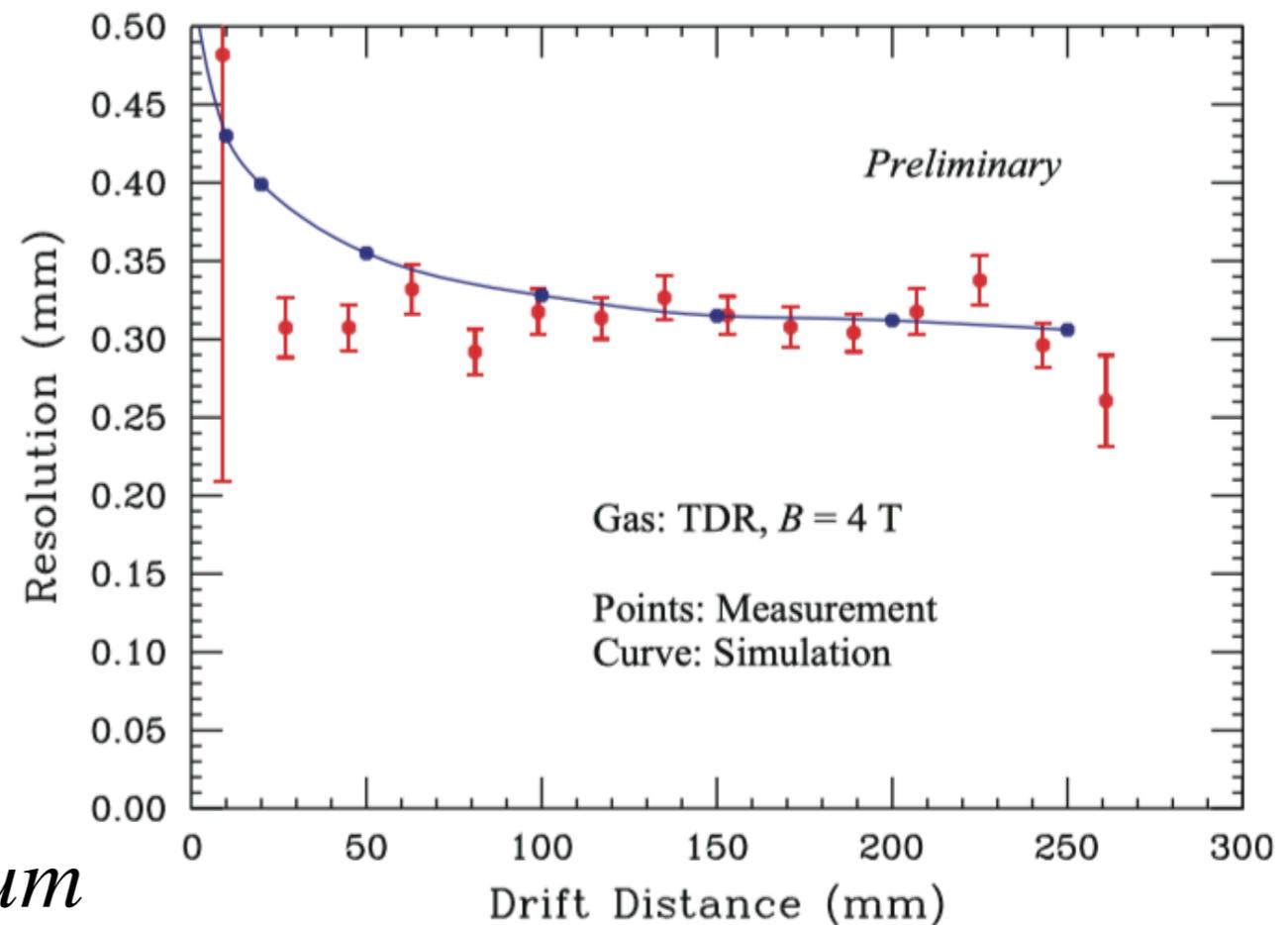
→ **$E \times B$ effect: bend the electron drift path near the wire** → p.48

the spread of drift electron is VERY LARGE under a strong axial B

TPC using MWPC



flat at position resolution of about 300 μm



MWPC cannot achieve

ILD requirement $\sigma_x \approx 100 \mu\text{m}$

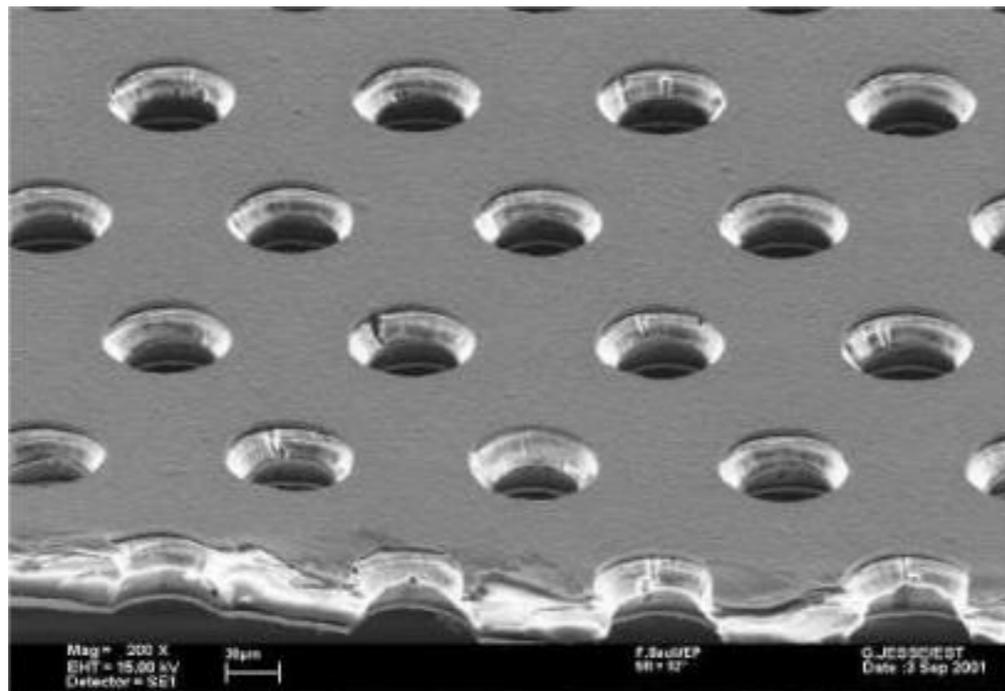
Readout module

MPGD (Micro-Pattern Gas Detector)

Gas detector using PCB(Printed Circuit board) etching technology

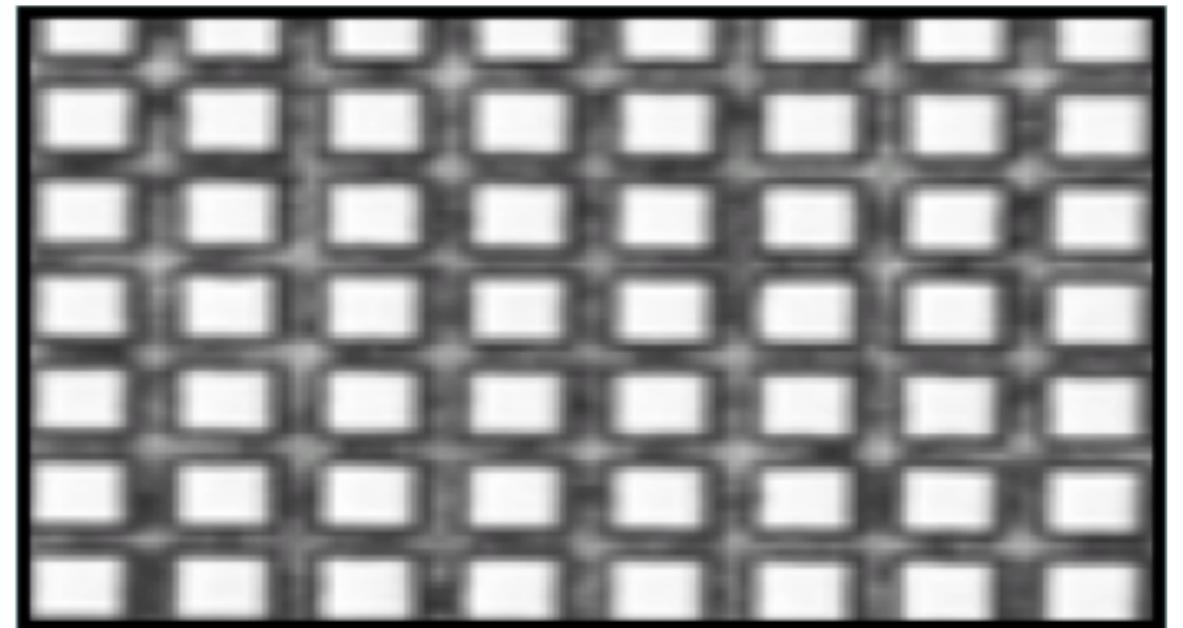
example of
MPGD

GEM



F.Sauli, NIM A 386(1997)531

MICROMEAS



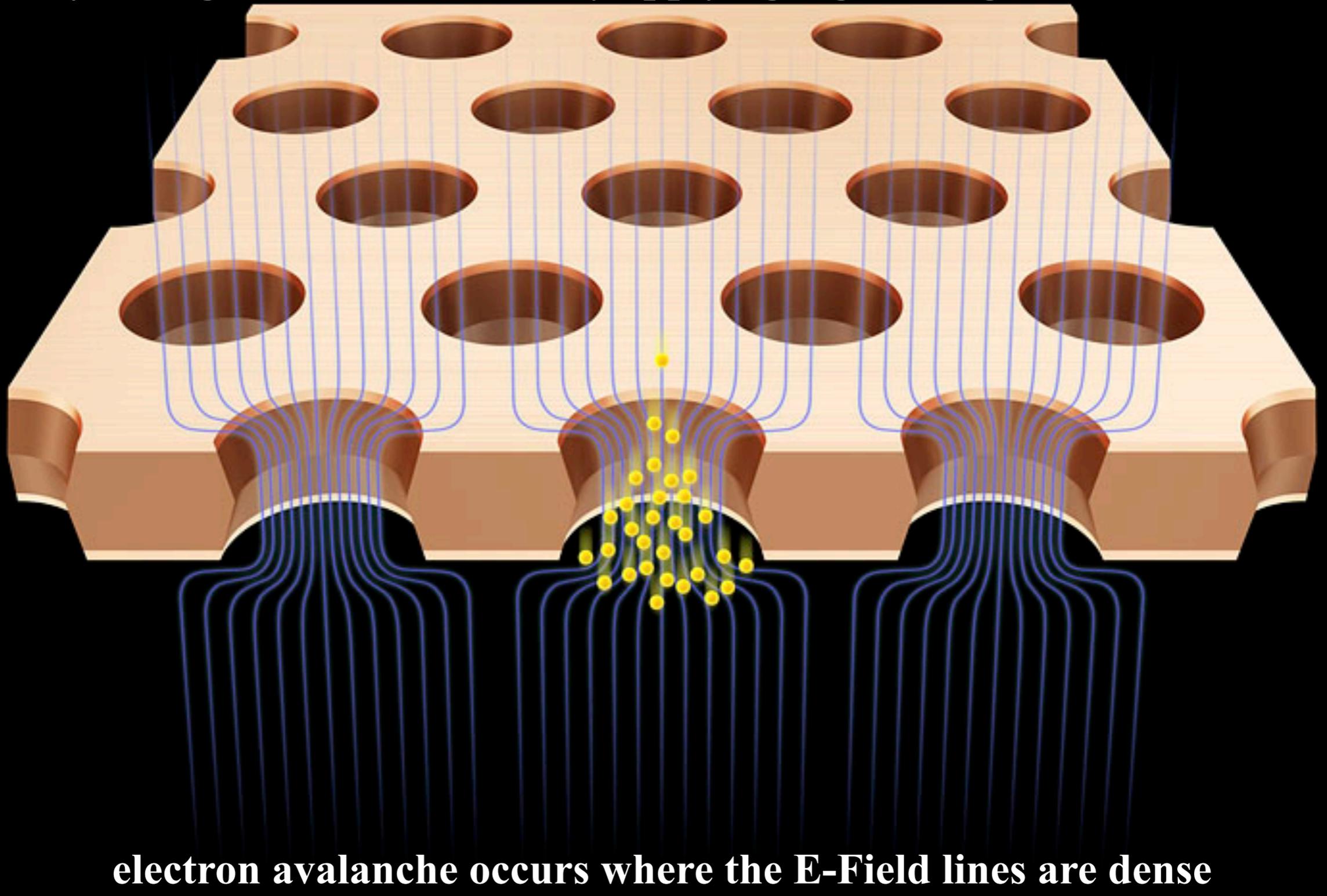
E×B effect is suppressed even in a high B-Field

the position resolution is good!

Amplification

very strong E-Field is formed by applying high voltage

© Rey.Hori/KEK



electron avalanche occurs where the E-Field lines are dense

The avalanche gas gain depends on the high voltage
and generally increases with the high voltage

Positive ions are also produced

Gas gain

The dependence of the gas gain M in the electric field

$$\log M = \int \alpha(E(s)) ds \quad \text{or} \quad M = e^{\int \alpha(E(s)) ds}$$

s along field line

where $\alpha(s)$ is the first Townsend coefficient

mean free path of the electron between ionising collision

in the case of Penning gas

the first Townsend coefficient

$$\alpha(s) \rightarrow (1 + r) \alpha(s) \quad \text{where } r \text{ is the penning transfer rate}$$

depends on gas mixture

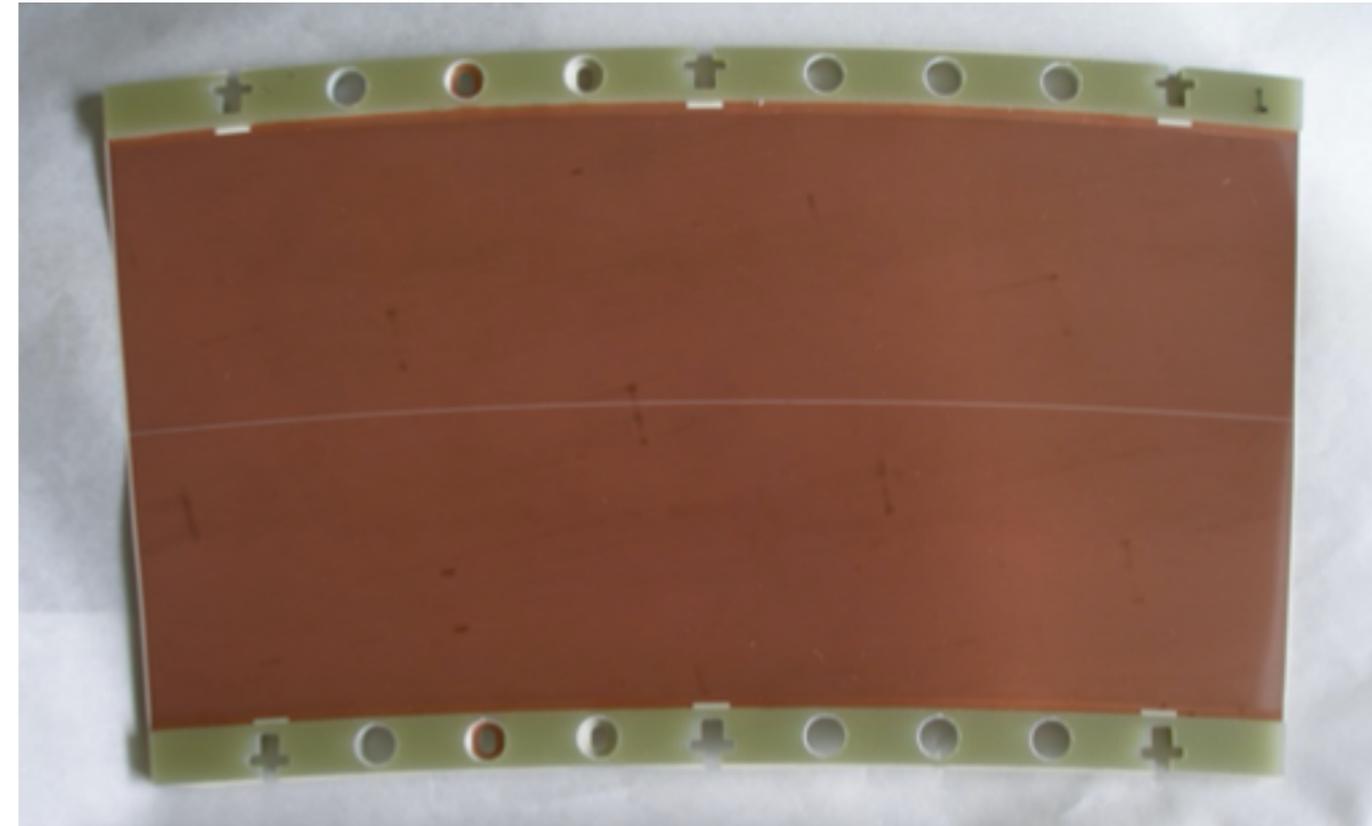
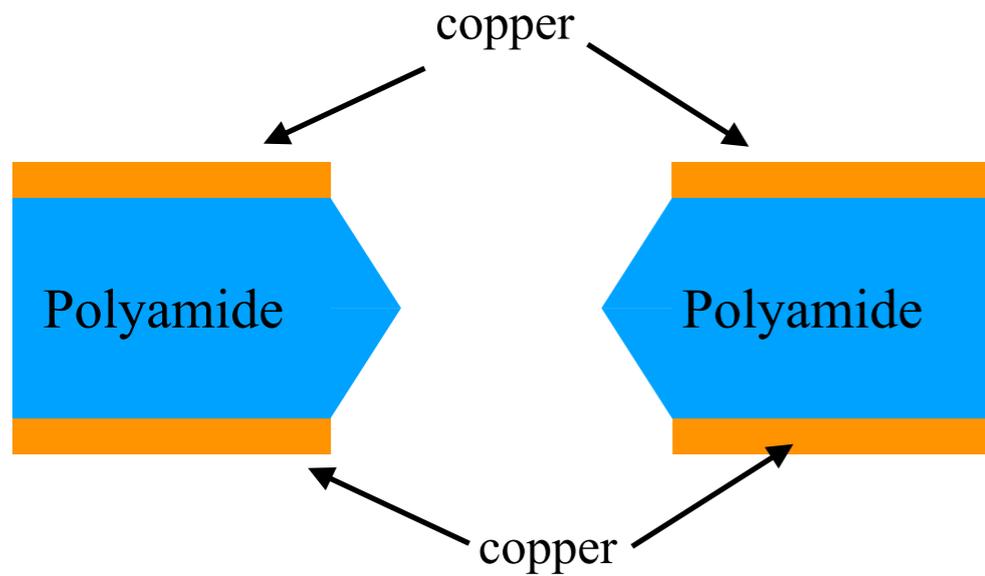
Gas gain for Penning Gas

$$M = e^{\int (1+r) \alpha(E(s)) ds}$$

ILC-TPC R&D

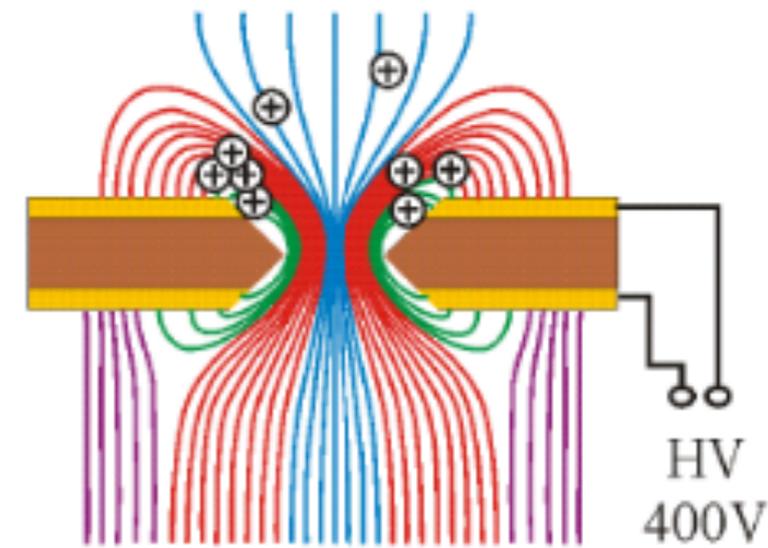
To develop a high-performance GEM as a detector for LCTPC

Asian-GEM



- fast signals $\sim \mathcal{O}(10 \text{ ns}) \rightarrow$
 - time resolution
 - 2-track separation
- Gas amp region is small \rightarrow good position resolution
- prevent positive ions to go into drift region

good!



To develop a high-performance GEM as a detector for LCTPC

Our Asian-GEM has still some problems

- discharge
- need for support structure
- gas gain fluctuations due to bending of GEM

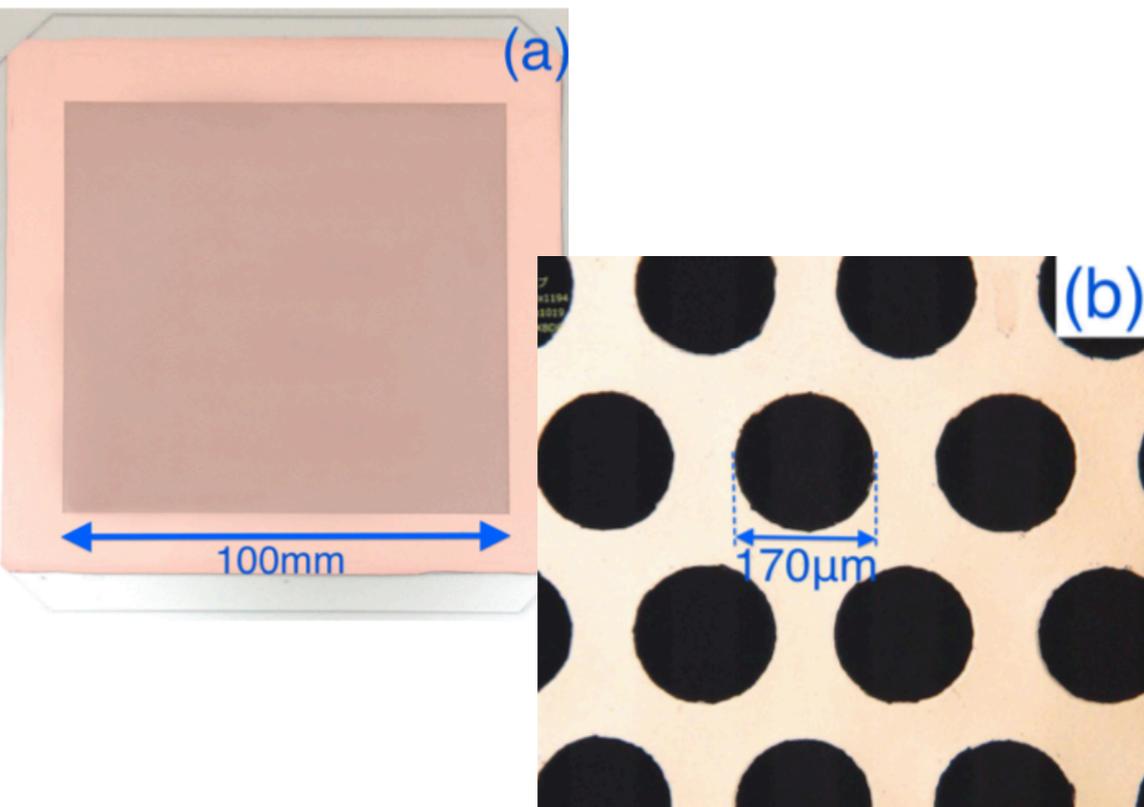
One solution to solve these problems is to use GEM with stiff insulating material

Insulation material of GEM

GEM is vulnerable to discharges: a single (large) discharge could be fatal
 => Looking for new insulator material

Glass GEM

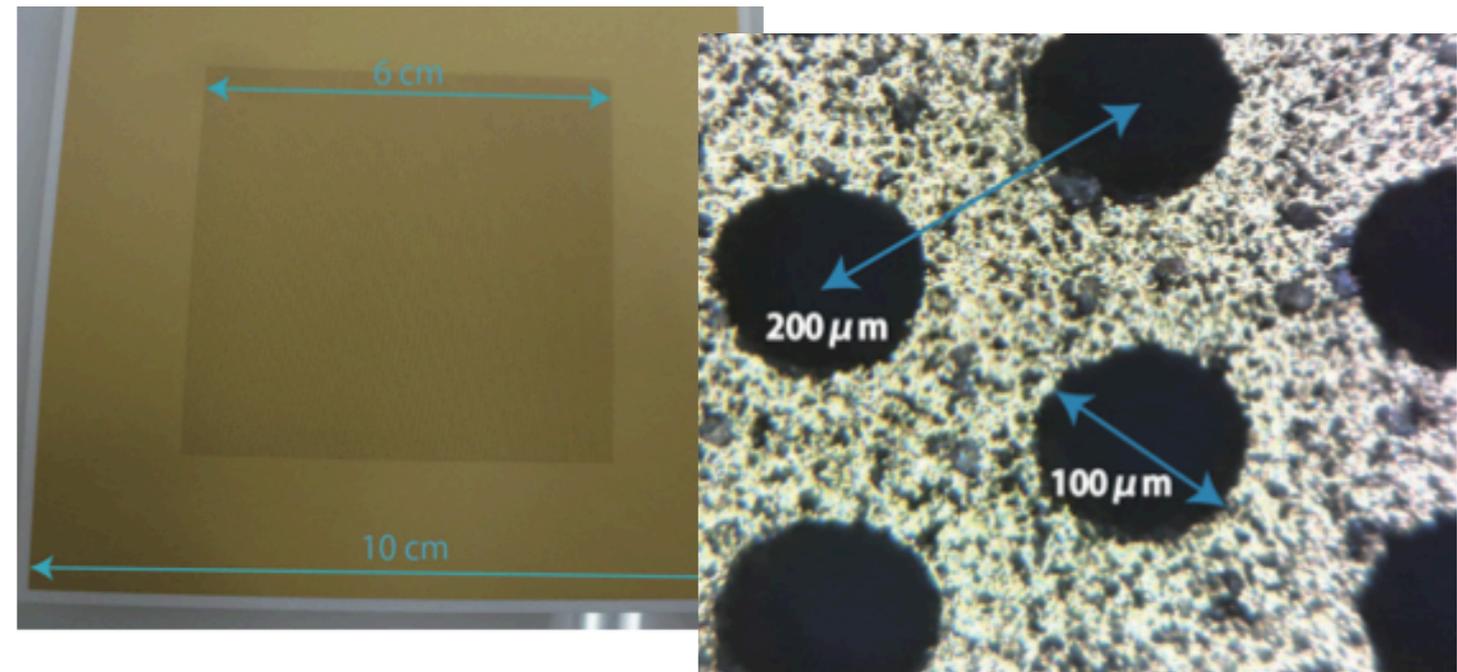
Using glass instead of polyimide



T. Fujiwara et al 2014 JINST 9 P11007

LTCC

Low Temperature Co-Fired Ceramics



Yukihiro Kato 2020 J. Phys.: Conf. Ser. 1498 012010

No outgassing

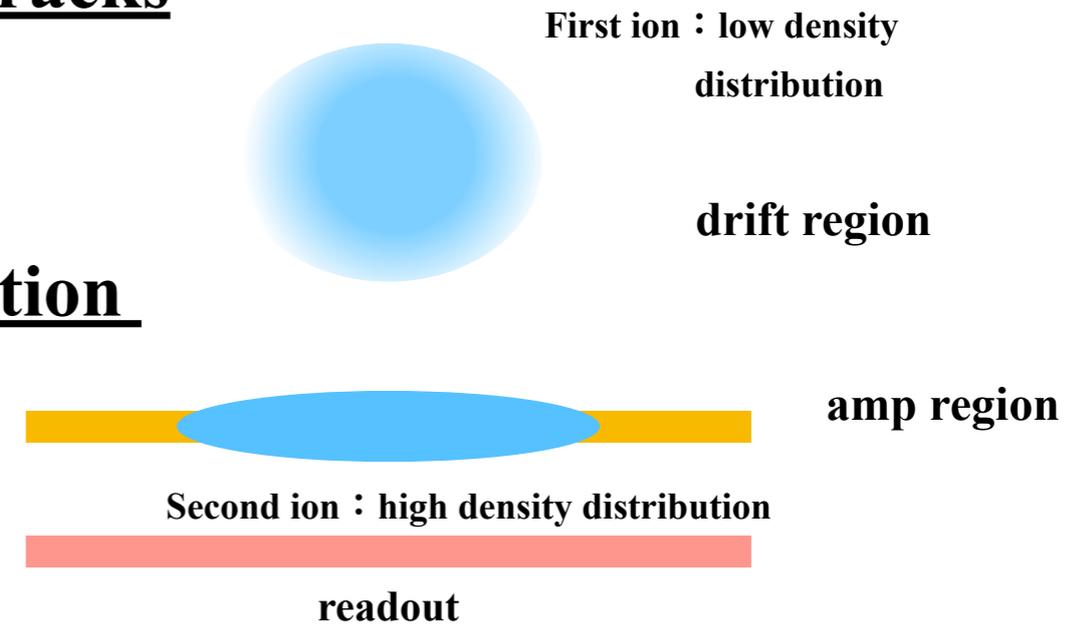
High gain with only one stage

LTCC or G-GEM is a thin but stiff “plate”: self-supporting without tension applied

Ion Backflow

Primary ion : Created along charged particle tracks
distributed over the drift volume

Secondary ion : Created during the gas-amplification
form 2-3 high density thin disks



Backward drift region moves to cathode

drift velocity of ion is **VERY SLOW** (about $\mathcal{O}(10^{-4})$ of electron)

The ion disks create a radial component of the E-field,
the drift electrons are **deflected** azimuthally due to the $\mathbf{E} \times \mathbf{B}$ effect.

effect on position resolution

effect of primary ion is negligible
secondary ion cannot be ignored **60 μm**

The positive ion back-flow needs to be blocked by a gating device
since the deflection could be $\mathcal{O}(1 \text{ mm})$ in our case.

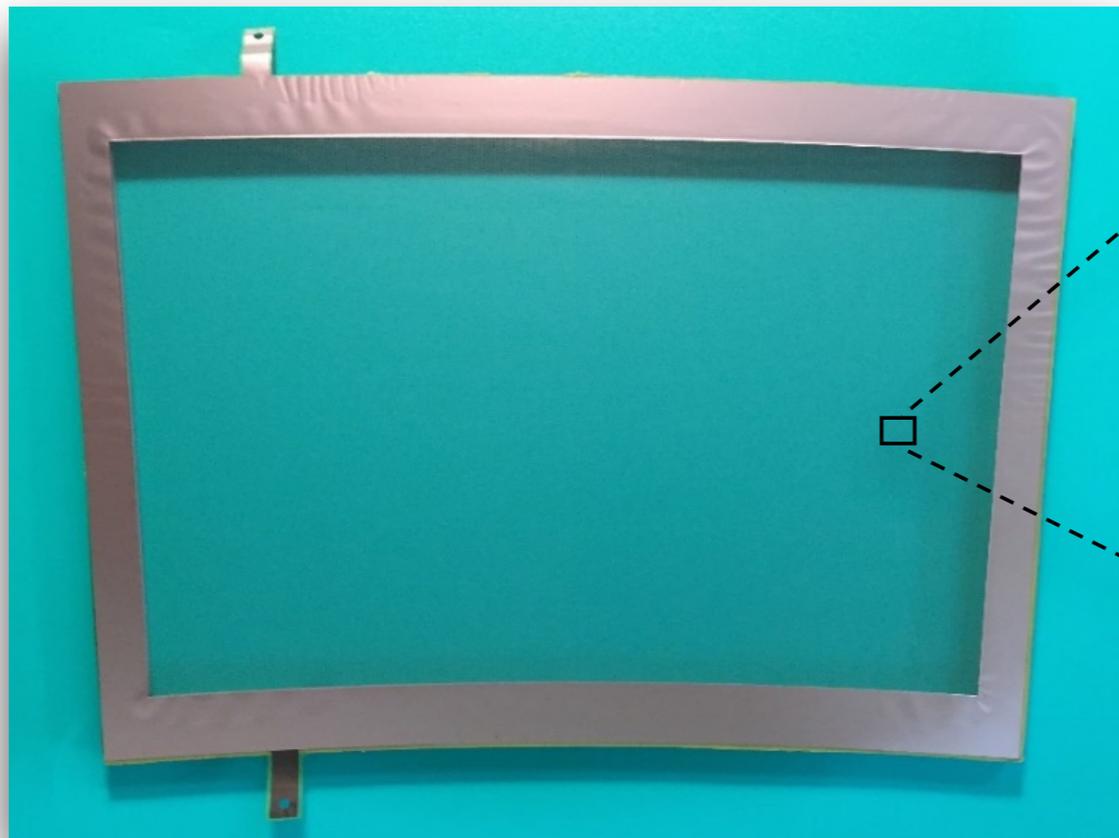
Gating foil

positive ions :

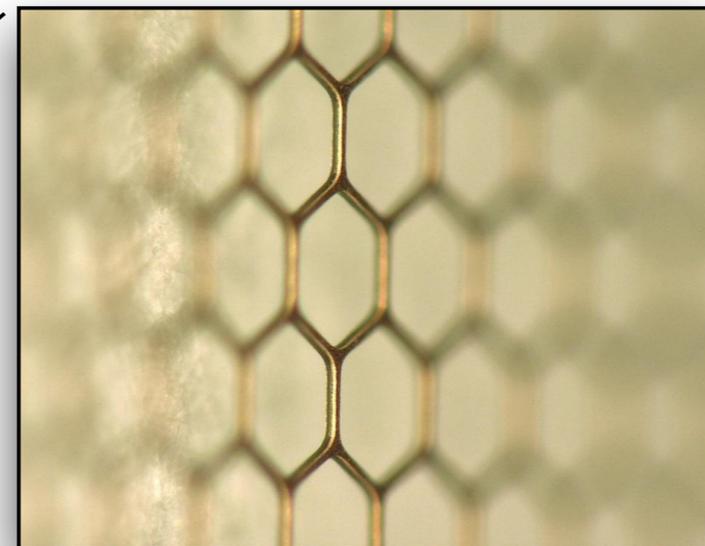
- much heavier than electrons
- moves along electrical flux line

Low diffusion

using GEM under low voltage -> positive ion blocking membrane



co-developed with Fujikura Co., Ltd.



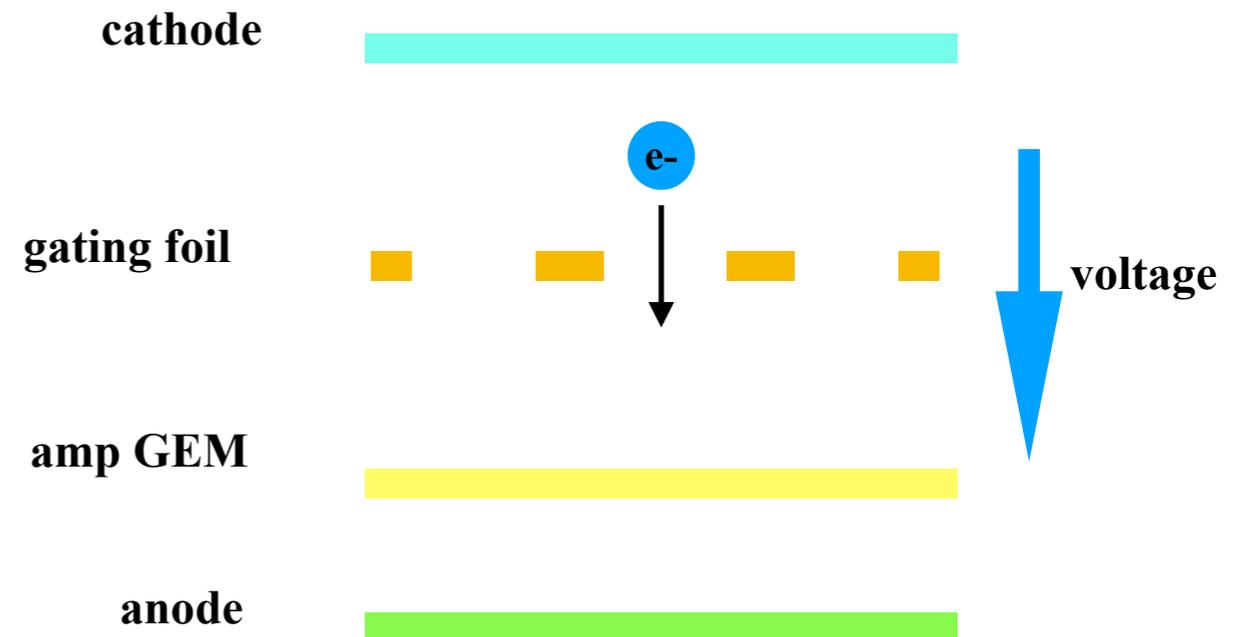
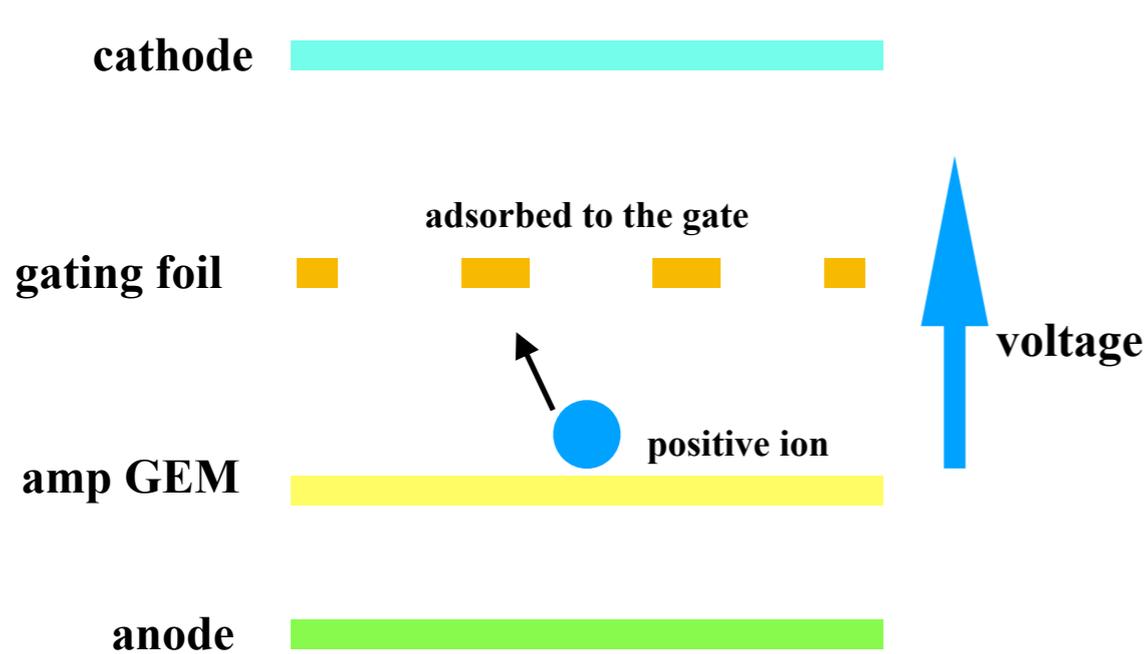
Gating foil • • • High electron transmission rate

suppress ion transmission

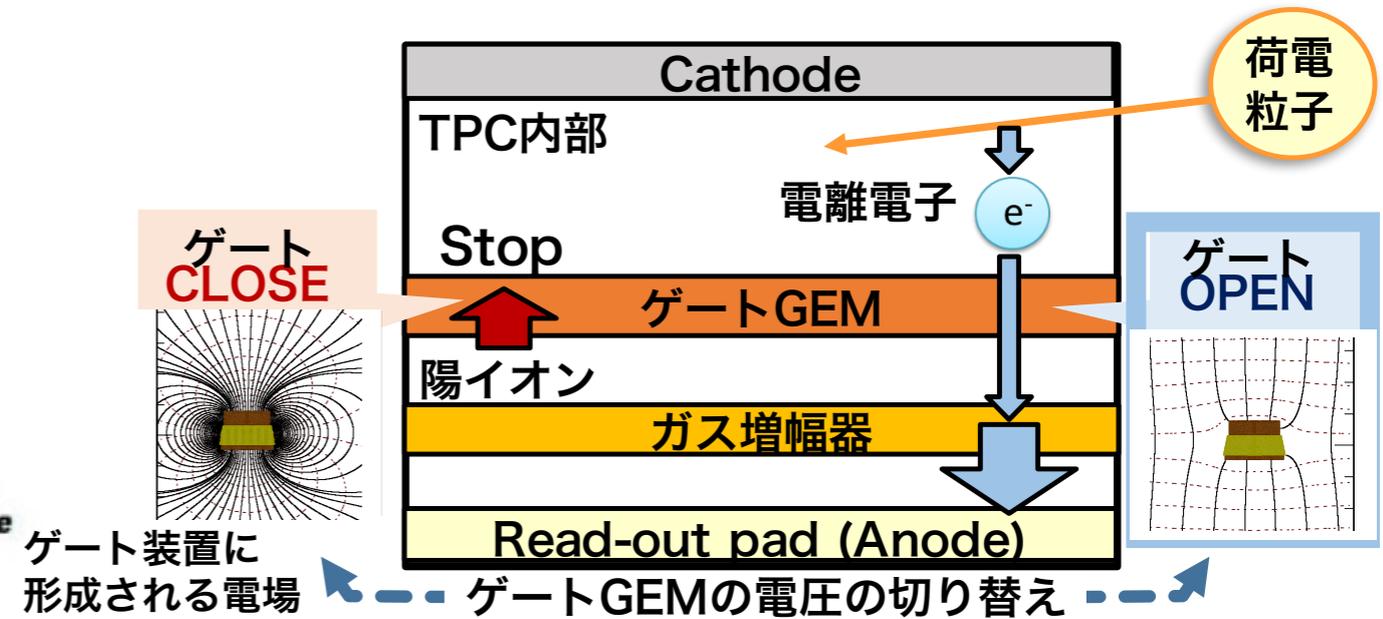
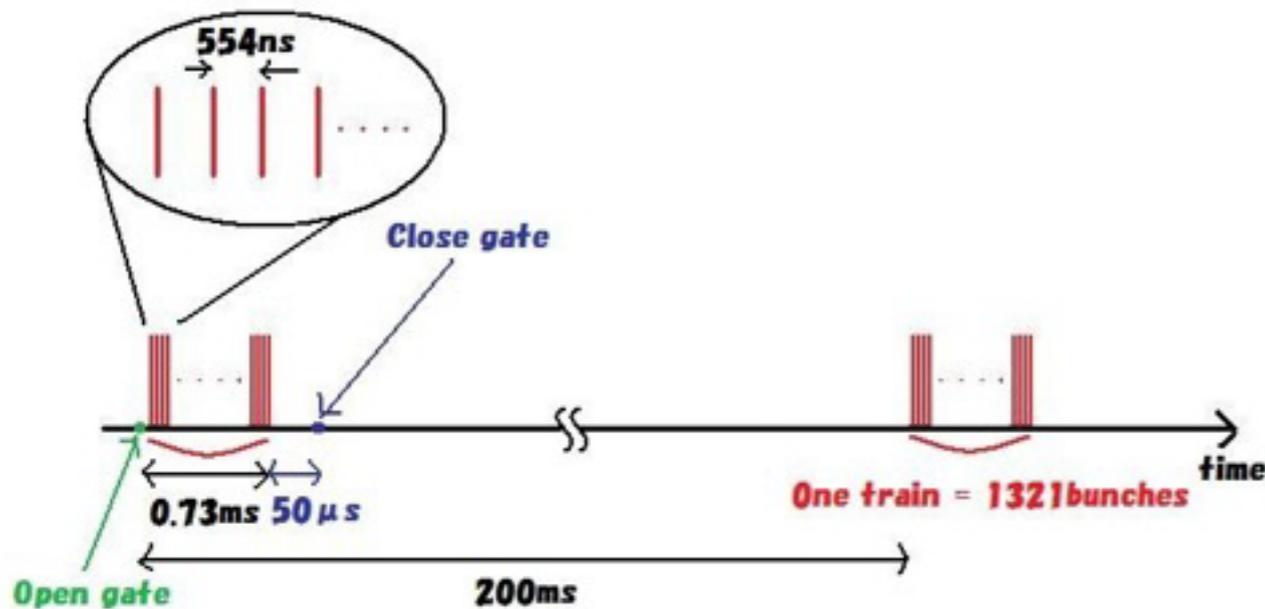
gate device

electron transmission rate in B-Field \doteq Optical aperture

Gating foil



▼ beam structure of ILC



**By closing the gate between bunch trains
Ion Backflow can be prevented**

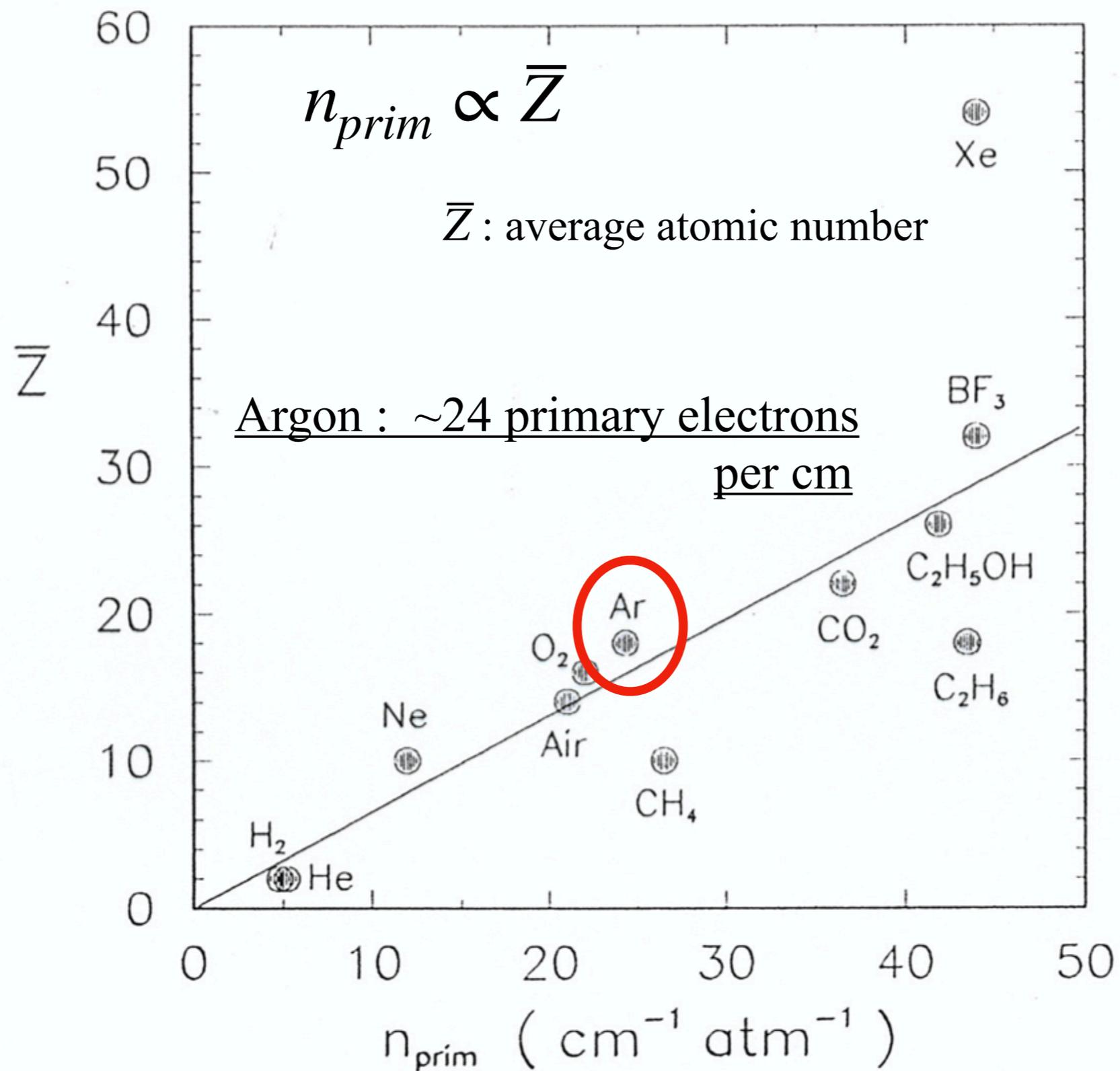
Summary

The ILD-TPC is a high-performance central tracker operated in a strong B-field, featuring MPGD readout modules.

The TPC provides excellent track pattern recognition capability with small 3-D voxels, along with good position, momentum, and dE/dx information of each track in jets, which are indispensable for the Particle Flow Analysis.

We have successfully developed a gating foil that meets the requirements, and are now working on the R&D of new GEM foils (plates) with new insulator materials in order to make the gas-amplification device simple and "die-hard".

Backup



Number of primary electrons versus the average atomic number of popular chamber gases

Total number of ionisation electrons n_{tot}

$$n_{tot} = \frac{\Delta E}{W_I}$$

ΔE total energy loss in the gas volume

W_I effective energy loss for the production of one ionisation

Gas	Z	A	δ (g/cm ³)	E_{ex}	E_i	I_0	W_i	dE/dx		n_p (i.p./cm) ^{a)}	n_T (i.p./cm) ^{a)}
								(MeV/g cm ⁻²)	(keV/cm)		
H ₂	2	2	8.38×10^{-5}	10.8	15.9	15.4	37	4.03	0.34	5.2	9.2
He	2	4	1.66×10^{-4}	19.8	24.5	24.6	41	1.94	0.32	5.9	7.8
N ₂	14	28	1.17×10^{-3}	8.1	16.7	15.5	35	1.68	1.96	(10)	56
O ₂	16	32	1.33×10^{-3}	7.9	12.8	12.2	31	1.69	2.26	22	73
Ne	10	20.2	8.39×10^{-4}	16.6	21.5	21.6	36	1.68	1.41	12	39
Ar	18	39.9	1.66×10^{-3}	11.6	15.7	15.8	26	1.47	2.44	29.4	94
Kr	36	83.8	3.49×10^{-3}	10.0	13.9	14.0	24	1.32	4.60	(22)	192
Xe	54	131.3	5.49×10^{-3}	8.4	12.1	12.1	22	1.23	6.76	44	307
CO ₂	22	44	1.86×10^{-3}	5.2	13.7	13.7	33	1.62	3.01	(34)	91
CH ₄	10	16	6.70×10^{-4}		15.2	13.1	28	2.21	1.48	16	53
C ₄ H ₁₀	34	58	2.42×10^{-3}		10.6	10.8	23	1.86	4.50	(46)	195

a) i.p. = ion pairs

Important parameters for frequently used chamber gases.

Argon

Gas	Z	A	δ (g/cm ³)	E_{ex}	E_i (eV)		W_i	dE/dx		n_p (i.p./cm) ^{a)}	n_T (i.p./cm) ^{a)}
								(MeV/g cm ⁻²)	(keV/cm)		
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C ₄ H ₁₀	34	58	2.42×10^{-3}		10.6	10.8	23	1.86	4.50	(46)	195

a) i.p. = ion pairs

Argon: total number of ionisation electrons is 94 /cm

24 primary electrons produce about 2, 3 secondary electrons

Characteristic of electron transmission

aim of ILD-TPC

momentum resolution:

$$\frac{\sigma_{p_{\perp}}}{p_{\perp}} \approx 1 \times 10^{-4} p_{\perp} \text{ GeV}/c$$

-> position resolution:

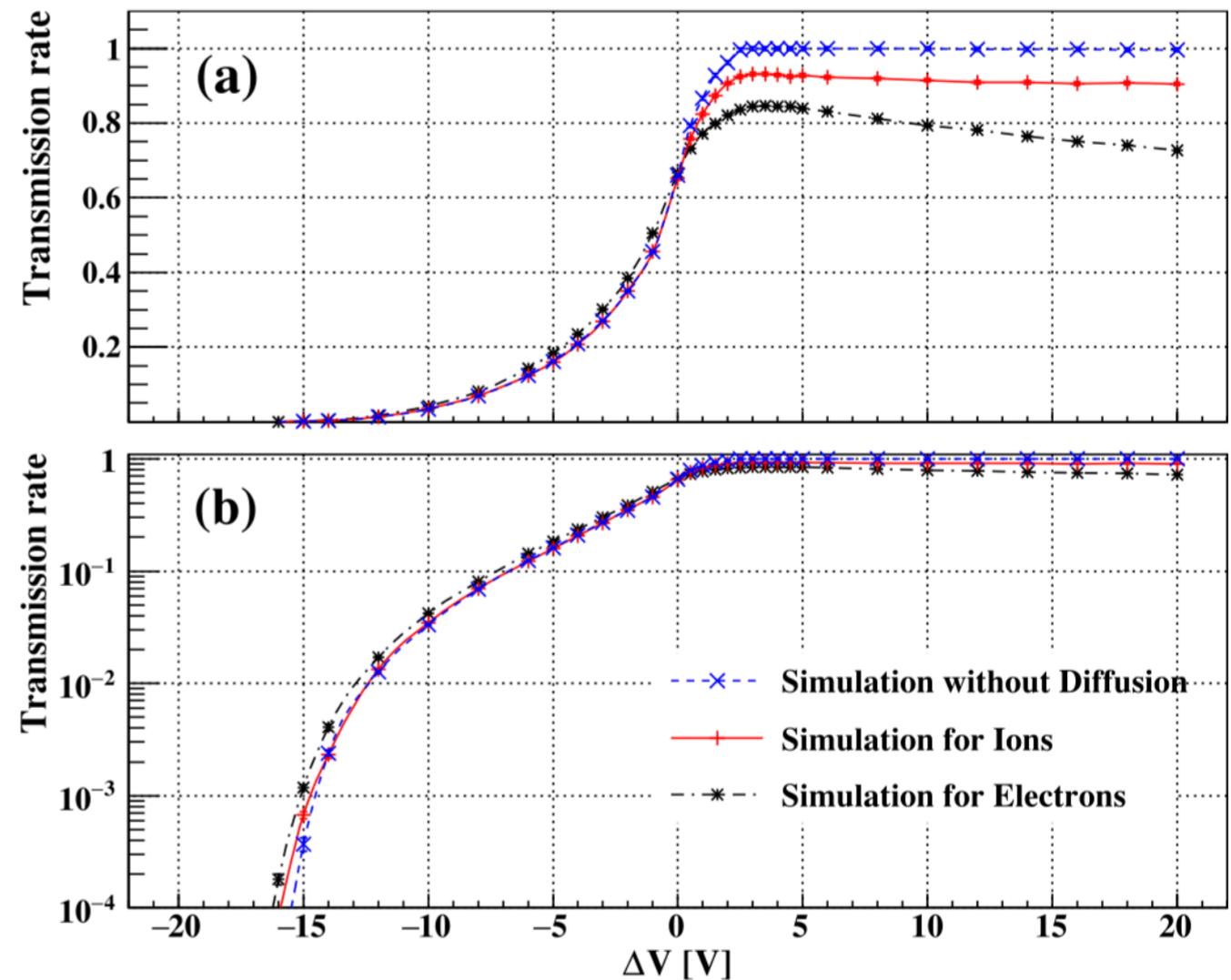
$$\sigma_x \approx 100 \mu m$$

aim of gate device

electron transmission rate > 80 %

ion blocking rate ~

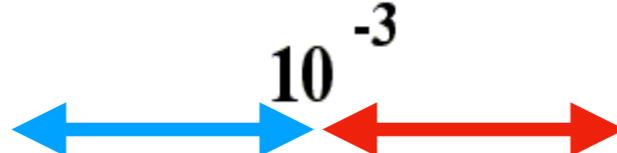
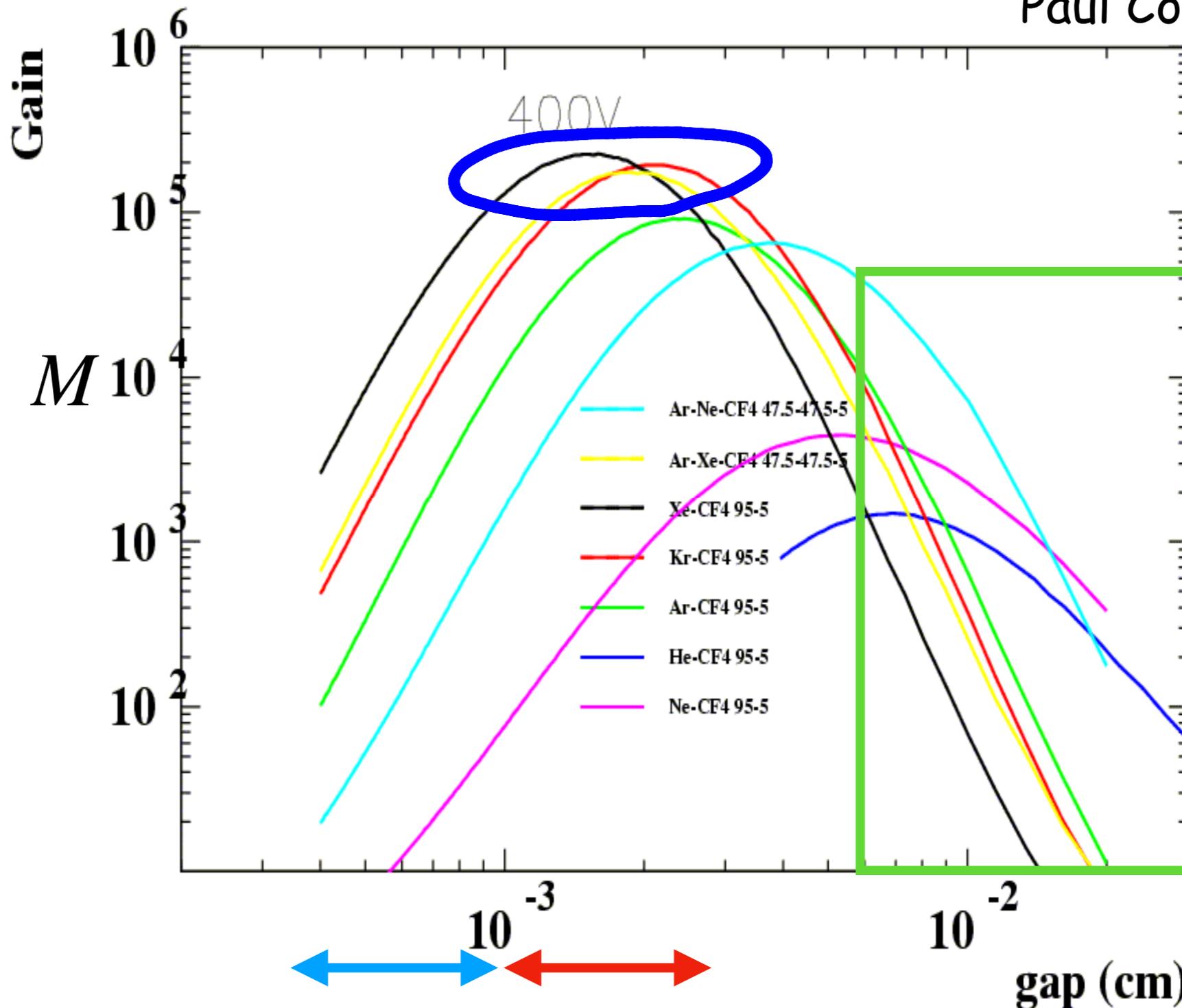
$$\mathcal{O}(10^{-4})$$



in the case of a MicroMEGAS, there is a “plateau” in a gap dependence of gas gain

Paul Colas

$$M = e^{\alpha d}$$



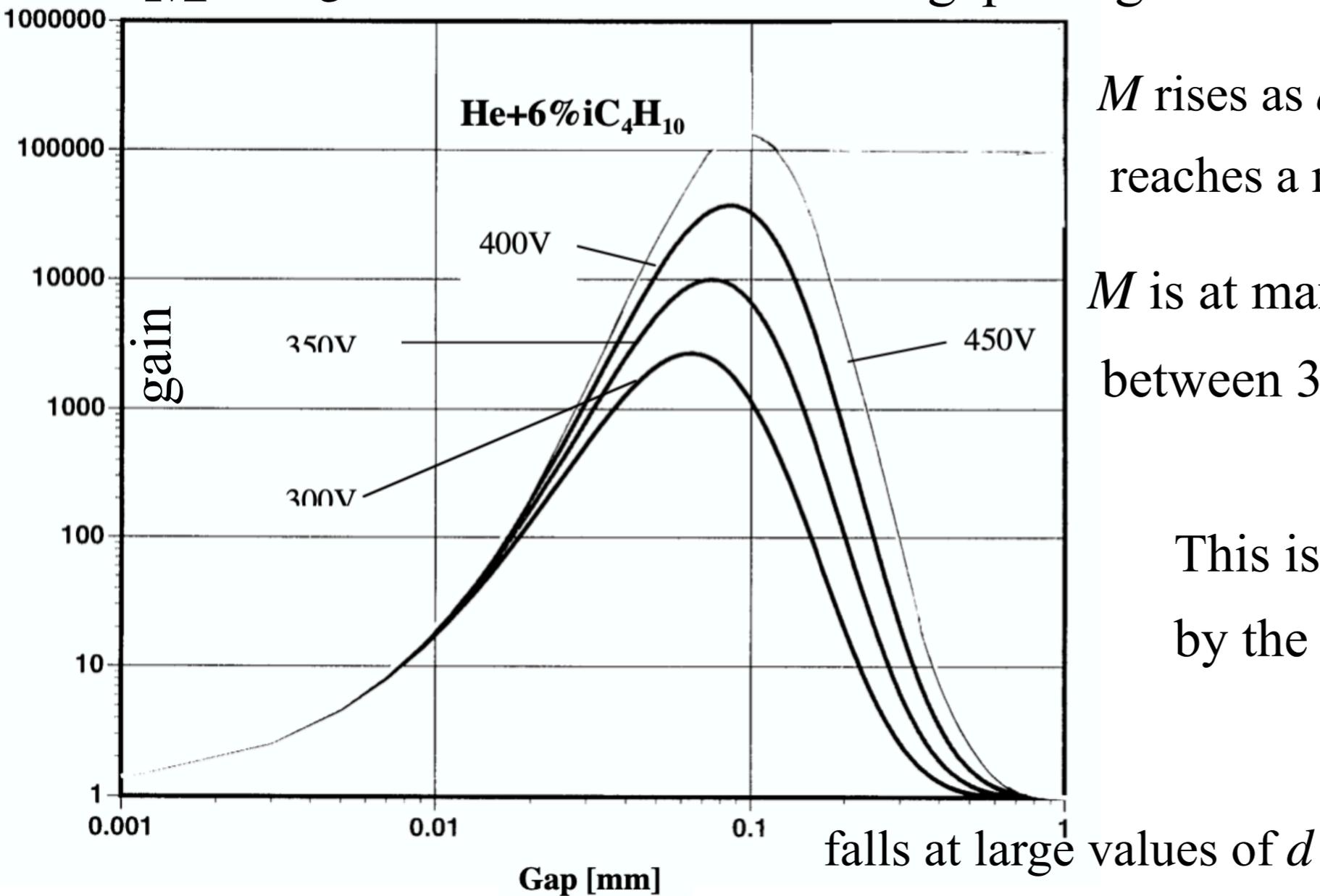
“plateau”

gap d : $\uparrow \uparrow$
EField: \downarrow
 α : \downarrow (depends on Efield)

gap d : \uparrow
EField: $\downarrow \downarrow$
 α : $\downarrow \downarrow$ (depends on Efield)

MICROME GAS

$M = e^{\alpha d}$ as a function of the gap d gas: He + iC₄H₁₀ = 94:6



M rises as d increases,
reaches a maximum

M is at maximum in the range of gaps
between 30-100 μm .

This is the range currently used
by the MICROME GAS detectors

MICROME GAS: results and prospects : I. Giomataris

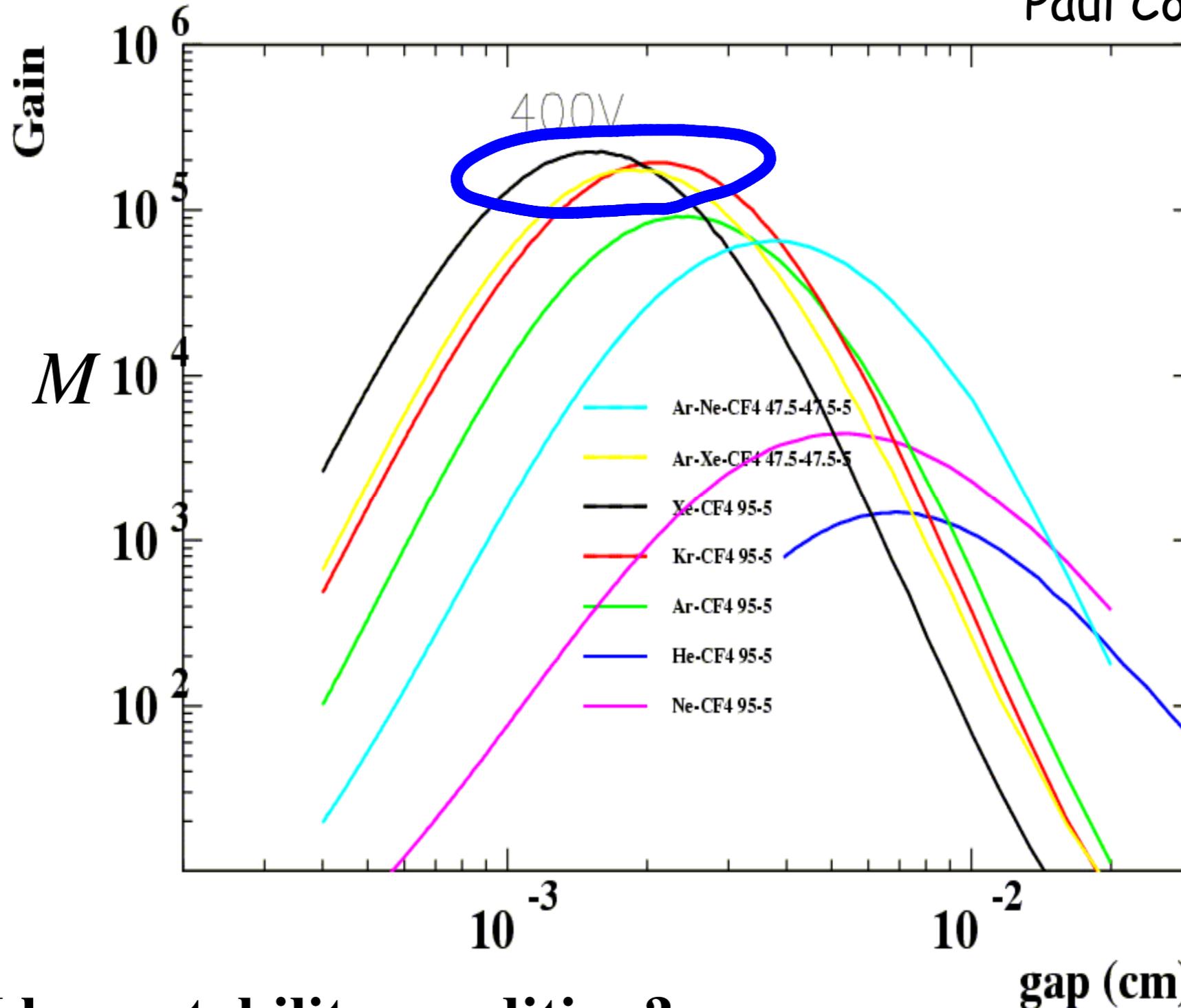
In this range, gas gain M is maximum and its fluctuations due to defects of flatness of the two parallel electrodes are canceled

Stability condition!!

in the case of a MicroMEGAS, there is a “plateau” in a gap dependence of gas gain

Paul Colas

$$M = e^{\alpha d}$$

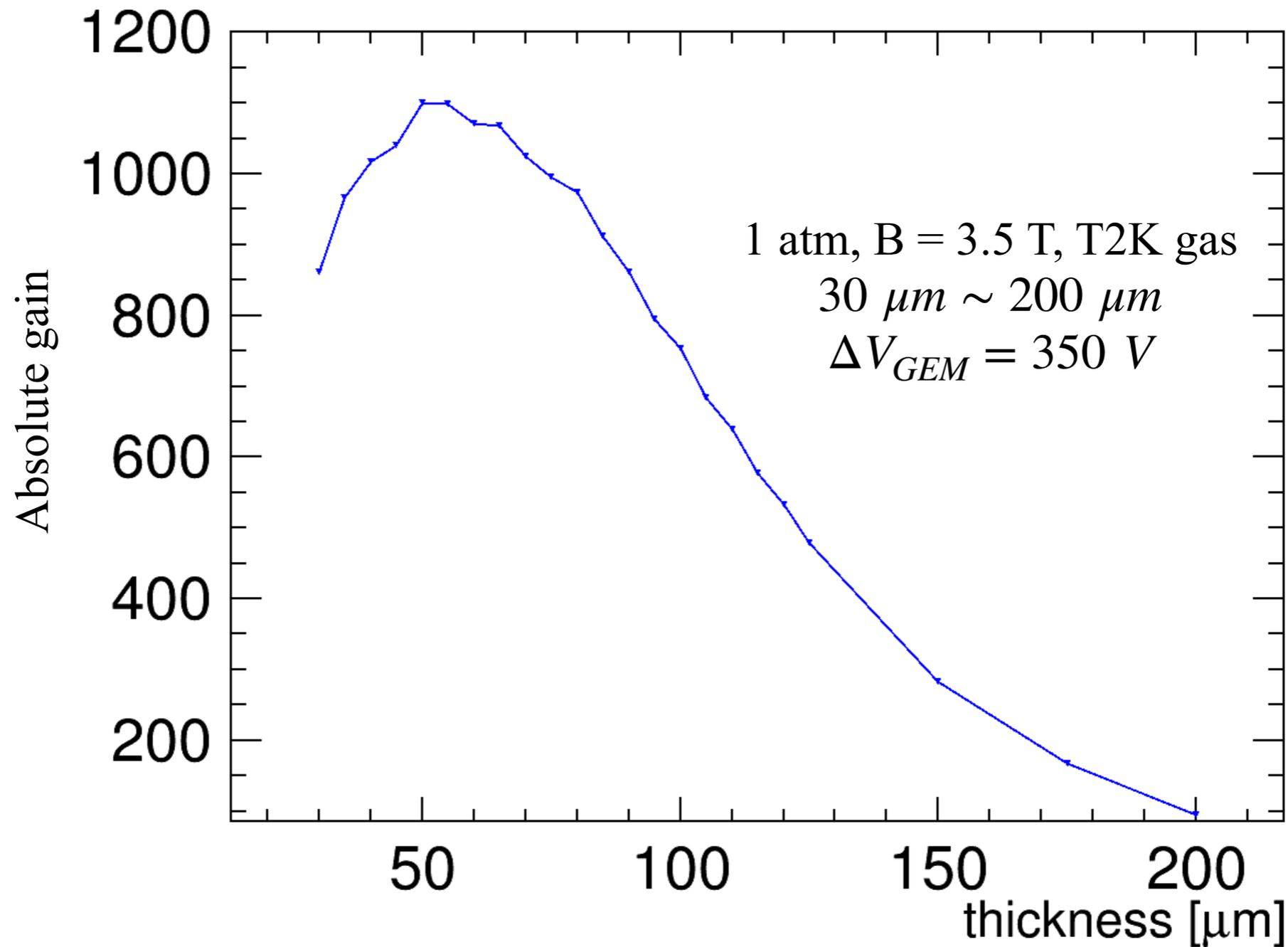


Does GEM have stability condition?

Theoretically, derive the stability conditions under which the gas gain is stable

I (KY) am working on this study on going

Thickness dependence of gain: Asian GEM



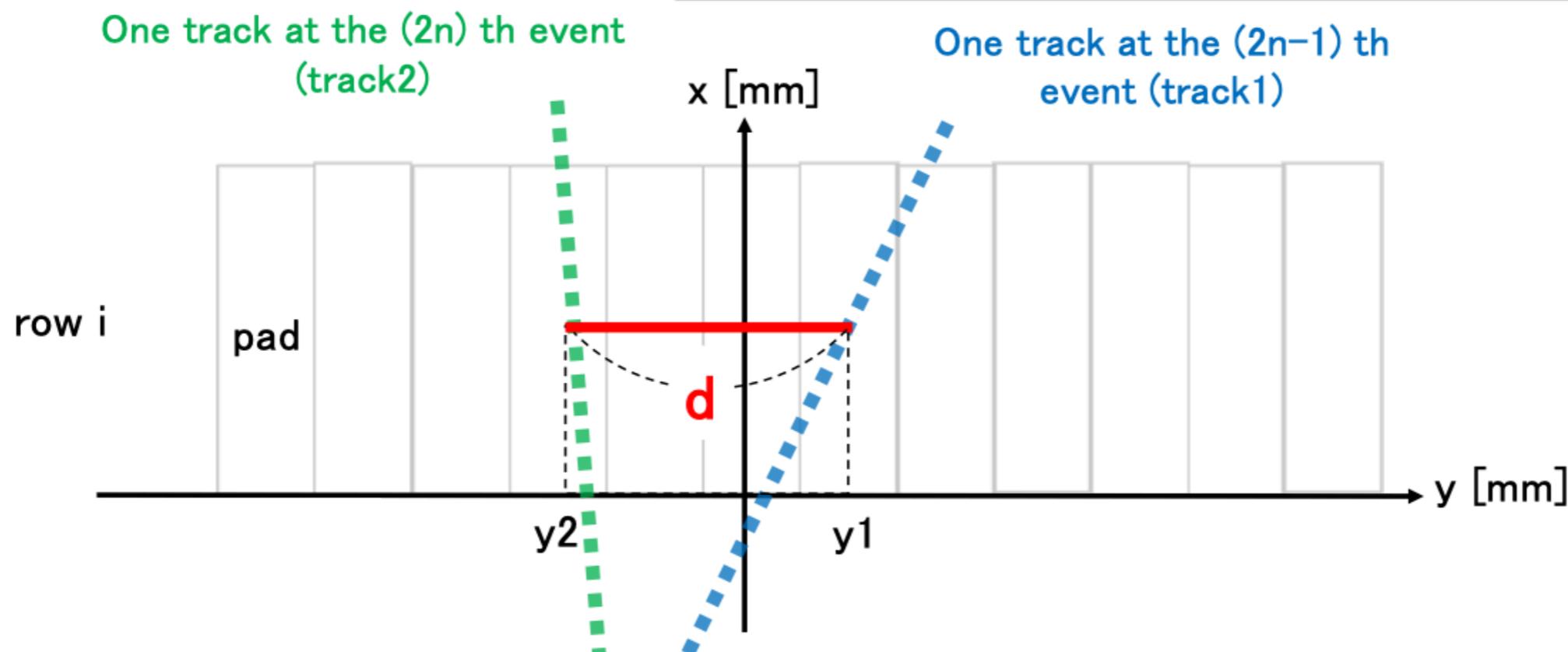
The plateau area was found in the range of 40 μm ~ 80 μm

cf. CERN GEM: thickness 50 μm

If our theory is correct, the stability condition should be satisfied in the range of 40 μm ~ 80 μm

- A MPGD-based TPC can provide clearly track separation thanks to its small ExB effect compared with MWPC.
- We're trying to investigate 2-track separation for a GEM-based TPC using electron beam.

σ_{point} in $r\phi$	$\simeq 60 \mu\text{m}$ for zero drift, $< 100 \mu\text{m}$ overall
σ_{point} in rz	$\simeq 0.4 - 1.4 \text{ mm}$ (for zero - full drift)
2-hit resolution in $r\phi$	$\simeq 2 \text{ mm}$
2-hit resolution in rz	$\simeq 6 \text{ mm}$
dE/dx resolution	$\simeq 5 \%$
Momentum resolution at B=3.5 T	$\delta(1/p_t) \simeq 10^{-4}/\text{GeV}/c$ (TPC only)

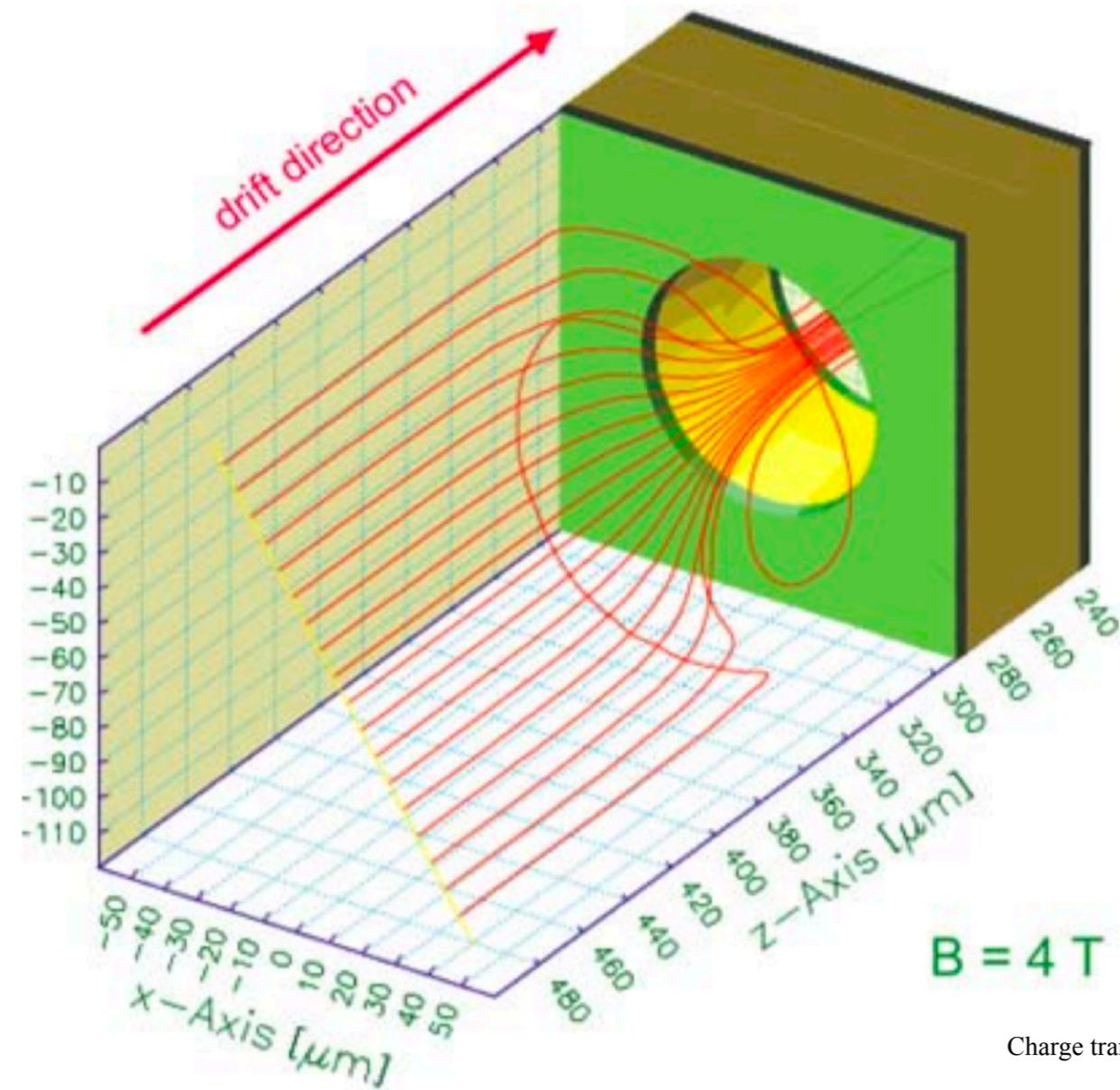


on going

Aiko shoji is working on this study

From Aiko Shoji (LCWS 2019) @ Sendai

Backup



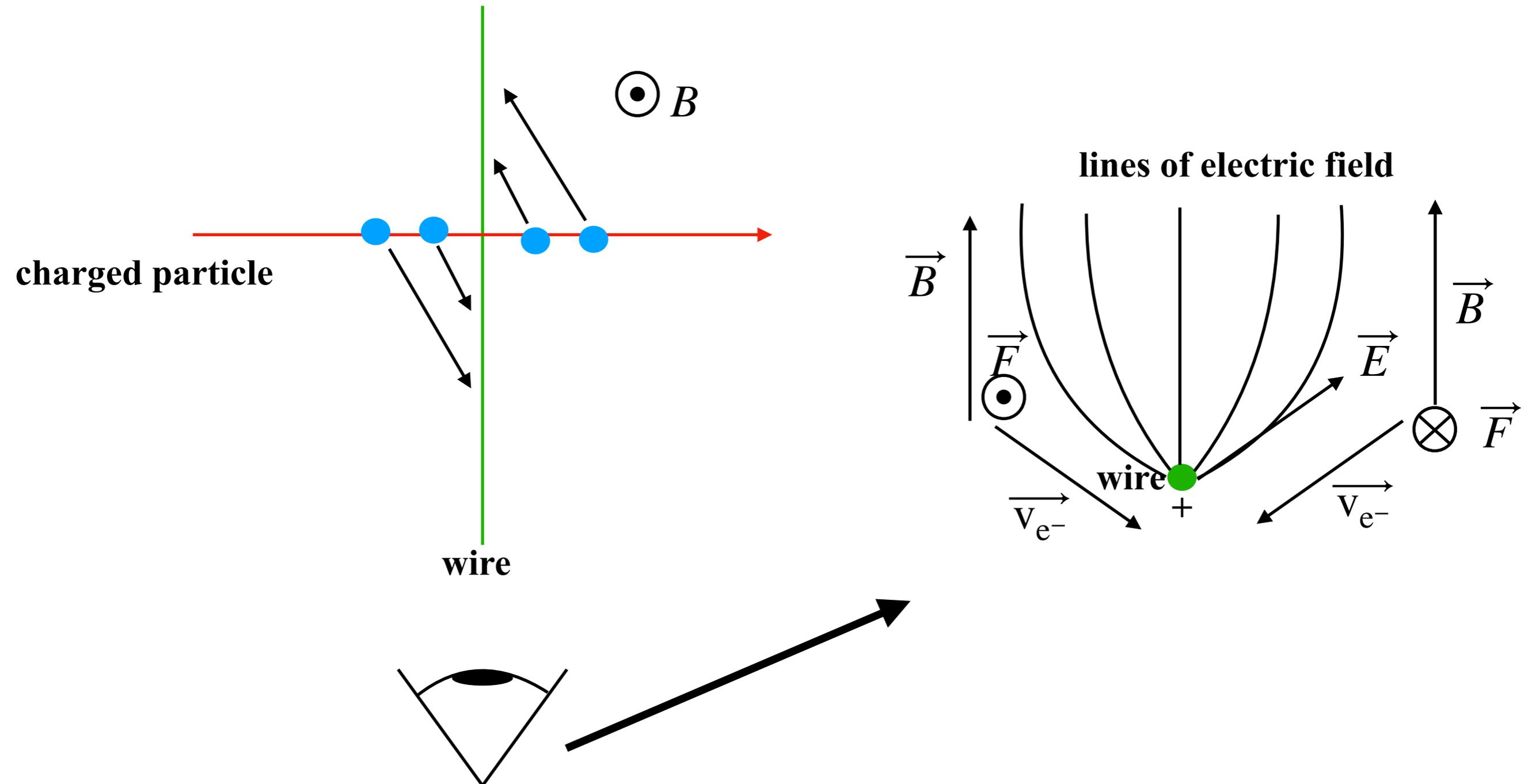
Charge transfer and charge broadening of GEM structures in high magnetic fields
M. Killenberg et al.

GARFIELD simulation of electron drift lines starting in front of a GEM (electric field 200 V/cm ; GEM voltage 400 V); at 4 T

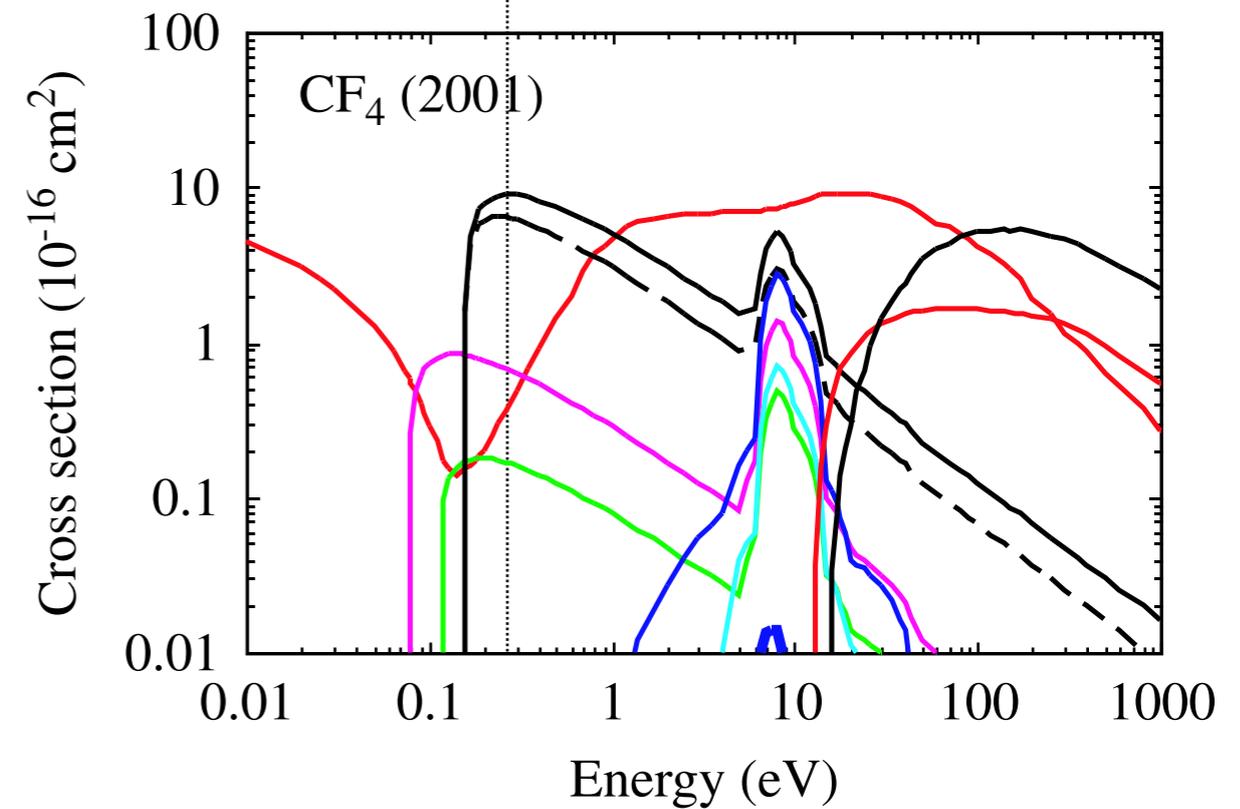
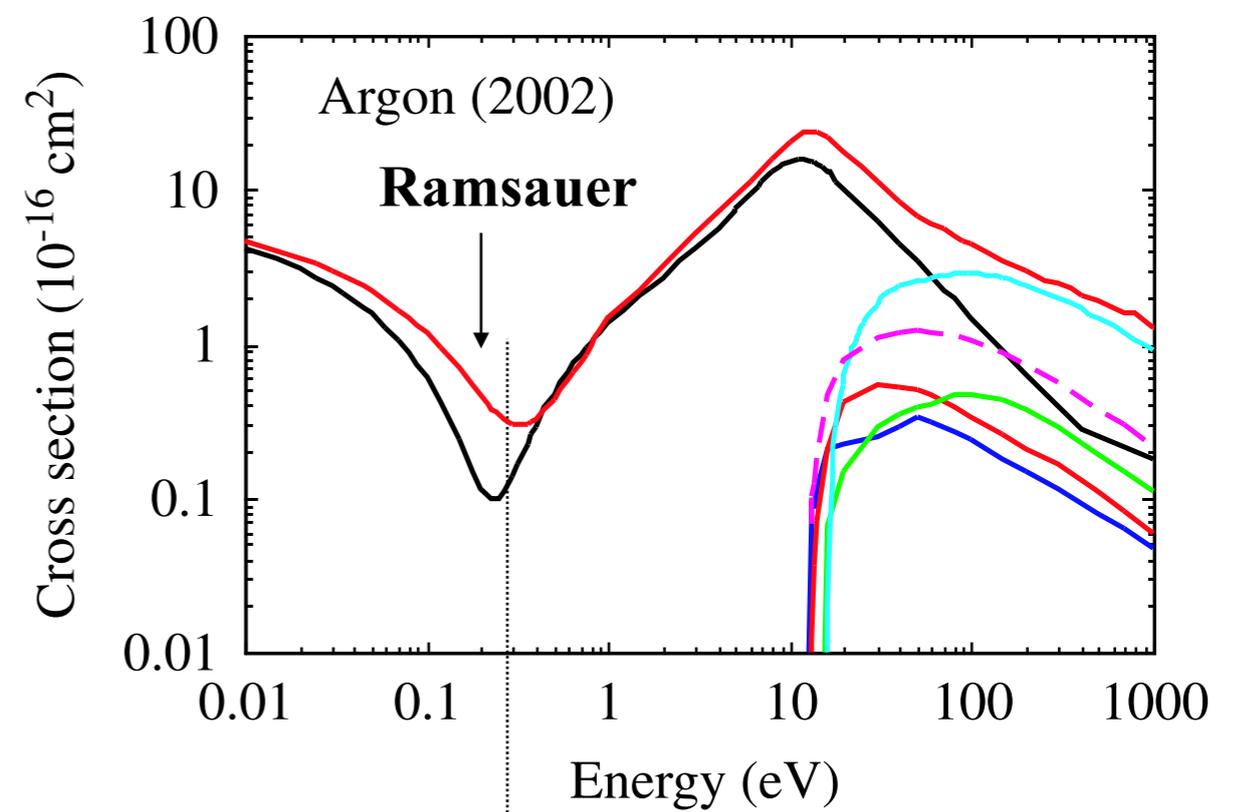
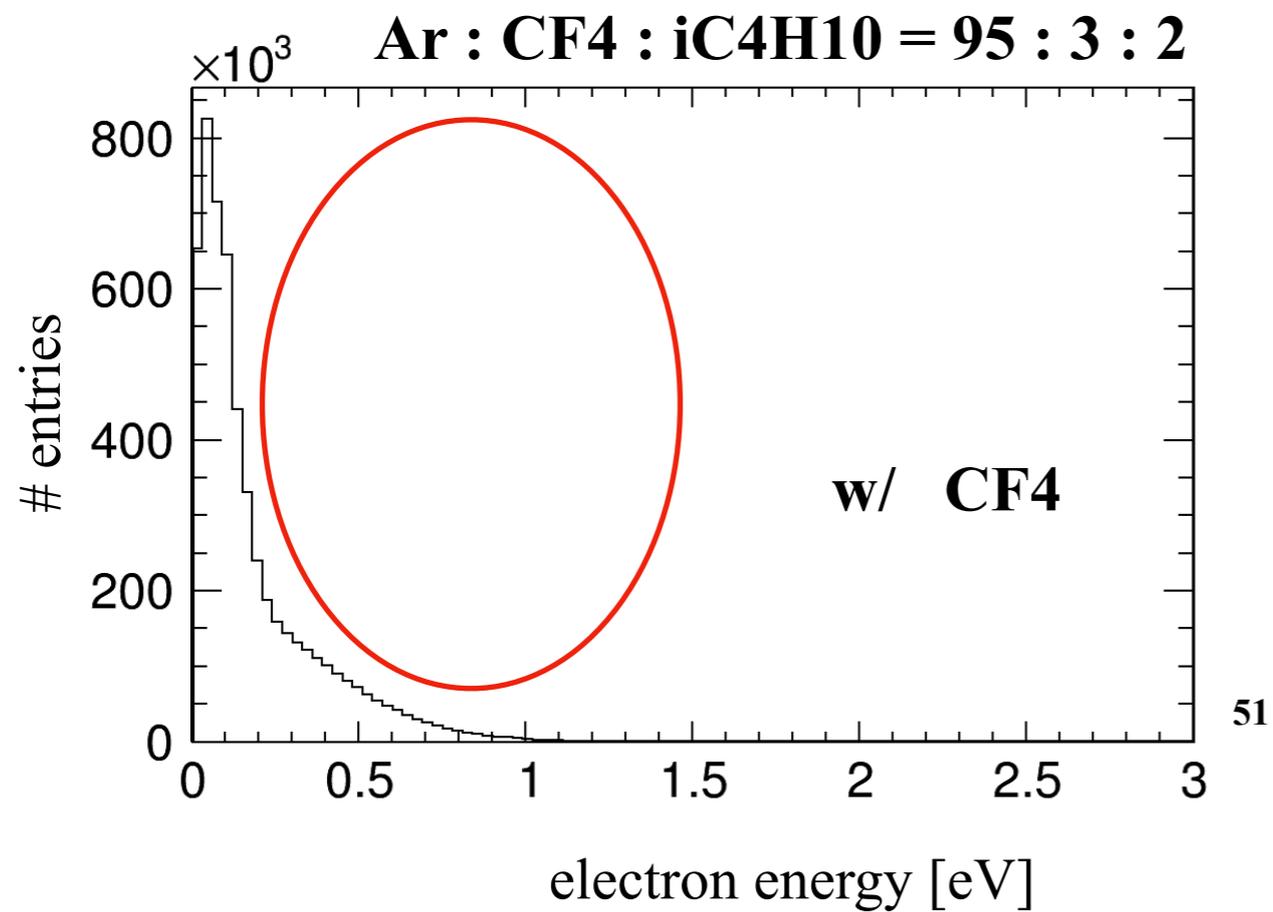
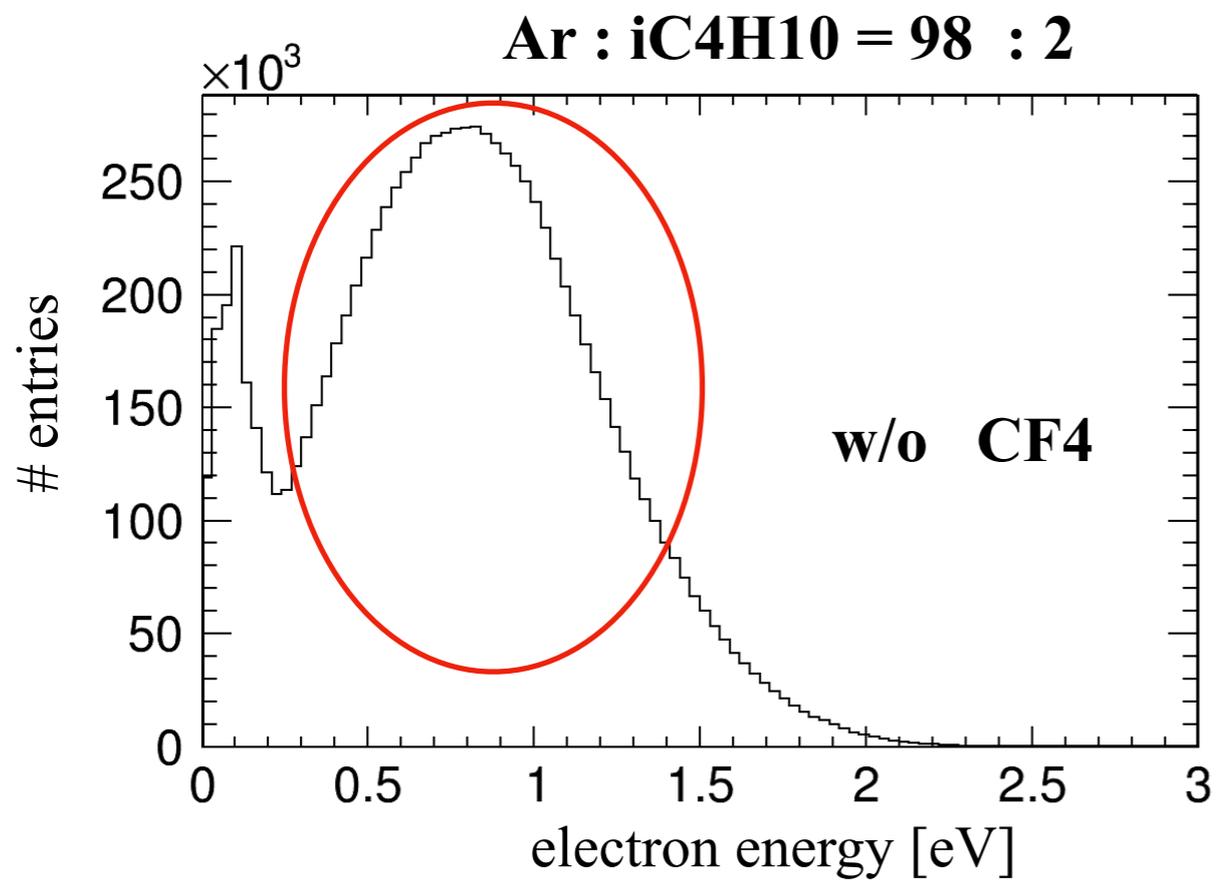
no electrons are lost during collection into the GEM holes.

$E \times B$ effect

bend the electron drift path near the wire

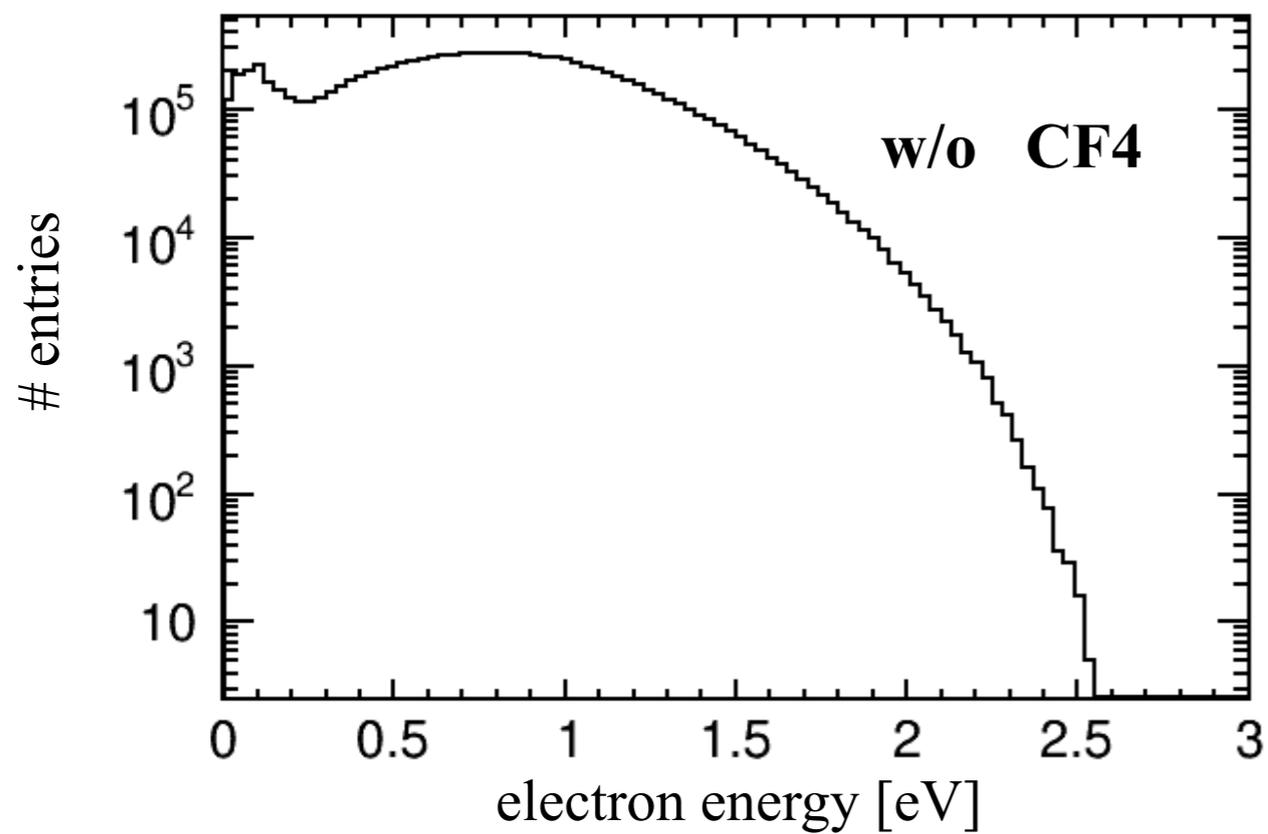


liberated electrons are bent along the wire (in the direction of wire)

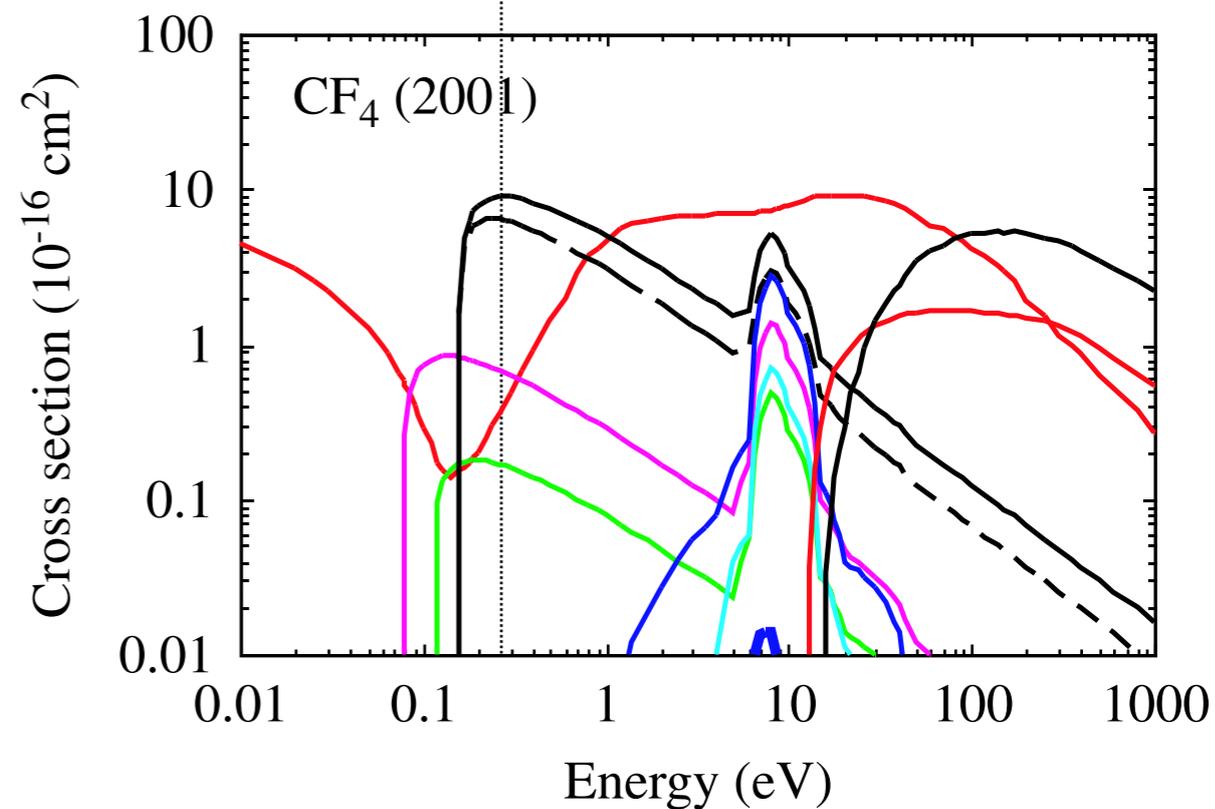
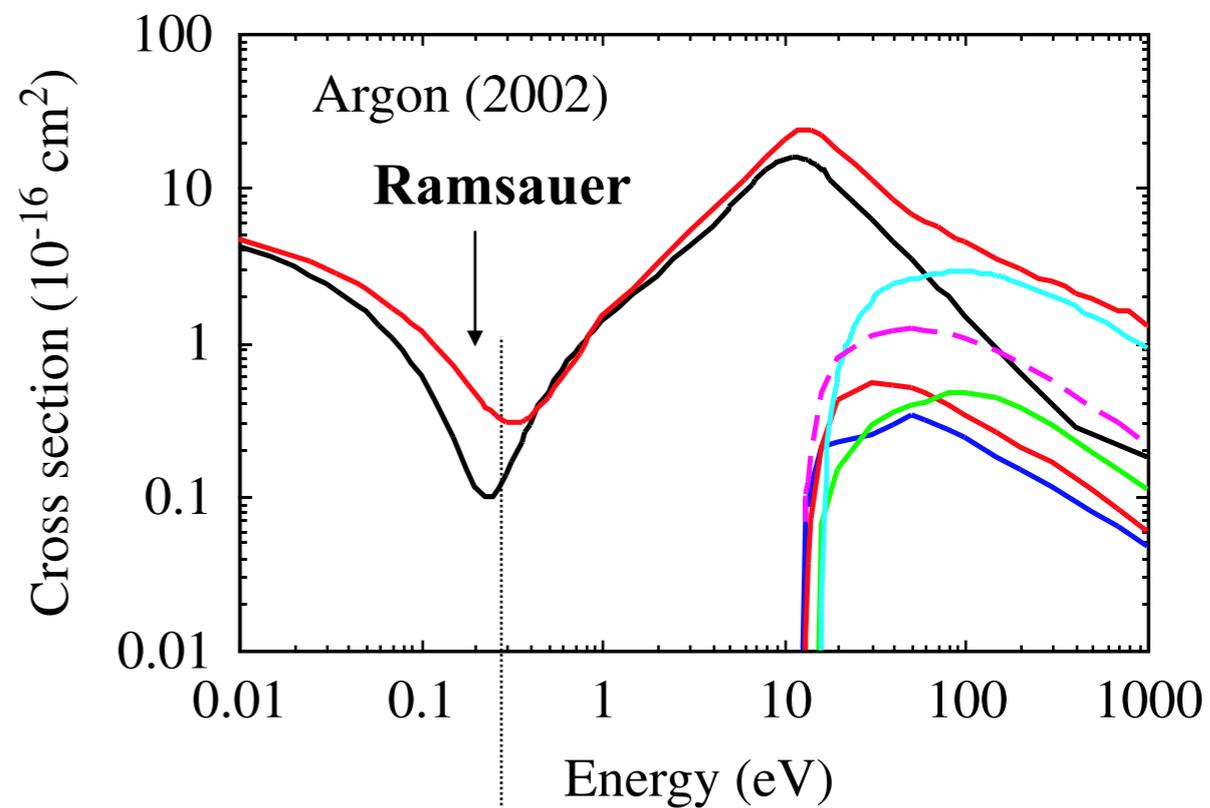
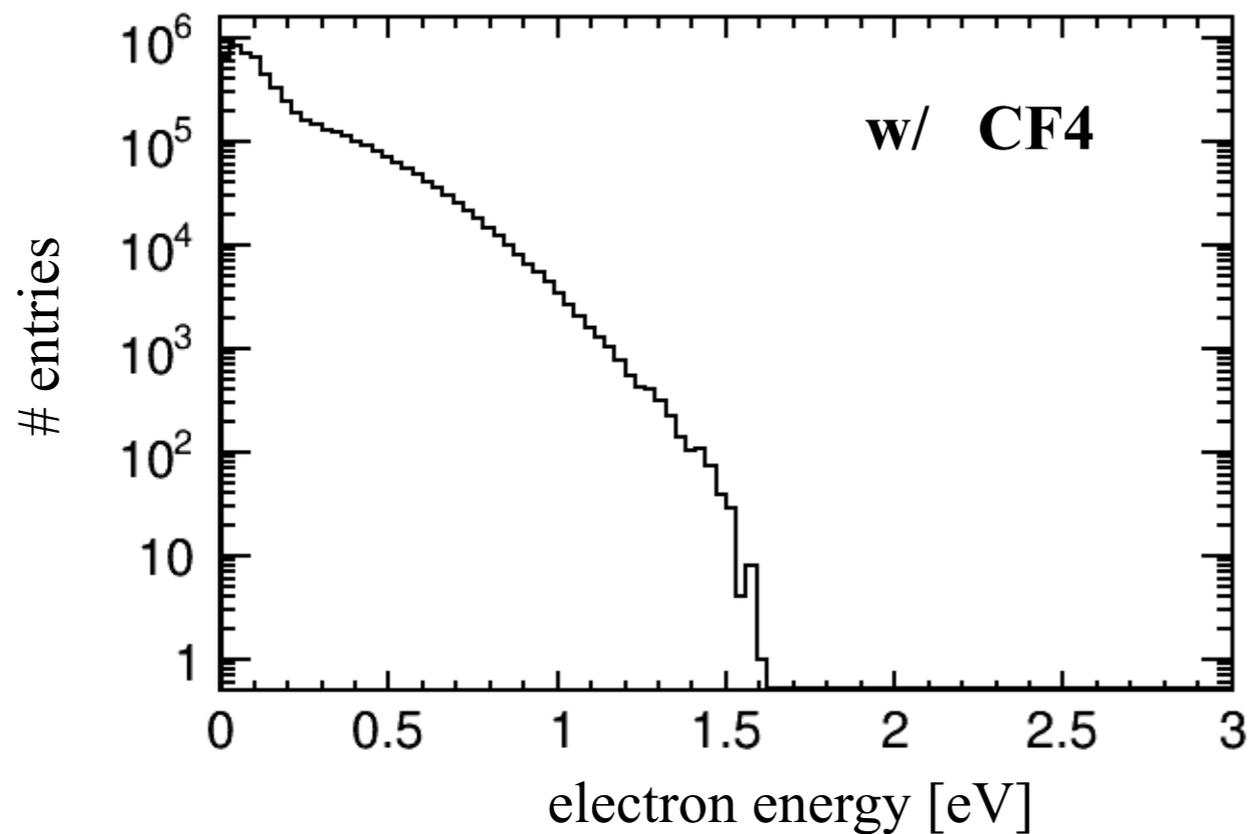


$E = 230 \text{ V/cm}$

Ar : iC4H10 = 98 : 2



Ar : CF4 : iC4H10 = 95 : 3 : 2



$E = 230 \text{ V/cm}$

Insulation material of GEM

GEM is vulnerable to discharges: a single (large) discharge could be fatal

= > Looking for new insulator material

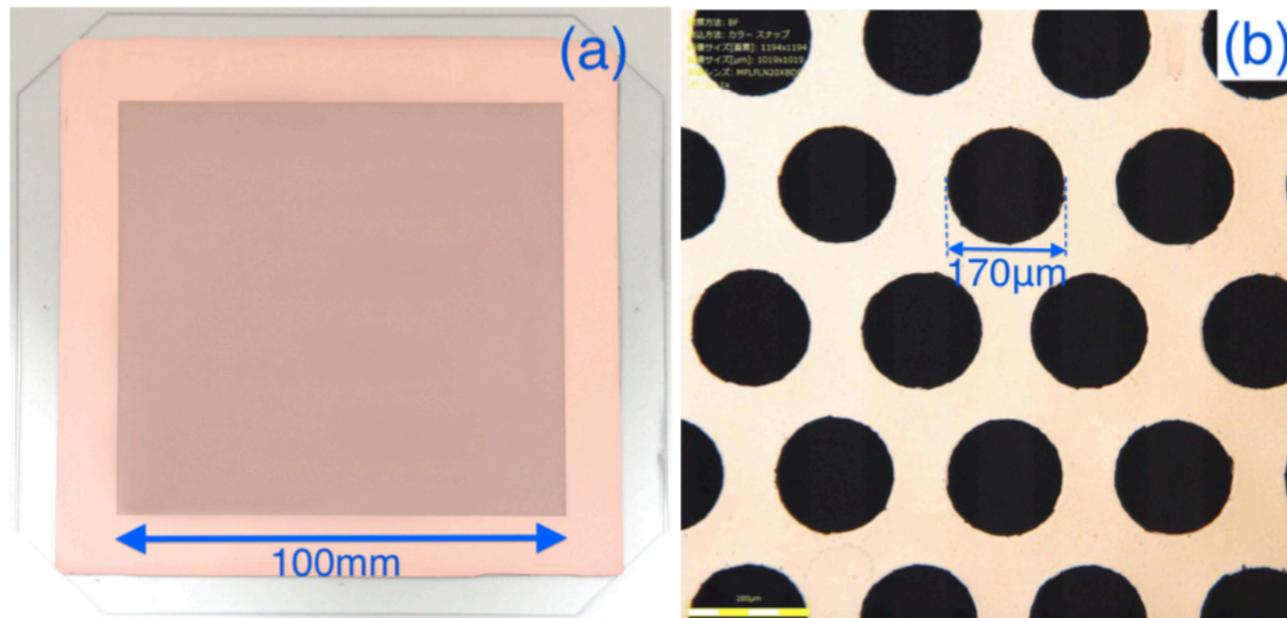
Glass GEM

Using glass instead of polyimide
as the substrate

No outgassing

High gain with only one stage

LTCC or G-GEM is a thin but stiff “plate”: self-supporting without tension applied



Photograph of the G-GEM

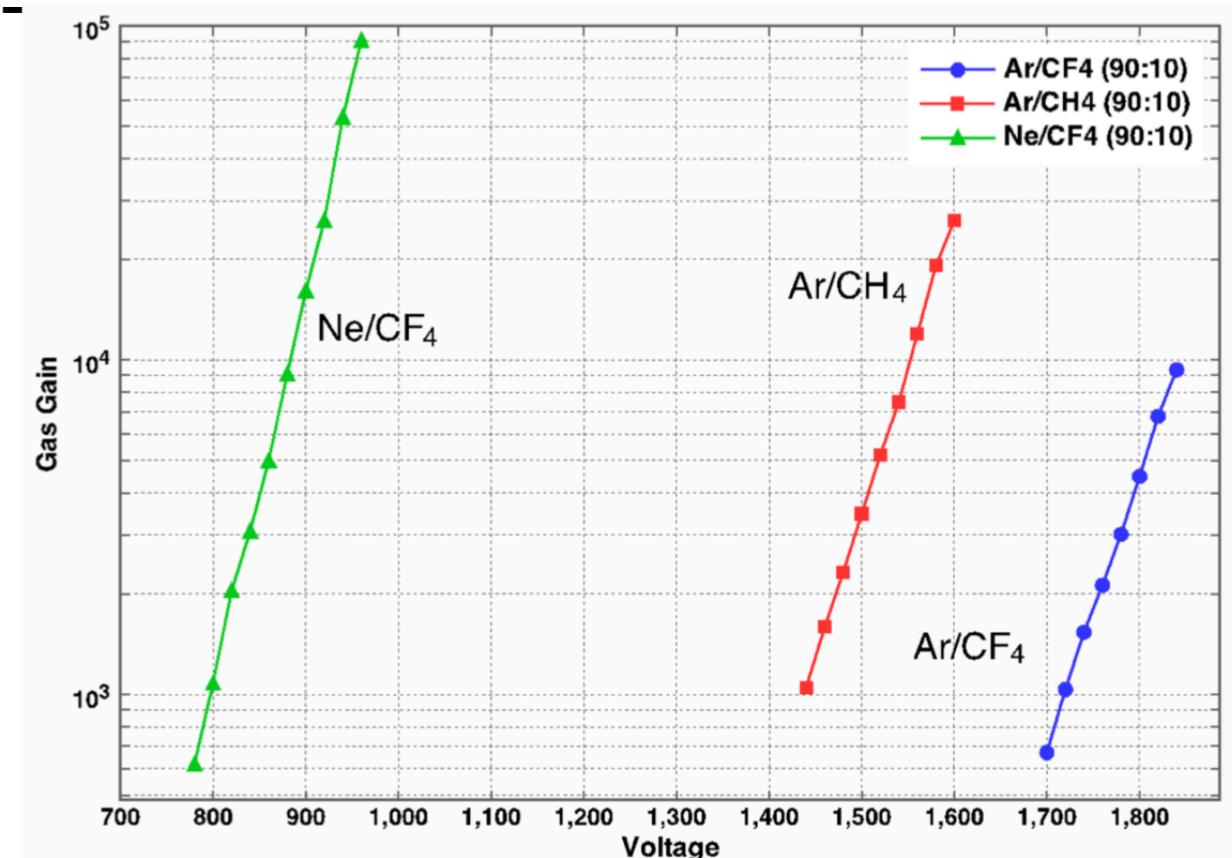
Microphotograph of the G-GEM

T. Fujiwara et al 2014 JINST 9 P11007

Characteristics of G-GEM & CERN GEM

Type of GEM	Glass GEM	CERN GEM
Hole diameter	170 μm	50 μm
Pitch	280 μm	150 μm
Thickness	680 μm	50 μm
Insulator	Glass	Polyimide

T. Fujiwara et al 2014 JINST 9 P11007



Gas gain curves of Glass GEM measured with 5.9-keV X-rays

T. Fujiwara et al 2014 JINST 9 P11007

Insulation material of GEM

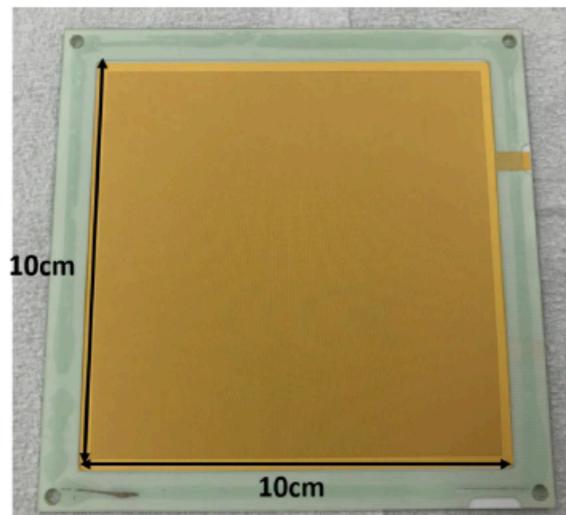
LTCC: Low Temperature Co-Fired Ceramics

By mixing glass components with alumina ceramics
annealing temperature $\sim 900^{\circ}\text{C}$

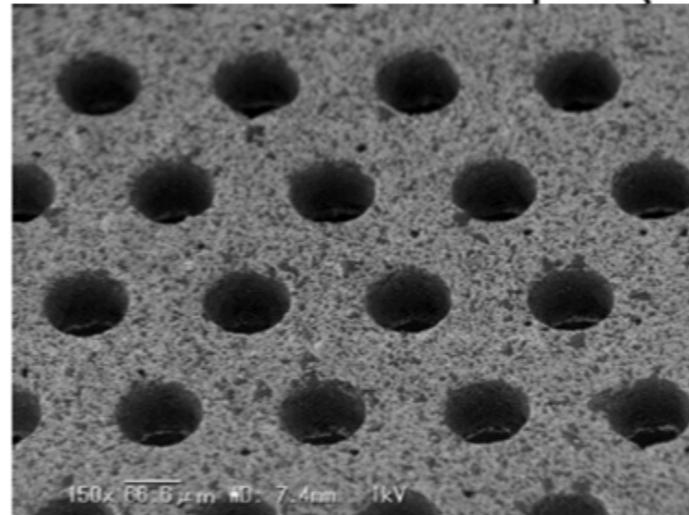
No outgassing

High gain with only one stage

LTCC or G-GEM is a thin but stiff “plate”: self-supporting without tension applied



Photograph of the LTCC-GEM



Microphotograph of the LTCC-GEM

Area

Substrate: 12.4 cm x 12.4 cm

Hole region: 10 cm x 10 cm

Thickness: 100 μm or 200 μm

Hole size: $\phi 100 \mu\text{m}$

Hole pitch: 200 μm

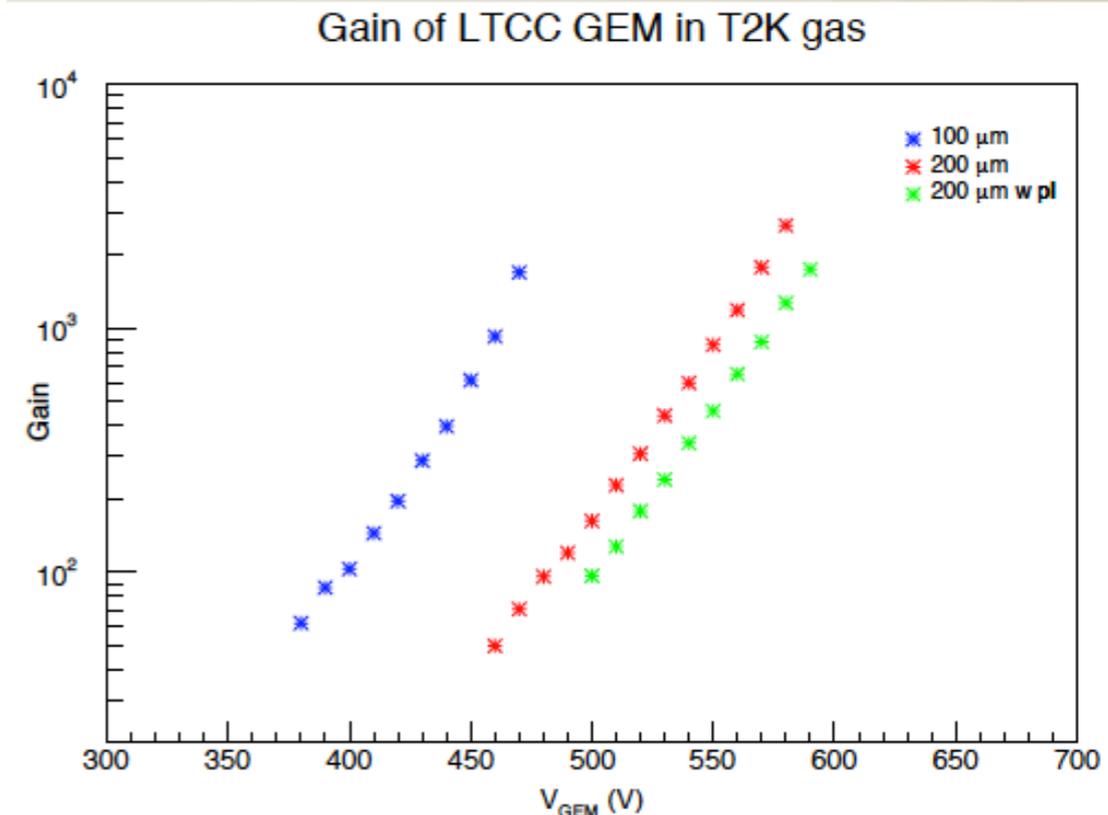
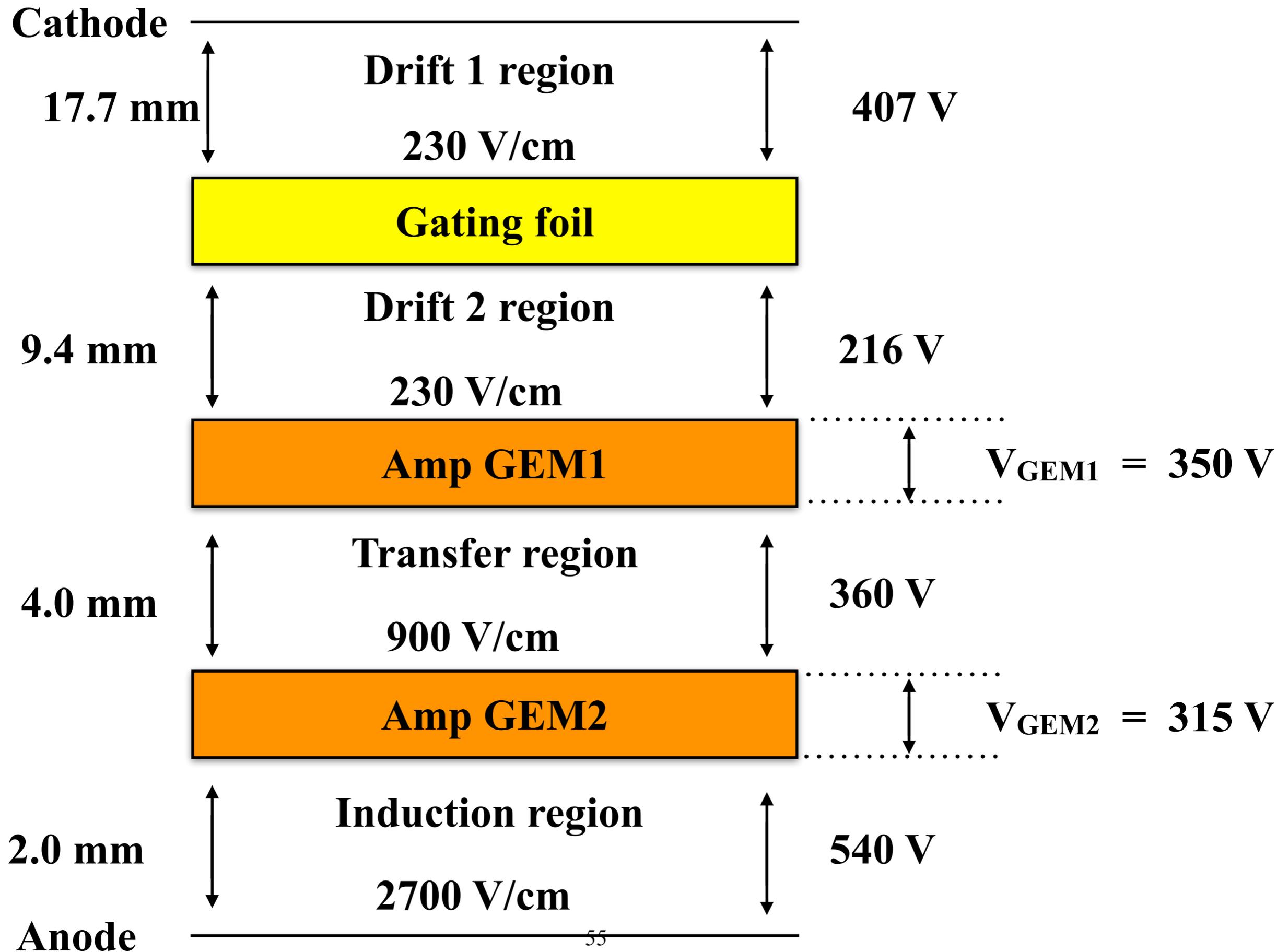


Figure by Y.Kato, Kindai Univ.

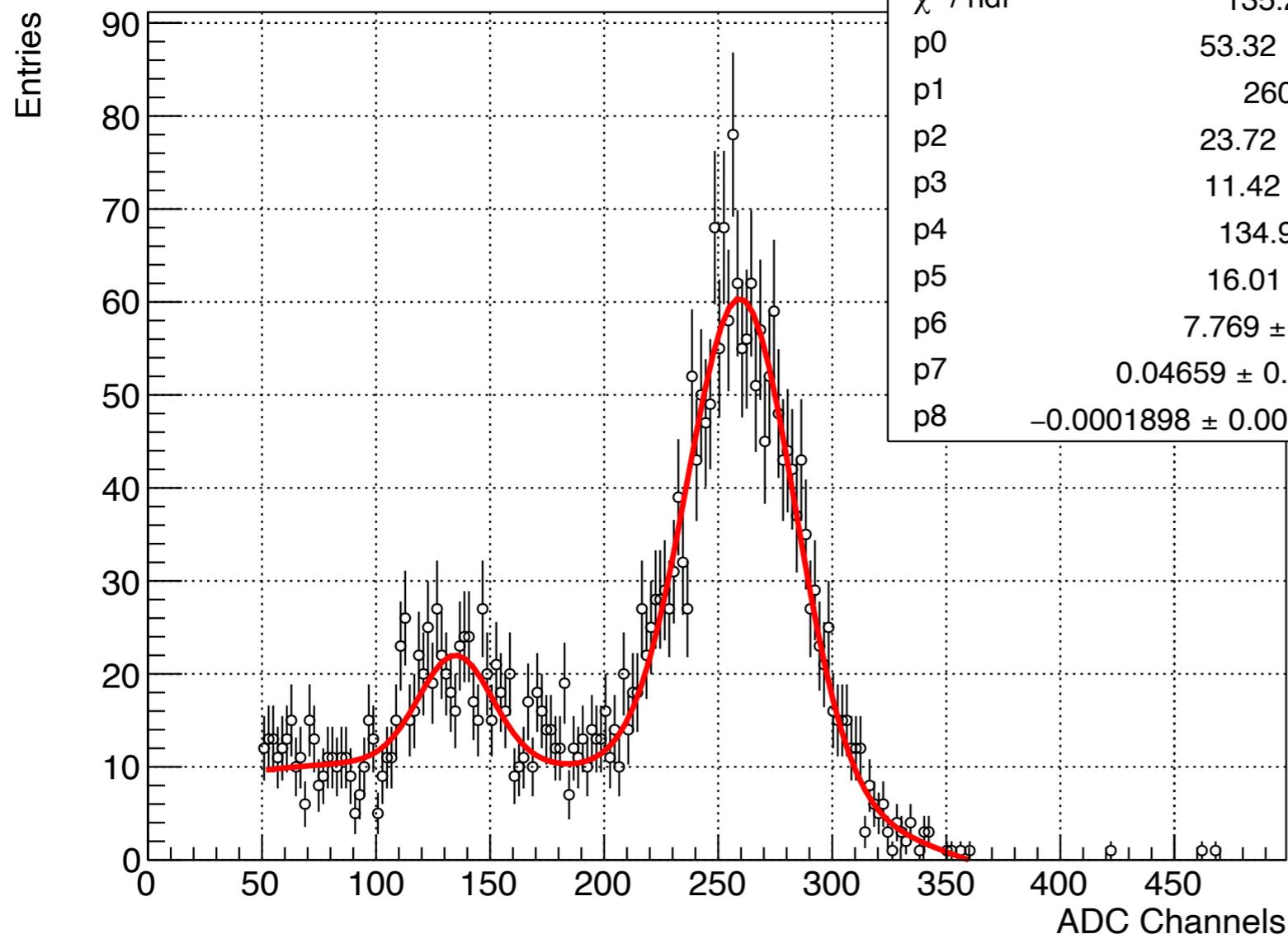
Electric field and voltage



Definition of Gain

[Example: run10]

Energy spectrum



Gain:

$$G = \frac{\text{Charge after amplification}}{\text{Charge before amplification}}$$

Q_{after}

Q_{before}

$$Q_{\text{after}} \sim 0.52 * p_1 - 0.78 \text{ [fC]}$$

This formula is obtained from ADC calibration. Correlation between ADC channels and charge was examined using a pulse generator.

$$Q_{\text{before}} \sim n_0 * 1.6 * 10^{-19} \text{ [C]}$$

n_0 : seed electrons ~ 227

Fitting function:

$$f(x) = p_0 \exp\left(-\frac{(x - p_1)^2}{2p_2^2}\right) + p_3 \exp\left(-\frac{(x - p_4)^2}{2p_5^2}\right) + p_6 + p_7x + p_8x^2$$

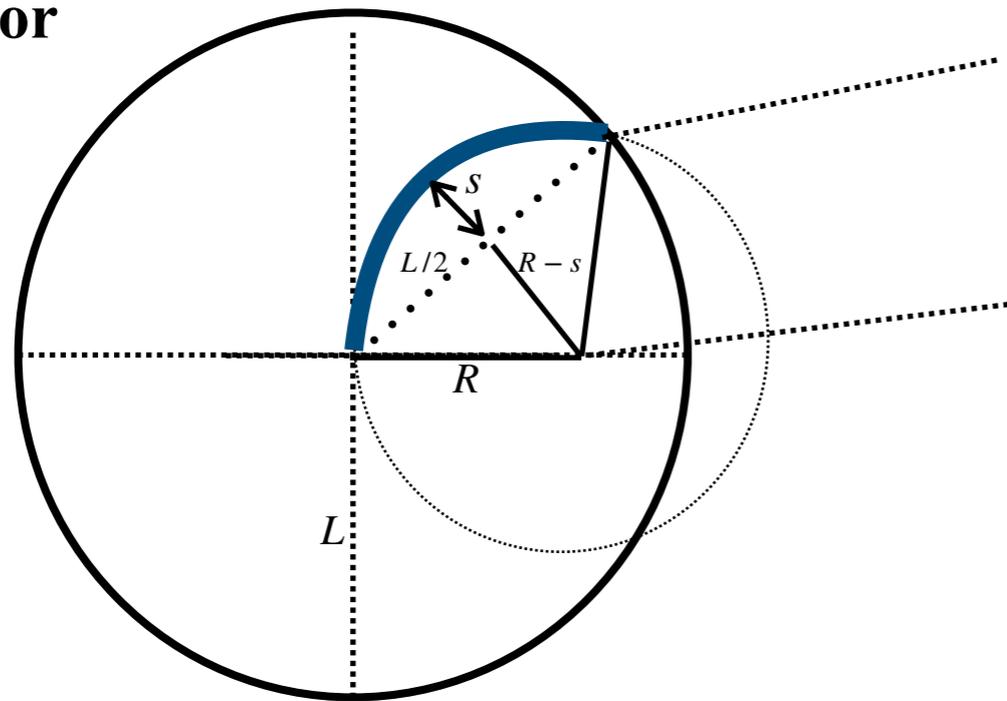
Main peak

Escape peak

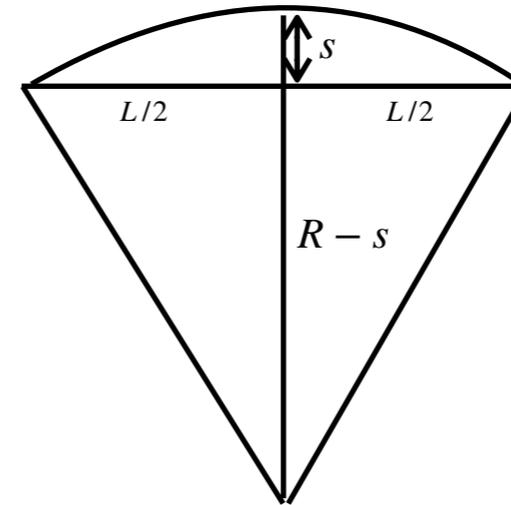
Background

Momentum resolution

cross section
of detector



using sagitta s



Let R be

$$R \gg s$$

$$R \approx \frac{L^2}{8s}$$

$$p_{\perp} = 0.3 BR \approx \frac{0.3BL^2}{8s}$$

by taking into account

- Multiple measurements points

- Multiple scattering

$$\frac{\sigma_{p_{\perp}}}{p_{\perp}} \propto \frac{\sigma_x p_{\perp}}{BL^2}$$

precisely,
Momentum resolution is

$$\frac{\sigma_{p_{\perp}}}{p_{\perp}} = \sqrt{\underbrace{\left(\frac{\alpha' \sigma_x}{BL^2}\right)^2 \left(\frac{720}{N+4}\right) p_{\perp}^2}_{\text{measurements}} + \underbrace{\left(\frac{\alpha' C}{BL}\right)^2 \frac{10}{7} \left(\frac{X}{X_0}\right)}_{\text{multiple scattering}}}$$

p_{\perp} : lateral momentum

B : strength of B-Field

L : track detection length

α', C : constant

σ_x : position resolution

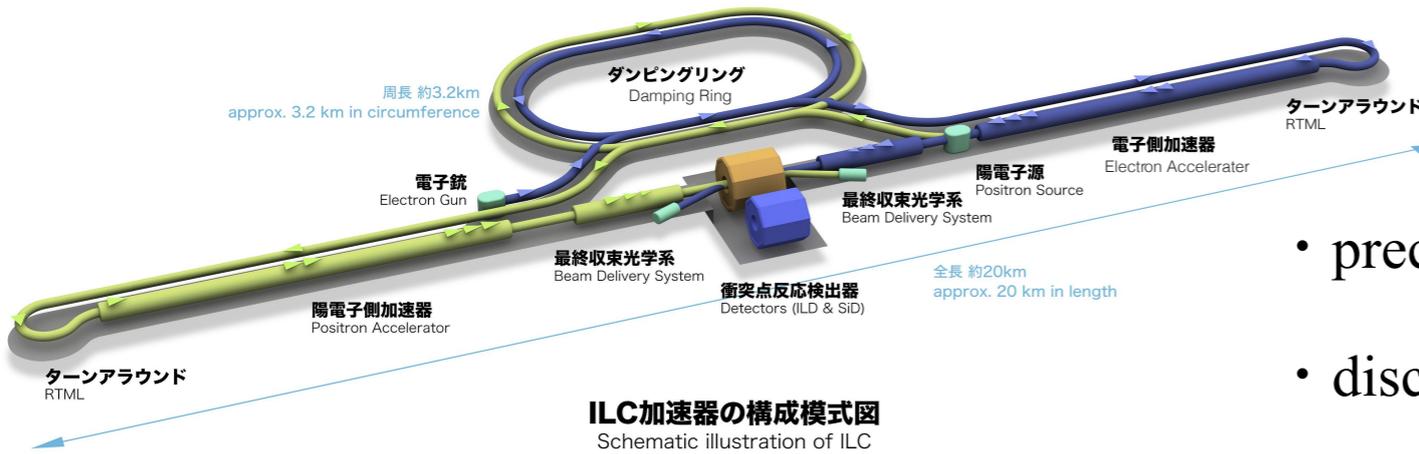
N : # of measurement
points

$\frac{X}{X_0}$: radiation length of gas

Introduction

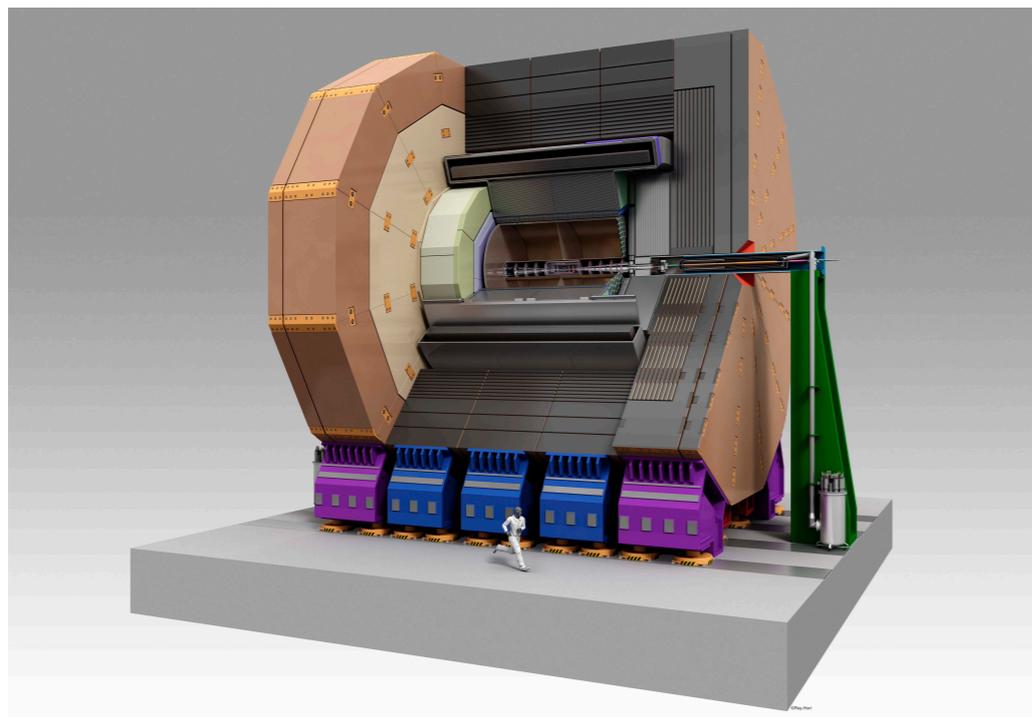
International Linear Collider (ILC)

linear electron-positron collider

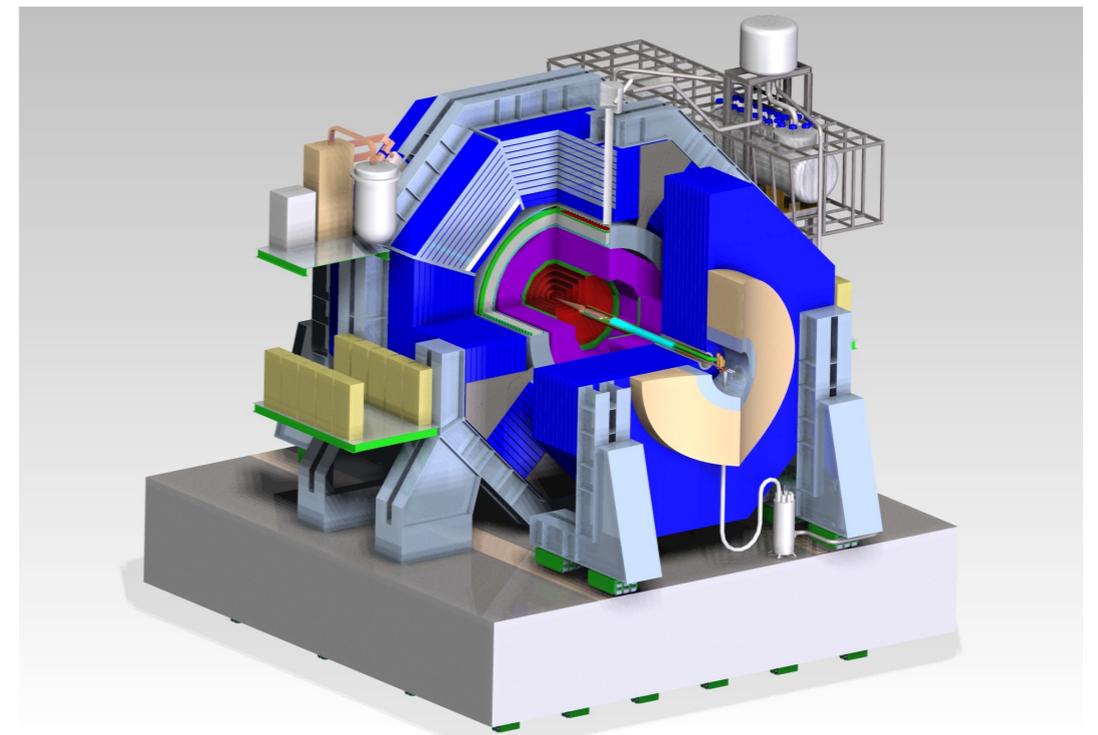


- precision measurement of the Higgs boson and top quark
- discovery of physics beyond the Standard Model
- search for candidates for dark matter

ILC has two detectors



ILD

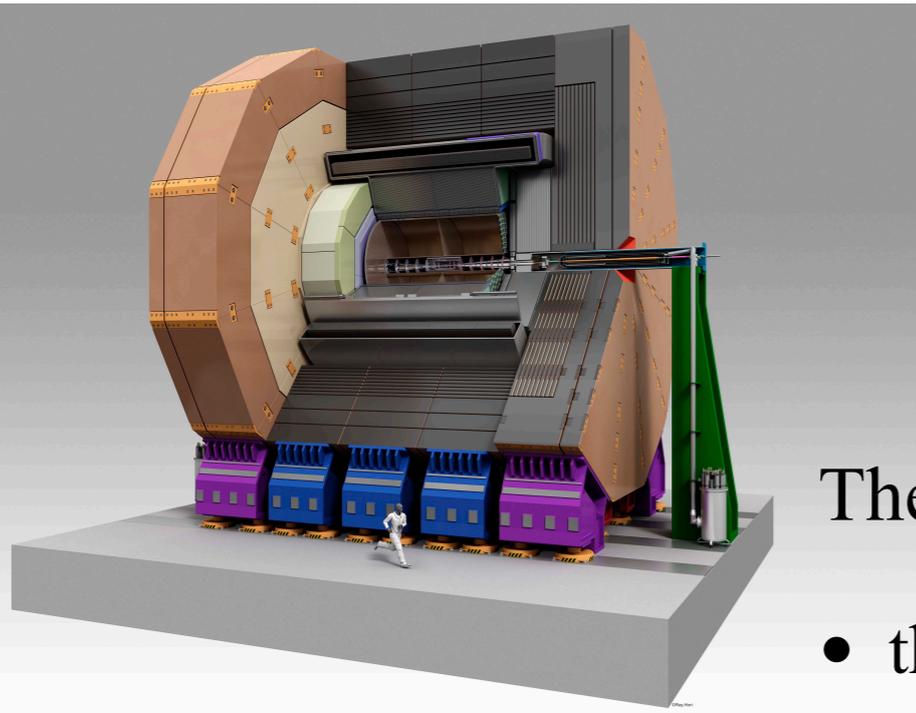


SiD

Introduction

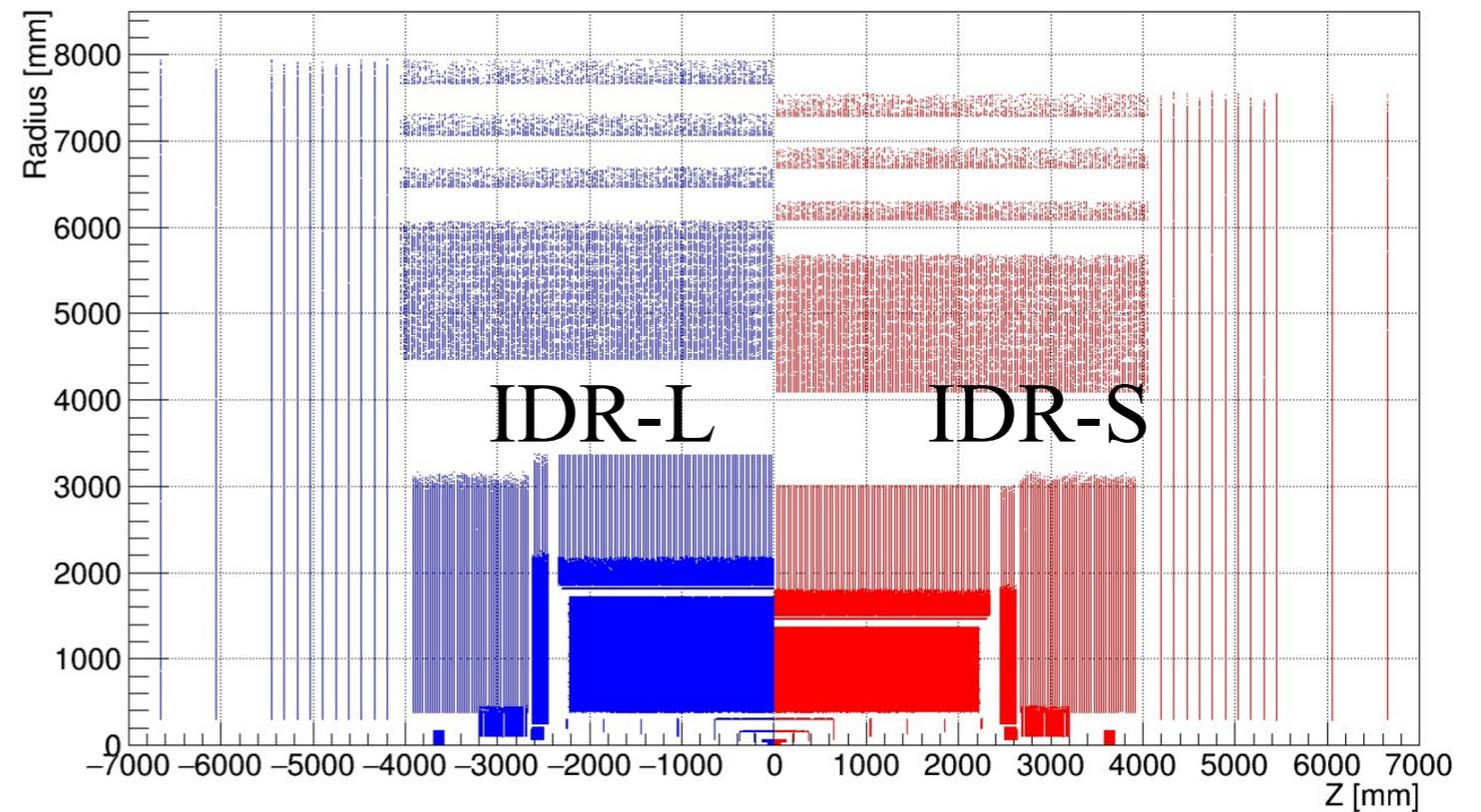
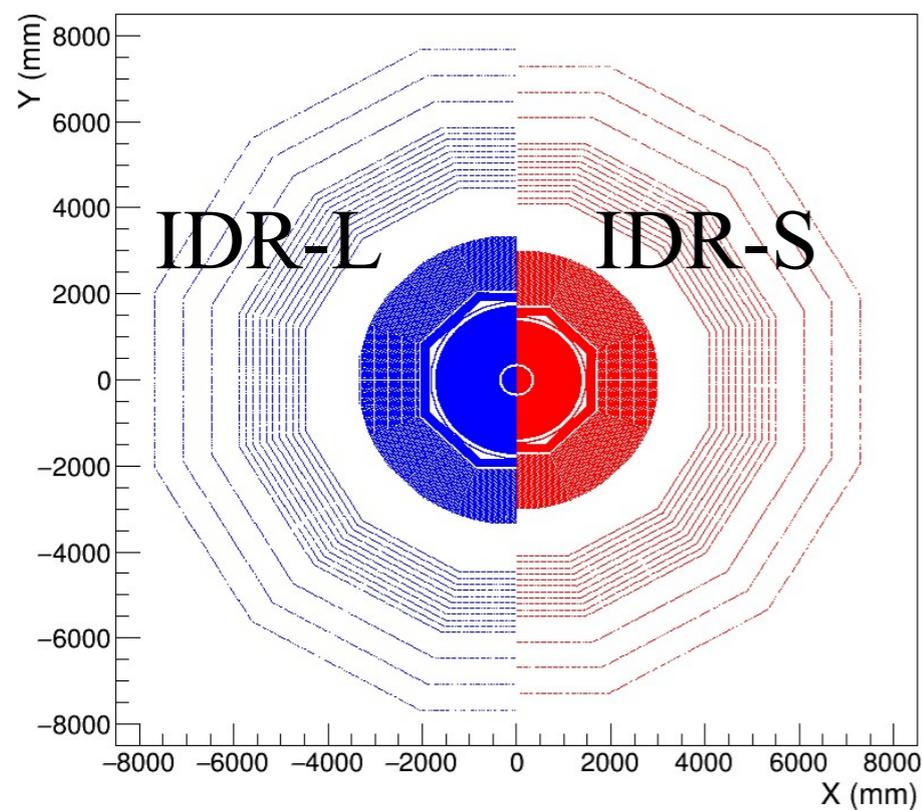
International Large Detector (ILD)

two models of the ILD detector



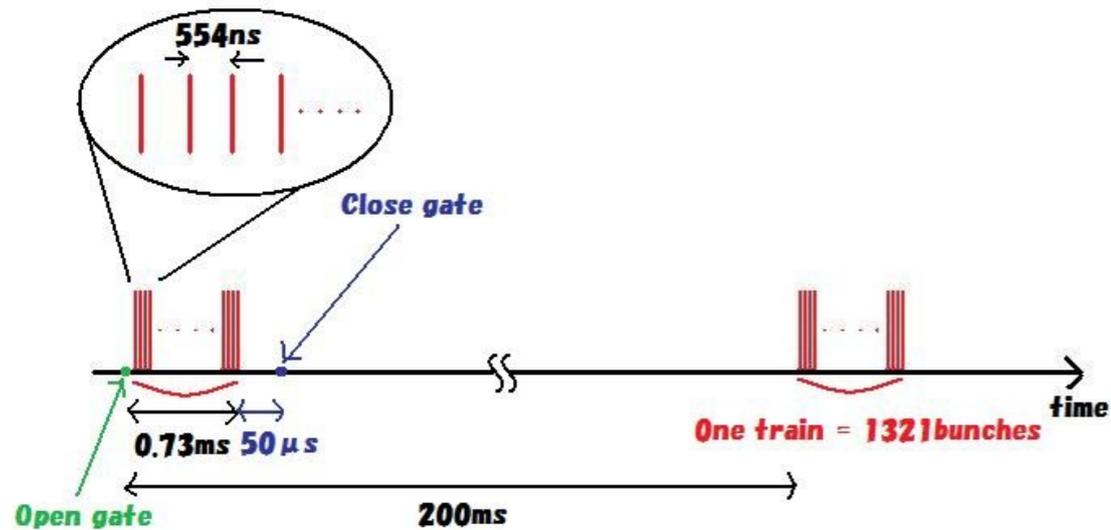
The difference

- | | IDR-L | IDR-S |
|------------------------------------|---------|---------|
| • the outer radius of TPC | 1770 mm | 1427 mm |
| • the strength of a magnetic field | 3.5 T | 4.0 T |



Effects of Positive Ions

ILC Beam Structure

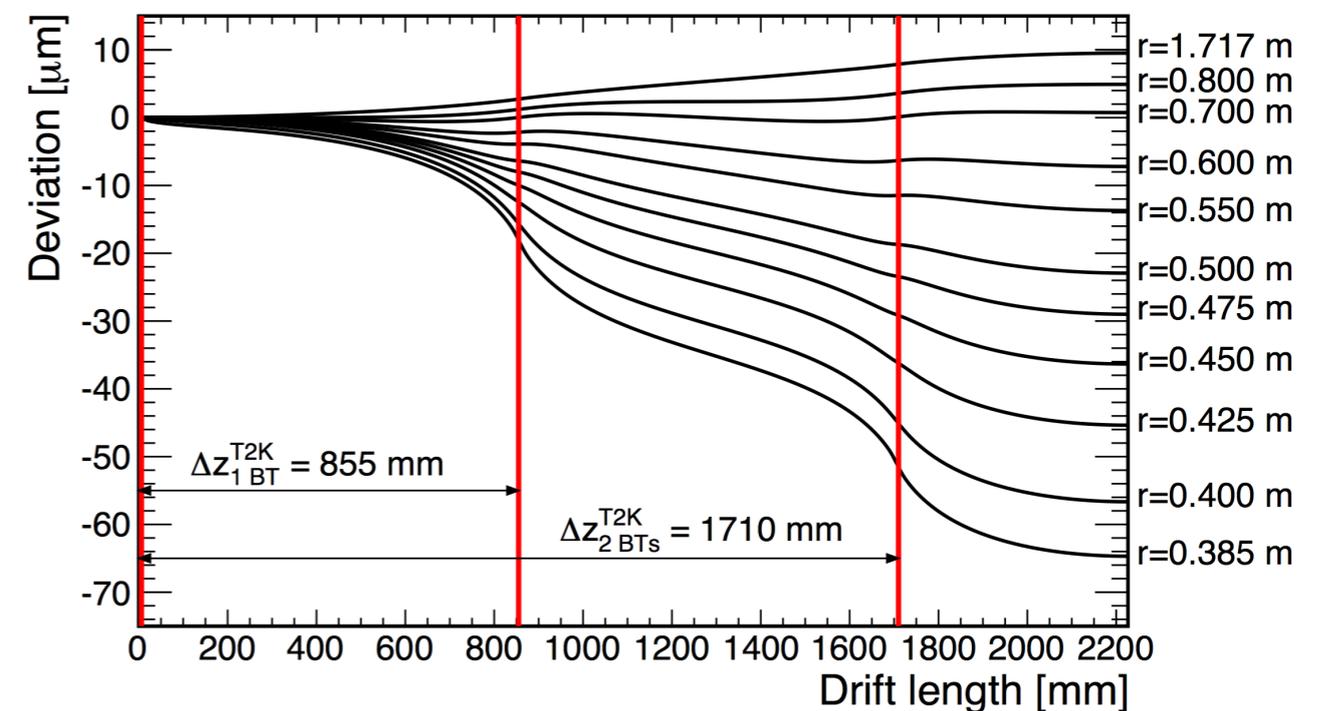
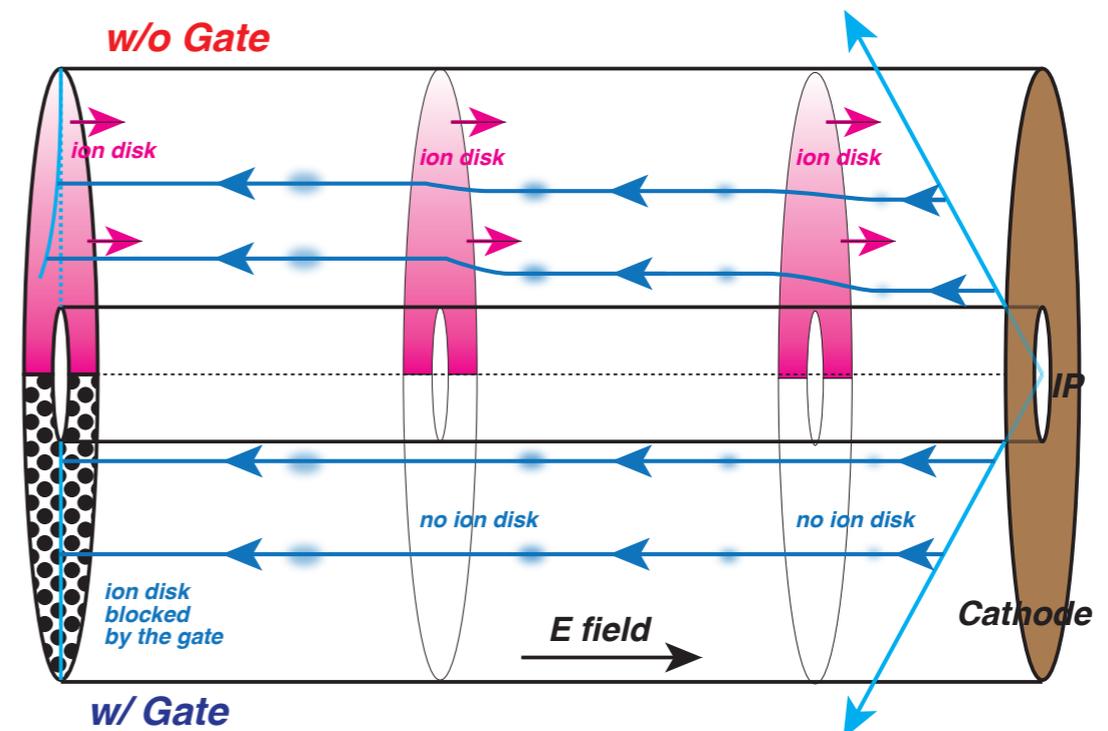


Positive Ion Disk

Positive ions created in the gas amplification region of readout MPGD modules drift slowly to the cathode.

Since they are slow, the positive ions created in a single bunch train form *a thin (<1cm) sheet (ion disk)*.

There would be *maximum three such ion disks* drifting towards the cathode, which *distort the drift paths of track electrons*, if there is no gating device.



σ of random walk

$$\sigma = \sqrt{2D^*t}$$

$D^*[\mu m/\sqrt{cm}]$: **Diffusion Coefficient**

σ of GEM

$$\sigma^2 = D^2L$$

$D[\mu m/\sqrt{cm}]$: **Diffusion Constant**

参考

阪大集中講義

http://www-het.phys.sci.osaka-u.ac.jp/lecture2016/201606Nakamura/Lecture2-3_ParticleDet.pdf

名古屋大学 講義

http://www.hepl.phys.nagoya-u.ac.jp/~makoto.nagoya/lectures/ParticlePhysics_3_2017/0809_20171201-1208.pdf

理論屋さん向けの検出器入門

http://research.kek.jp/people/nojiri/2015.11.26_PID_Jinnouchi.pdf